

8-BIT SINGLE-CHIP MICROCONTROLLERS

DESCRIPTION

The μ PD780021A, 780022A, 780023A, and 780024A are members of the μ PD780024A Subseries of the 78K/0 Series. Only selected functions of the existing μ PD78054 Subseries are provided, and the serial interface is enhanced.

The μ PD780021AY, 780022AY, 780023AY, and 780024AY are the μ PD780024A Subseries with a multimaster supporting I²C bus interface, which makes them suitable for AV equipment.

Flash memory versions, the μ PD78F0034A, 78F0034B, 78F0034AY, and 78F0034BY, that can operate in the same power supply voltage range as the mask ROM versions, and various development tools, are also available.

Detailed function descriptions are provided in the following user's manuals. Be sure to read them before designing.

μ PD780024A, 780034A, 780024AY, 780034AY	
Subseries User's Manual:	U14046E
78K/0 Series Instructions User's Manual:	U12326E

FEATURES

- Internal ROM and RAM

Part Number	Item	Program Memory (Internal ROM)	Data Memory (Internal High-Speed RAM)	Package
μ PD780021A, 780021AY		8 KB	512 bytes	<ul style="list-style-type: none"> • 64-pin plastic SDIP (19.05 mm (750)) • 64-pin plastic QFP (14 x 14) • 64-pin plastic LQFP (14 x 14)
μ PD780022A, 780022AY		16 KB		
μ PD780023A, 780023AY		24 KB	1024 bytes	<ul style="list-style-type: none"> • 64-pin plastic TQFP (12 x 12) • 64-pin plastic LQFP (10 x 10) • 73-pin plastic FBGA (9 x 9)
μ PD780024A, 780024AY		32 KB		

- External memory expansion space: 64 KB
- Minimum instruction execution time
 - Expanded-specification products of μ PD780021A, 780022A, 780023A, 780024A: 0.166 μ s ($f_x = 12$ MHz, $V_{DD} = 4.5$ to 5.5 V)
 - μ PD780021AY, 780022AY, 780023AY, 780024AY and conventional products of μ PD780021A, 780022A, 780023A, 780024A: 0.238 μ s ($f_x = 8.38$ MHz, $V_{DD} = 4.0$ to 5.5 V)
- I/O ports: 51 (N-ch open-drain (5 V withstanding voltage): 4)
- 8-bit resolution A/D converter: 8 channels ($A_{VDD} = 1.8$ to 5.5 V)
- Serial interface: 3 channels
 - μ PD780021A, 780022A, 780023A, 780024A: UART mode, 3-wire serial I/O mode (2 channels)
 - μ PD780021AY, 780022AY, 780023AY, 780024AY: UART mode, 3-wire serial I/O mode, I²C bus mode
- Timer: 5 channels
- Power supply voltage: $V_{DD} = 1.8$ to 5.5 V

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
 Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

APPLICATIONS

Telephones, household electrical appliances, pagers, AV equipment, car audios, office automation equipment, etc.

ORDERING INFORMATION (1/2)**(1) μPD780024A Subseries**

	Part Number	Package
	μPD780021ACW-xxx	64-pin plastic SDIP (19.05 mm (750))
	μPD780021AGC-xxx-AB8	64-pin plastic QFP (14 x 14)
★	μPD780021AGC-xxx-8BS	64-pin plastic LQFP (14 x 14)
	μPD780021AGK-xxx-9ET	64-pin plastic TQFP (12 x 12)
★	μPD780021AGB-xxx-8EU	64-pin plastic LQFP (10 x 10)
★	μPD780021AF1-xxx-CN3	73-pin plastic FBGA (9 x 9)
	μPD780022ACW-xxx	64-pin plastic SDIP (19.05 mm (750))
	μPD780022AGC-xxx-AB8	64-pin plastic QFP (14 x 14)
★	μPD780022AGC-xxx-8BS	64-pin plastic LQFP (14 x 14)
	μPD780022AGK-xxx-9ET	64-pin plastic TQFP (12 x 12)
★	μPD780022AGB-xxx-8EU	64-pin plastic LQFP (10 x 10)
★	μPD780022AF1-xxx-CN3	73-pin plastic FBGA (9 x 9)
	μPD780023ACW-xxx	64-pin plastic SDIP (19.05 mm (750))
	μPD780023AGC-xxx-AB8	64-pin plastic QFP (14 x 14)
★	μPD780023AGC-xxx-8BS	64-pin plastic LQFP (14 x 14)
	μPD780023AGK-xxx-9ET	64-pin plastic TQFP (12 x 12)
★	μPD780023AGB-xxx-8EU	64-pin plastic LQFP (10 x 10)
★	μPD780023AF1-xxx-CN3	73-pin plastic FBGA (9 x 9)
	μPD780024ACW-xxx	64-pin plastic SDIP (19.05 mm (750))
	μPD780024AGC-xxx-AB8	64-pin plastic QFP (14 x 14)
★	μPD780024AGC-xxx-8BS	64-pin plastic LQFP (14 x 14)
	μPD780024AGK-xxx-9ET	64-pin plastic TQFP (12 x 12)
★	μPD780024AGB-xxx-8EU	64-pin plastic LQFP (10 x 10)
★	μPD780024AF1-xxx-CN3	73-pin plastic FBGA (9 x 9)

Remark xxx indicates ROM code suffix.

ORDERING INFORMATION (2/2)

(2) μPD780024AY Subseries

	Part Number	Package
	μPD780021AYCW-xxx	64-pin plastic SDIP (19.05 mm (750))
	μPD780021AYGC-xxx-AB8	64-pin plastic QFP (14 x 14)
★	μPD780021AYGC-xxx-8BS	64-pin plastic LQFP (14 x 14)
	μPD780021AYGK-xxx-9ET	64-pin plastic TQFP (12 x 12)
★	μPD780021AYGB-xxx-8EU	64-pin plastic LQFP (10 x 10)
★	μPD780021AYF1-xxx-CN3	73-pin plastic FBGA (9 x 9)
	μPD780022AYCW-xxx	64-pin plastic SDIP (19.05 mm (750))
	μPD780022AYGC-xxx-AB8	64-pin plastic QFP (14 x 14)
★	μPD780022AYGC-xxx-8BS	64-pin plastic LQFP (14 x 14)
	μPD780022AYGK-xxx-9ET	64-pin plastic TQFP (12 x 12)
★	μPD780022AYGB-xxx-8EU	64-pin plastic LQFP (10 x 10)
★	μPD780022AYF1-xxx-CN3	73-pin plastic FBGA (9 x 9)
	μPD780023AYCW-xxx	64-pin plastic SDIP (19.05 mm (750))
	μPD780023AYGC-xxx-AB8	64-pin plastic QFP (14 x 14)
★	μPD780023AYGC-xxx-8BS	64-pin plastic LQFP (14 x 14)
	μPD780023AYGK-xxx-9ET	64-pin plastic TQFP (12 x 12)
★	μPD780023AYGB-xxx-8EU	64-pin plastic LQFP (10 x 10)
★	μPD780023AYF1-xxx-CN3	73-pin plastic FBGA (9 x 9)
	μPD780024AYCW-xxx	64-pin plastic SDIP (19.05 mm (750))
	μPD780024AYGC-xxx-AB8	64-pin plastic QFP (14 x 14)
★	μPD780024AYGC-xxx-8BS	64-pin plastic LQFP (14 x 14)
	μPD780024AYGK-xxx-9ET	64-pin plastic TQFP (12 x 12)
★	μPD780024AYGB-xxx-8EU	64-pin plastic LQFP (10 x 10)
★	μPD780024AYF1-xxx-CN3	73-pin plastic FBGA (9 x 9)

Remark xxx indicates ROM code suffix.

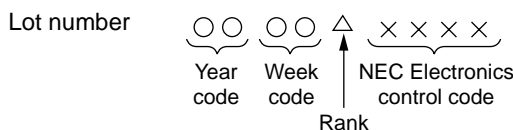
★ EXPANDED-SPECIFICATION PRODUCTS AND CONVENTIONAL PRODUCTS

The expanded-specification product and conventional product refer to the following products.

Expanded-specification product: μPD780021A, 780022A, 780023A, 780024A for which orders were received after December 1, 2001.
(Products with a rank^{Note} other than K, E, P, X)

Conventional product: Products other than the above expanded specification products.
(Products with rank^{Note} K, E, P, X)
μPD780021AY, 780022AY, 780023AY, 780024AY

Note The rank is indicated by the 5th digit from the left in the lot number marked on the package.



Expanded-specification products and conventional products differ in the power supply voltage range and operating frequency ratings.

Power Supply Voltage (V _{DD})	Guaranteed Operating Speed (Operating Frequency)	
	Conventional Products	Expanded-Specification Products
4.5 to 5.5 V	8.38 MHz (0.238 μs)	12 MHz (0.166 μs)
4.0 to 5.5 V	8.38 MHz (0.238 μs)	8.38 MHz (0.238 μs)
3.0 to 5.5 V	5 MHz (0.4 μs)	8.38 MHz (0.238 μs)
2.7 to 5.5 V	5 MHz (0.4 μs)	5 MHz (0.4 μs)
1.8 to 5.5 V	1.25 MHz (1.6 μs)	1.25 MHz (1.6 μs)

Remark The parenthesized values indicates the minimum instruction execution time.

★ CORRESPONDENCE BETWEEN MASK ROM PRODUCTS AND FLASH MEMORY PRODUCTS

Mask ROM Products	Flash Memory Products
Expanded-specification products of μPD780021A, 780022A, 780023A, 780024A	μPD78F0034B
Conventional products of μPD780021A, 780022A, 780023A, 780024A	μPD78F0034A
μPD780021AY, 780022AY, 780023AY, 780024AY	μPD78F0034AY, 78F0034BY

Remark The μPD78F0034A and 78F0034B differ in the operating frequency ratings and communication mode of flash memory programming. The μPD78F0034AY and 78F0034BY only differ in the communication mode of flash memory programming. Refer to the data sheet of the products.

★ 78K/0 SERIES LINEUP

The products in the 78K/0 Series are listed below. The names enclosed in boxes are subseries names.



Y subseries products are compatible with I²C bus.

Pin Count	Subseries Name	Description
Control		
100-pin	μPD78075B	EMI-noise reduced version of the μPD78078
100-pin	μPD78078	μPD78054 with timer and enhanced external interface
100-pin	μPD78078Y	μPD78054 with timer and enhanced external interface
100-pin	μPD78070A	ROMless version of the μPD78078
100-pin	μPD78070AY	ROMless version of the μPD78078
100-pin	μPD780018AY	μPD78078Y with enhanced serial I/O and limited function
80-pin	μPD780058	μPD78054 with enhanced serial I/O
80-pin	μPD780058Y	μPD78054 with enhanced serial I/O
80-pin	μPD78058F	EMI-noise reduced version of the μPD78054
80-pin	μPD78058FY	EMI-noise reduced version of the μPD78054
80-pin	μPD78054	μPD78018F with UART and D/A converter, and enhanced I/O
80-pin	μPD78054Y	μPD78018F with UART and D/A converter, and enhanced I/O
80-pin	μPD780065	μPD780024A with expanded RAM
64-pin	μPD780078	μPD780034A with timer and enhanced serial I/O
64-pin	μPD780078Y	μPD780034A with timer and enhanced serial I/O
64-pin	μPD780034A	μPD780024A with enhanced A/D converter
64-pin	μPD780034AY	μPD780024A with enhanced A/D converter
64-pin	μPD780024A	μPD78018F with enhanced serial I/O
64-pin	μPD780024AY	μPD78018F with enhanced serial I/O
52-pin	μPD780034AS	52-pin version of the μPD780034A
52-pin	μPD780024AS	52-pin version of the μPD780024A
64-pin	μPD78014H	EMI-noise reduced version of the μPD78018F
64-pin	μPD78018F	Basic subseries for control
64-pin	μPD78018FY	Basic subseries for control
42/44-pin	μPD78083	On-chip UART, capable of operating at low voltage (1.8 V)
Inverter control		
64-pin	μPD780988	On-chip inverter control circuit and UART. EMI-noise reduced.
VFD drive		
100-pin	μPD780208	μPD78044F with enhanced I/O and VFD C/D. Display output total: 53
80-pin	μPD780232	For panel control. On-chip VFD C/D. Display output total: 53
80-pin	μPD78044H	μPD78044F with N-ch open-drain I/O. Display output total: 34
80-pin	μPD78044F	Basic subseries for driving VFD. Display output total: 34
LCD drive		
100-pin	μPD780354	μPD780344 with enhanced A/D converter
100-pin	μPD780344	μPD780308 with enhanced display function and timer. Segment signal output: 40 pins max.
100-pin	μPD780344Y	μPD780308 with enhanced display function and timer. Segment signal output: 40 pins max.
120-pin	μPD780338	μPD780308 with enhanced display function and timer. Segment signal output: 40 pins max.
120-pin	μPD780328	μPD780308 with enhanced display function and timer. Segment signal output: 32 pins max.
120-pin	μPD780318	μPD780308 with enhanced display function and timer. Segment signal output: 24 pins max.
100-pin	μPD780308	μPD78064 with enhanced SIO, and expanded ROM and RAM
100-pin	μPD780308Y	μPD78064 with enhanced SIO, and expanded ROM and RAM
100-pin	μPD78064B	EMI-noise reduced version of the μPD78064
100-pin	μPD78064	Basic subseries for driving LCDs, on-chip UART
100-pin	μPD78064Y	Basic subseries for driving LCDs, on-chip UART
Bus interface supported		
100-pin	μPD780948	On-chip CAN controller
80-pin	μPD78098B	μPD78054 with IEBus™ controller
80-pin	μPD780702Y	On-chip IEBus controller
80-pin	μPD780703Y	On-chip CAN controller
80-pin	μPD780833Y	On-chip controller compliant with J1850 (Class 2)
64-pin	μPD780816	Specialized for CAN controller function
Meter control		
100-pin	μPD780958	For industrial meter control
80-pin	μPD780852	On-chip automobile meter controller/driver
80-pin	μPD780828B	For automobile meter driver. On-chip CAN controller

Remark VFD (Vacuum Fluorescent Display) is referred to as FIP™ (Fluorescent Indicator Panel) in some documents, but the functions of the two are same.

The major functional differences among the subseries are listed below.

- Non-Y subseries

Subseries Name	Function	ROM Capacity (Bytes)	Timer				8-Bit	10-Bit	8-Bit	Serial Interface	I/O	V _{DD} MIN. Value	External Expansion	
			8-Bit	16-Bit	Watch	WDT	A/D	A/D	D/A					
Control	μPD78075B	32 K to 40 K	4 ch	1 ch	1 ch	1 ch	8 ch	-	2 ch	3 ch (UART: 1 ch)	88	1.8 V	√	
	μPD78078	48 K to 60 K												
	μPD78070A	-								61	2.7 V			
	μPD780058	24 K to 60 K	2 ch							3 ch (time-division UART: 1 ch)	68	1.8 V		
	μPD78058F	48 K to 60 K												
	μPD78054	16 K to 60 K									2.0 V			
	μPD780065	40 K to 48 K							-	4 ch (UART: 1 ch)	60	2.7 V		
	μPD780078	48 K to 60 K		2 ch			-	8 ch		3 ch (UART: 2 ch)	52	1.8 V		
	μPD780034A	8 K to 32 K		1 ch						3 ch (UART: 1 ch)	51			
	μPD780024A						8 ch	-						
	μPD780034AS						-	4 ch			39			-
	μPD780024AS						4 ch	-						
	μPD78014H						8 ch			2 ch	53			√
	μPD78018F	8 K to 60 K												
μPD78083	8 K to 16 K		-	-					1 ch (UART: 1 ch)	33		-		
Inverter control	μPD780988	16 K to 60 K	3 ch	Note	-	1 ch	-	8 ch	-	3 ch (UART: 2 ch)	47	4.0 V	√	
VFD drive	μPD780208	32 K to 60 K	2 ch	1 ch	1 ch	1 ch	8 ch	-	-	2 ch	74	2.7 V	-	
	μPD780232	16 K to 24 K	3 ch	-	-		4 ch				40	4.5 V		
	μPD78044H	32 K to 48 K	2 ch	1 ch	1 ch		8 ch			1 ch	68	2.7 V		
	μPD78044F	16 K to 40 K								2 ch				
LCD drive	μPD780354	24 K to 32 K	4 ch	1 ch	1 ch	1 ch	-	8 ch	-	3 ch (UART: 1 ch)	66	1.8 V	-	
	μPD780344						8 ch	-						
	μPD780338	48 K to 60 K	3 ch	2 ch			-	10 ch	1 ch	2 ch (UART: 1 ch)	54			
	μPD780328										62			
	μPD780318										70			
	μPD780308	48 K to 60 K	2 ch	1 ch			8 ch	-	-	3 ch (time-division UART: 1 ch)	57	2.0 V		
	μPD78064B	32 K								2 ch (UART: 1 ch)				
μPD78064	16 K to 32 K													
Bus interface supported	μPD780948	60 K	2 ch	2 ch	1 ch	1 ch	8 ch	-	-	3 ch (UART: 1 ch)	79	4.0 V	√	
	μPD78098B	40 K to 60 K		1 ch					2 ch		69	2.7 V	-	
	μPD780816	32 K to 60 K		2 ch			12 ch		-	2 ch (UART: 1 ch)	46	4.0 V		
Meter control	μPD780958	48 K to 60 K	4 ch	2 ch	-	1 ch	-	-	-	2 ch (UART: 1 ch)	69	2.2 V	-	
Dash-board control	μPD780852	32 K to 40 K	3 ch	1 ch	1 ch	1 ch	5 ch	-	-	3 ch (UART: 1 ch)	56	4.0 V	-	
	μPD780828B	32 K to 60 K									59			

Note 16-bit timer: 2 channels
10-bit timer: 1 channel

• Y subseries

Function Subseries Name	ROM Capacity (Bytes)	Timer				8-Bit	10-Bit	8-Bit	Serial Interface	I/O	V _{DD} MIN. Value	External Expansion	
		8-Bit	16-Bit	Watch	WDT	A/D	A/D	D/A					
Control	μPD78078Y	48 K to 60 K	4 ch	1 ch	1 ch	1 ch	8 ch	-	2 ch	3 ch (UART: 1 ch, I ² C: 1 ch)	88	1.8 V	√
	μPD78070AY	-								61	2.7 V		
	μPD780018AY	48 K to 60 K								88			
	μPD780058Y	24 K to 60 K	2 ch	-	-	-	-	2 ch	3 ch (time-division UART: 1 ch, I ² C: 1 ch)	68	1.8 V		
	μPD78058FY	48 K to 60 K							3 ch (UART: 1 ch, I ² C: 1 ch)	69	2.7 V		
	μPD78054Y	16 K to 60 K	2 ch	-	-	-	-	-	-	2.0 V			
	μPD780078Y	48 K to 60 K								4 ch (UART: 2 ch, I ² C: 1 ch)	52	1.8 V	
	μPD780034AY	8 K to 32 K								1 ch	3 ch (UART: 1 ch, I ² C: 1 ch)	51	
	μPD780024AY		8 ch	-	-	-	-	-	-	-	-		
μPD78018FY	8 K to 60 K	2 ch (I ² C: 1 ch)										53	
LCD drive	μPD780354Y	24 K to 32 K	4 ch	1 ch	1 ch	1 ch	-	8 ch	-	4 ch (UART: 1 ch, I ² C: 1 ch)	66	1.8 V	-
	μPD780344Y						8 ch	-					
	μPD780308Y	48 K to 60 K	2 ch	-	-	-	-	-	-	3 ch (time-division UART: 1 ch, I ² C: 1 ch)	57	2.0 V	
	μPD78064Y	16 K to 32 K								2 ch (UART: 1 ch, I ² C: 1 ch)			
Bus interface supported	μPD780701Y	60 K	3 ch	2 ch	1 ch	1 ch	16 ch	-	-	4 ch (UART: 1 ch, I ² C: 1 ch)	67	3.5 V	-
	μPD780703Y												
	μPD780833Y										65	4.5 V	

Remark The functions of non-Y subseries and Y subseries products are the same, except for the serial interface.

OVERVIEW OF FUNCTIONS (1/2)

Item		Part Number			
		μPD780021A μPD780021AY	μPD780022A μPD780022AY	μPD780023A μPD780023AY	μPD780024A μPD780024AY
Internal memory	ROM	8 KB	16 KB	24 KB	32 KB
	High-speed RAM	512 bytes		1024 bytes	
Memory space		64 KB			
General-purpose registers		8 bits × 32 registers (8 bits × 8 registers × 4 banks)			
Minimum instruction execution time		On-chip minimum instruction execution time cycle variable function			
	When main system clock selected	<ul style="list-style-type: none"> Expanded-specification products of μPD780021A, 780022A, 780023A, 780024A: 0.166 μs/0.333 μs/0.666 μs/1.33 μs/2.66 μs (@12 MHz, V_{DD} = 4.5 to 5.5 V operation) μPD780021AY, 780022AY, 780023AY, 780024AY and conventional products of μPD780021A, 780022A, 780023A, 780024A: 0.238 μs/0.48 μs/0.95 μs/1.91 μs/3.81 μs (@8.38 MHz, V_{DD} = 4.0 to 5.5 V operation) 			
	When subsystem clock selected	122 μs (@ 32.768 kHz operation)			
Instruction set		<ul style="list-style-type: none"> 16-bit operation Multiply/divide (8 bits × 8 bits, 16 bits ÷ 8 bits) Bit manipulation (set, reset, test, Boolean operation) BCD adjust, etc. 			
I/O ports		Total: 51 <hr/> <ul style="list-style-type: none"> CMOS input: 8 CMOS I/O: 39 N-ch open-drain I/O (5 V withstanding voltage): 4 			
A/D converter		<ul style="list-style-type: none"> 8-bit resolution × 8 channels Low-voltage operation available: AV_{DD} = 1.8 to 5.5 V 			
Serial interface		<ul style="list-style-type: none"> μPD780021A, 780022A, 780023A, 780024A <ul style="list-style-type: none"> UART mode: 1 channel 3-wire serial I/O mode: 2 channels μPD780021AY, 780022AY, 780023AY, 780024AY <ul style="list-style-type: none"> UART mode: 1 channel 3-wire serial I/O mode: 1 channel I²C bus mode (multimaster supporting): 1 channel 			
Timers		<ul style="list-style-type: none"> 16-bit timer/event counter: 1 channel 8-bit timer/event counter: 2 channels Watch timer: 1 channel Watchdog timer: 1 channel 			
Timer outputs		3 (8-bit PWM output capable: 2)			

★

OVERVIEW OF FUNCTIONS (2/2)

Item		Part Number		μPD780021A	μPD780022A	μPD780023A	μPD780024A
				μPD780021AY	μPD780022AY	μPD780023AY	μPD780024AY
★	Clock output		<ul style="list-style-type: none"> Expanded-specification products of μPD780021A, 780022A, 780023A, 780024A: 93.75 kHz, 187.5 kHz, 375 kHz, 750 kHz, 1.25 MHz, 3 MHz, 6 MHz, 12 MHz (@12MHz operation with main system clock) 32.768 kHz (@ 32.768 kHz operation with subsystem clock) μPD780021AY, 780022AY, 780023AY, 780024AY and conventional products of μPD780021A, 780022A, 780023A, 780024A: 65.5 kHz, 131 kHz, 262 kHz, 524 kHz, 1.05 MHz, 2.10 MHz, 4.19 MHz, 8.38 MHz (@ 8.38 MHz operation with main system clock) 32.768 kHz (@ 32.768 kHz operation with subsystem clock) 				
★	Buzzer output		<ul style="list-style-type: none"> Expanded-specification products of μPD780021A, 780022A, 780023A, 780024A: 1.46 kHz, 2.93 kHz, 5.86 kHz, 11.7 kHz (@ 12 MHz operation with main system clock) μPD780021AY, 780022AY, 780023AY, 780024AY and conventional products of μPD780021A, 780022A, 780023A, 780024A: 1.02 kHz, 2.05 kHz, 4.10 kHz, 8.19 kHz (@ 8.38 MHz operation with main system clock) 				
	Vectored interrupt sources	Maskable	Internal: 13, external: 5				
		Non-maskable	Internal: 1				
		Software	1				
	Power supply voltage		V _{DD} = 1.8 to 5.5 V				
	Operating ambient temperature		T _A = -40 to +85°C				
★	Package	<ul style="list-style-type: none"> 64-pin plastic SDIP (19.05 mm (750)) 					
★		<ul style="list-style-type: none"> 64-pin plastic QFP (14 x 14) 					
★		<ul style="list-style-type: none"> 64-pin plastic LQFP (14 x 14) 					
★		<ul style="list-style-type: none"> 64-pin plastic TQFP (12 x 12) 					
	<ul style="list-style-type: none"> 64-pin plastic LQFP (10 x 10) 						
	<ul style="list-style-type: none"> 73-pin plastic FBGA (9 x 9) 						

CONTENTS

1. PIN CONFIGURATION (TOP VIEW) 11

2. BLOCK DIAGRAM 15

3. PIN FUNCTIONS 16

 3.1 Port Pins 16

 3.2 Non-Port Pins 17

 3.3 Pin I/O Circuits and Recommended Connection of Unused Pins 19

4. MEMORY SPACE 21

5. PERIPHERAL HARDWARE FUNCTION FEATURES 22

 5.1 Ports 22

 5.2 Clock Generator 23

 5.3 Timer/Counter 24

 5.4 Clock Output/Buzzer Output Controller 28

 5.5 A/D Converter 29

 5.6 Serial Interface 30

6. INTERRUPT FUNCTIONS 33

7. EXTERNAL DEVICE EXPANSION FUNCTION 36

8. STANDBY FUNCTION 36

9. RESET FUNCTION 36

10. MASK OPTION 36

11. INSTRUCTION SET 37

12. ELECTRICAL SPECIFICATIONS 39

 12.1 Expanded-Specification Products of μ PD780021A, 780022A, 780023A, 780024A 39

 12.2 μ PD780021AY, 780022AY, 780023AY, 780024AY, and Conventional Products of μ PD780021A, 780022A, 780023A, 780024A 55

 12.3 Timing Chart 71

13. PACKAGE DRAWINGS 77

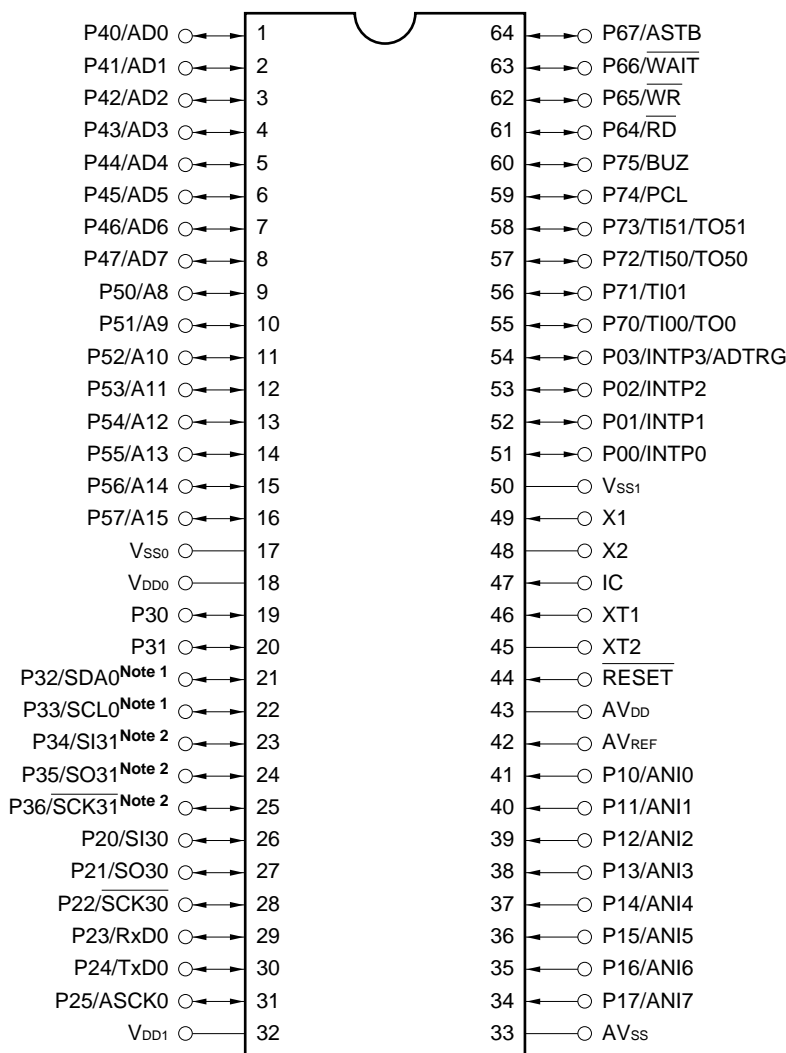
14. RECOMMENDED SOLDERING CONDITIONS 83

APPENDIX A. DEVELOPMENT TOOLS 87

APPENDIX B. RELATED DOCUMENTS 91

1. PIN CONFIGURATION (TOP VIEW)

- 64-pin plastic SDIP (19.05 mm (750))

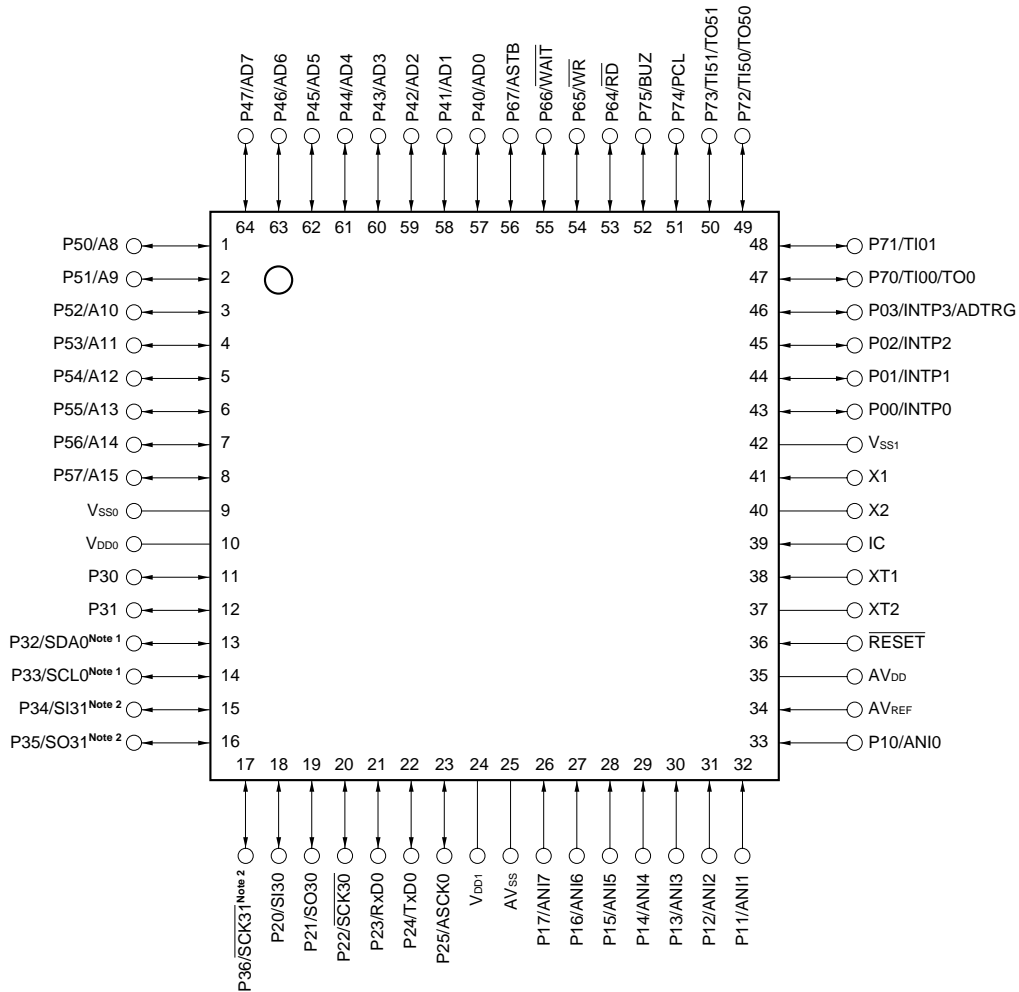


- Notes**
1. SDA0 and SCL0 are incorporated only in the μPD780024AY Subseries.
 2. SI31, SO31, and SCK31 are incorporated only in the μPD780024A Subseries.

- Cautions**
1. Connect the IC (Internally Connected) pin directly to VSS0 or VSS1.
 2. Connect the AVSS pin to VSS0.

Remark When the μPD780021A, 780022A, 780023A, 780024A, 780021AY, 780022AY, 780023AY, and 780024AY are used in applications where the noise generated inside the microcontroller needs to be reduced, the implementation of noise reduction measures, such as supplying voltage to VDD0 and VDD1 individually and connecting VSS0 and VSS1 to different ground lines, is recommended.

- 64-pin plastic QFP (14 x 14)
- ★ • 64-pin plastic LQFP (14 x 14)
- 64-pin plastic TQFP (12 x 12)
- ★ • 64-Pin plastic LQFP (10 x 10)

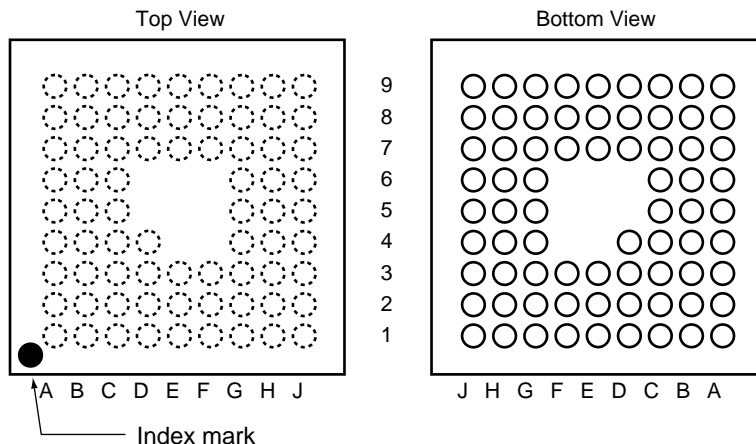


- Notes**
1. SDA0 and SCL0 are incorporated only in the μPD780024AY Subseries.
 2. SI31, SO31, and SCK31 are incorporated only in the μPD780024A Subseries.

- Cautions**
1. Connect the IC (Internally Connected) pin directory to VSS0 or VSS1.
 2. Connect the AVSS pin to VSS0.

Remark When the μPD780021A, 780022A, 780023A, 780024A, 780021AY, 780022AY, 780023AY, and 780024AY are used in applications where the noise generated inside the microcontroller needs to be reduced, the implementation of noise reduction measures, such as supplying voltage to VDD0 and VDD1 individually and connecting VSS0 and VSS1 to different ground lines, is recommended.

★ • 73-pin plastic FBGA (9 x 9)



Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name
A1	NC	C1	P52/A10	E1	P57/A15	G1	P33/SCL0 ^{Note 1}	J1	NC
A2	P46/AD6	C2	P53/A11	E2	V _{DD0}	G2	P32/SDA0 ^{Note 1}	J2	P36/SCK31 ^{Note 2}
A3	P44/AD4	C3	P45/AD5	E3	P54/A12	G3	P20/SI30	J3	NC
A4	P41/AD1	C4	P42/AD2	E4	–	G4	P21/SO30	J4	P25/ASCK0
A5	P67/ASTB	C5	P64/R _D	E5	–	G5	P24/TxD0	J5	NC
A6	P65/W _R	C6	P73/TI51/TO51	E6	–	G6	V _{DD1}	J6	P17/ANI7
A7	P74/PCL	C7	P03/INTP3/ADTRG	E7	P00/INTP0	G7	P16/ANI6	J7	P12/ANI2
A8	NC	C8	P01/INTP1	E8	XT1	G8	AV _{DD}	J8	P13/ANI3
A9	NC	C9	V _{SS1}	E9	X2	G9	NC	J9	NC
B1	P51/A9	D1	P55/A13	F1	P30	H1	P34/SI31 ^{Note 2}		
B2	P47/AD7	D2	P56/A14	F2	P31	H2	P35/SO31 ^{Note 2}		
B3	P43/AD3	D3	P50/A8	F3	V _{SS0}	H3	P23/RxD0		
B4	P40/AD0	D4	NC	F4	–	H4	P22/SCK30		
B5	P66/W _{AIT}	D5	–	F5	–	H5	AV _{SS}		
B6	P75/BUZ	D6	–	F6	–	H6	P15/ANI5		
B7	P72/TI50/TO51	D7	P02/INTP2	F7	P14/ANI4	H7	P11/ANI1		
B8	P71/TI01	D8	IC	F8	R _{ESET}	H8	P10/ANI0		
B9	P70/TI00/TO0	D9	X1	F9	XT2	H9	AV _{REF}		

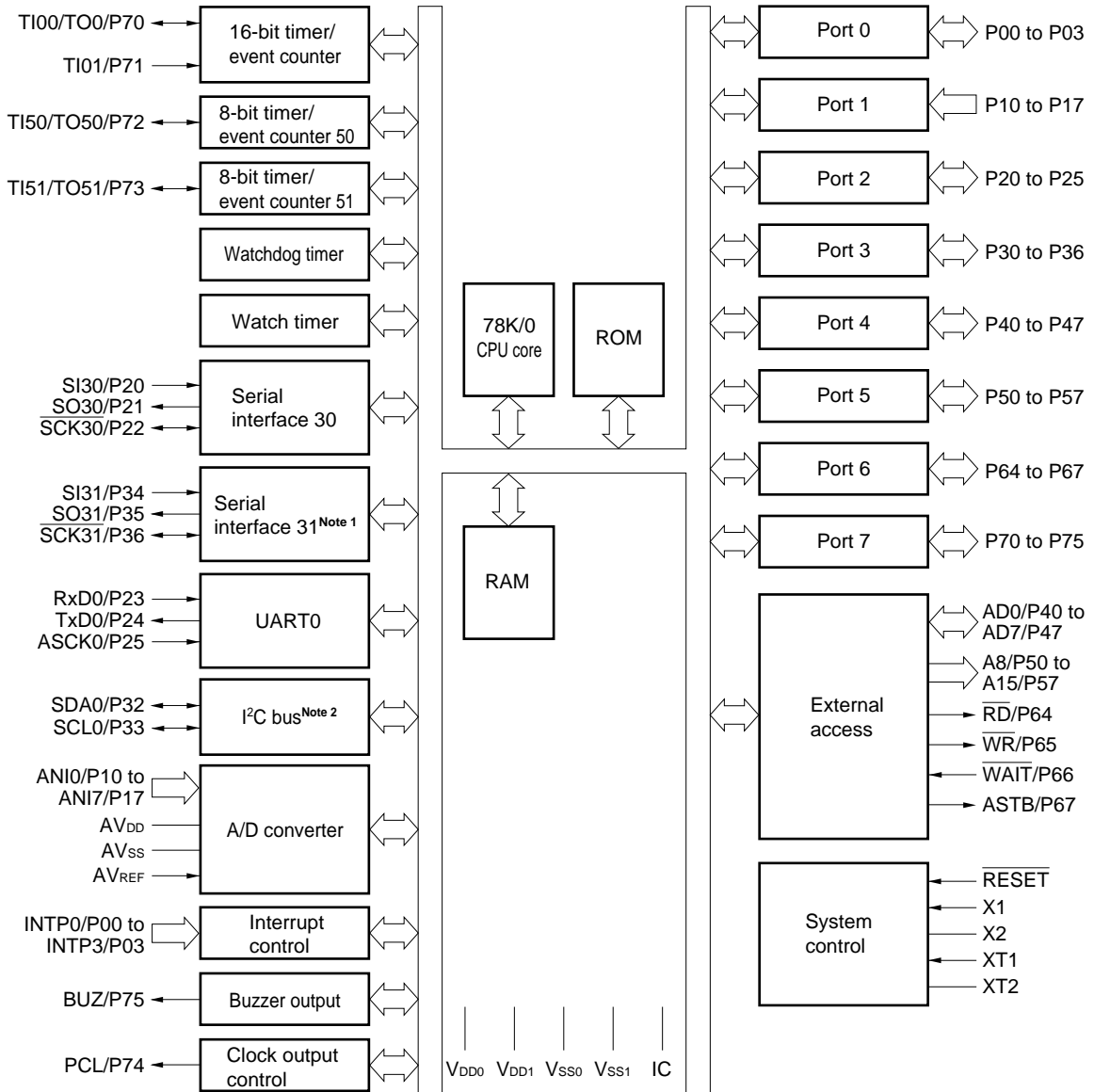
- Notes**
1. SDA0 and SCL0 are incorporated only in the μPD780024AY Subseries.
 2. SI31, SO31, and SCK31 are incorporated only in the μPD780024A Subseries.

- Cautions**
1. Connect the IC (Internally Connected) pin directory to V_{SS0} or V_{SS1}.
 2. Connect the AV_{SS} pin to V_{SS0}.

Remark When the μPD780021A, 780022A, 780023A, 780024A, 780021AY, 780022AY, 780023AY, and 780024AY are used in applications where the noise generated inside the microcontroller needs to be reduced, the implementation of noise reduction measures, such as supplying voltage to V_{DD0} and V_{DD1} individually and connecting V_{SS0} and V_{SS1} to different ground lines, is recommended.

A8 to A15:	Address bus	P64 to P67:	Port 6
AD0 to AD7:	Address/data bus	P70 to P75:	Port 7
ADTRG:	AD trigger input	PCL:	Programmable clock
ANI0 to ANI7:	Analog input	\overline{RD} :	Read strobe
ASCK0:	Asynchronous serial clock	\overline{RESET} :	Reset
ASTB:	Address strobe	RxD0:	Receive data
AV _{DD} :	Analog power supply	$\overline{SCK30}$, $\overline{SCK31}$, SCL0:	Serial clock
AV _{REF} :	Analog reference voltage	SDA0:	Serial data
AV _{SS} :	Analog ground	SI30, SI31:	Serial input
BUZ:	Buzzer clock	SO30, SO31:	Serial output
IC:	Internally connected	TI00, TI01, TI50, TI51:	Timer input
INTP0 to INTP3:	External interrupt input	TO0, TO50, TO51:	Timer output
★ NC:	No connection	TxD0:	Transmit data
P00 to P03:	Port 0	V _{DD0} , V _{DD1} :	Power supply
P10 to P17:	Port 1	V _{SS0} , V _{SS1} :	Ground
P20 to P25:	Port 2	\overline{WAIT} :	Wait
P30 to P36:	Port 3	\overline{WR} :	Write strobe
P40 to P47:	Port 4	X1, X2:	Crystal (main system clock)
P50 to P57:	Port 5	XT1, XT2:	Crystal (subsystem clock)

2. BLOCK DIAGRAM



- Notes**
1. Incorporated only in the μPD780024A Subseries.
 2. Incorporated only in the μPD780024AY Subseries.

Remark The internal ROM and RAM capacities vary depending on the product.

3. PIN FUNCTIONS

3.1 Port Pins (1/2)

Pin Name	I/O	Function		After Reset	Alternate Function
P00 to P02	I/O	Port 0 4-bit I/O port Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.		Input	INTP0 to INTP2
P03					INTP3/ADTRG
P10 to P17	Input	Port 1 8-bit input only port		Input	ANI0 to ANI7
P20	I/O	Port 2 6-bit I/O port Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.		Input	SI30
P21					SO30
P22					SCK30
P23					RxD0
P24					TxD0
P25					ASCK0
P30	I/O	Port 3 7-bit I/O port Input/output can be specified in 1-bit units.	N-ch open-drain I/O port An on-chip pull-up resistor can be specified by the mask option. LEDs can be driven directly.	Input	—
P31					SDA0 ^{Note 1}
P32					SCL0 ^{Note 1}
P33		SI31 ^{Note 2}			
P34		SO31 ^{Note 2}			
P35		SCK31 ^{Note 2}			
P36					
P40 to P47	I/O	Port 4 8-bit I/O port Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software. The interrupt request flag (KRIF) is set to 1 by falling edge detection.		Input	AD0 to AD7
P50 to P57	I/O	Port 5 8-bit I/O port LEDs can be driven directly. Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.		Input	A8 to A15
P64	I/O	Port 6 4-bit I/O port Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.		Input	\overline{RD}
P65					\overline{WR}
P66					\overline{WAIT}
P67					ASTB

- Notes**
1. SDA0 and SCL0 are incorporated only in the μPD780024AY Subseries.
 2. SI31, SO31, and SCK31 are incorporated only in the μPD780024A Subseries.

3.1 Port Pins (2/2)

Pin Name	I/O	Function	After Reset	Alternate Function
P70	I/O	Port 7 6-bit I/O port Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.	Input	T100/TO0
P71				T101
P72				T150/TO50
P73				T151/TO51
P74				PCL
P75				BUZ

3.2 Non-Port Pins (1/2)

Pin Name	I/O	Function	After Reset	Alternate Function
INTP0	Input	External interrupt request input for which the valid edge (rising edge, falling edge, or both rising and falling edges) can be specified	Input	P00
INTP2				P01
INTP2				P02
INTP3				P03/ADTRG
SI30	Input	Serial interface serial data input	Input	P20
SI31 ^{Note 1}				P34
SO30	Output	Serial interface serial data output	Input	P21
SO31 ^{Note 1}				P35
SDA0 ^{Note 2}	I/O	Serial Interface serial data input/output	Input	P32
SCK30	I/O	Serial interface serial clock input/output	Input	P22
SCK31 ^{Note 1}				P36
SCL0 ^{Note 2}				P33
RxD0	Input	Serial data input for asynchronous serial interface	Input	P23
TxD0	Output	Serial data output for asynchronous serial interface	Input	P24
ASCK0	Input	Serial clock input for asynchronous serial interface	Input	P25
TI00	Input	External count clock input to 16-bit timer/event counter 0	Input	P70/TO0
TI01		Capture trigger input to capture register 01 (CR01) of 16-bit timer/event counter 0		P71
TI50		External count clock input to 8-bit timer/event counter 50		P72/TO50
TI51		External count clock input to 8-bit timer/event counter 51		P73/TO51
TO0	Output	16-bit timer/event counter 0 output	Input	P70/TO0
TO50		8-bit timer/event counter 50 output (also used for 8-bit PWM output)		P72/TO50
TO51		8-bit timer/event counter 51 output (also used for 8-bit PWM output)		P73/TO51
PCL	Output	Clock output (for trimming of main system clock and subsystem clock)	Input	P74
BUZ	Output	Buzzer output	Input	P75
AD0 to AD7	I/O	Lower address/data bus for expanding memory externally	Input	P40 to P47
A8 to A15	Output	Higher address bus for expanding memory externally	Input	P50 to P57
RD	Output	Strobe signal output for reading from external memory	Input	P64
WR		Strobe signal output for writing to external memory		P65
WAIT	Input	Wait insertion at external memory access	Input	P66
ASTB	Output	Strobe output that externally latches address information output to ports 4 and 5 to access external memory	Input	P67

- Notes**
1. SI31, SO31, and SCK31 are incorporated only in the μPD780024A Subseries.
 2. SDA0 and SCL0 are incorporated only in the μPD780024AY Subseries.

3.2 Non-Port Pins (2/2)

Pin Name	I/O	Function	After Reset	Alternate Function
ANI0 to ANI7	Input	A/D converter analog input	Input	P10 to P17
ADTRG	Input	A/D converter trigger signal input	Input	P03/INTP3
AVREF	Input	A/D converter reference voltage input	—	—
AVDD	—	A/D converter analog power supply. Set potential to that of V _{DD0} or V _{DD1}	—	—
AVSS	—	A/D converter ground potential. Set potential to that of V _{SS0} or V _{SS1}	—	—
RESET	Input	System reset input	—	—
X1	Input	Connecting crystal resonator for main system clock oscillation	—	—
X2	—		—	—
XT1	Input	Connecting crystal resonator for subsystem clock oscillation	—	—
XT2	—		—	—
V _{DD0}	—	Positive power supply for ports	—	—
V _{SS0}	—	Ground potential of ports	—	—
V _{DD1}	—	Positive power supply (except ports)	—	—
V _{SS1}	—	Ground potential (except ports)	—	—
IC	—	Internally connected. Connect directly to V _{SS0} or V _{SS1} .	—	—
★ NC ^{Note}	—	Not internally connected. Leave open.	—	—

★ **Note** NC pins are incorporated only in the 73-pin plastic FBGA.

3.3 Pin I/O Circuits and Recommended Connection of Unused Pins

The I/O circuit type of each pin and recommended connection of unused pins are shown in Table 3-1. For the I/O circuit configuration of each type, see Figure 3-1.

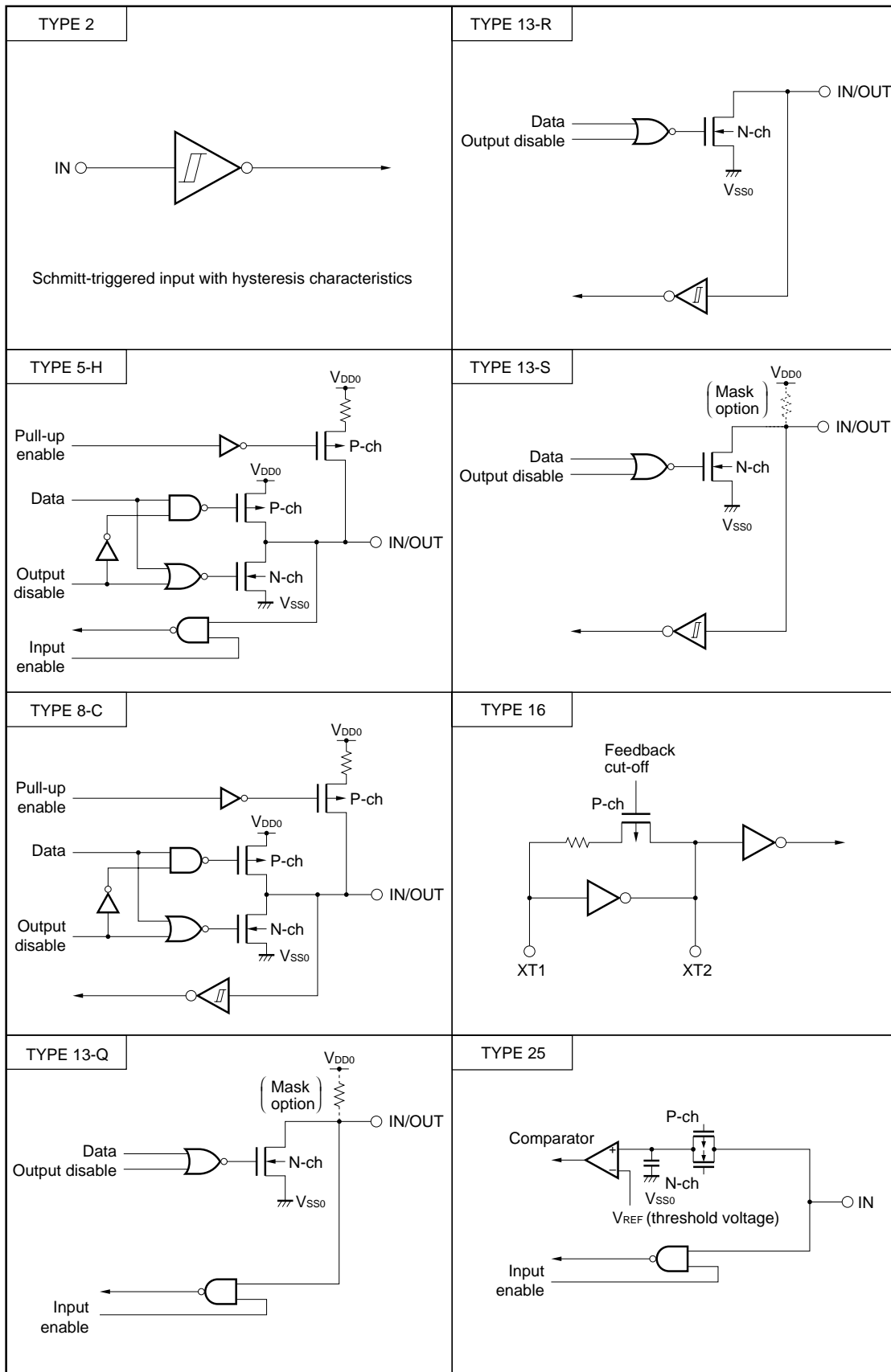
★

Table 3-1. Types of Pin I/O Circuits

Pin Name	I/O Circuit Type	I/O	Recommended Connection of Unused Pins	
P00/INTP0 to P02/INTP2	8-C	I/O	Input: Independently connect to V _{SS0} or V _{SS1} via a resistor. Output: Leave open.	
P03/INTP3/ADTRG				
P10/ANI0 to P17/ANI7	25	Input	Connect directly to V _{DD0} , V _{DD1} , V _{SS0} , or V _{SS1} via a resistor.	
P20/S130	8-C	I/O	Input: Independently connect to V _{DD0} , V _{DD1} , V _{SS0} , or V _{SS1} via a resistor. Output: Leave open.	
P21/SO30	5-H			
P22/SCK30	8-C			
P23/RxD0				
P24/TxD0	5-H			
P25/ASCK0	8-C			
P30, P31	13-Q			
P32, P33 (μPD780024A Subseries only)	13-S			
P32/SDA0 (μPD780024AY Subseries only)	13-R			
P33/SCL0 (μPD780024AY Subseries only)				
P34/SI31 ^{Note}	8-C	Input: Independently connect to V _{DD0} , V _{DD1} , V _{SS0} , or V _{SS1} via a resistor. Output: Leave open.		
P35/SO31 ^{Note}	5-H			
P36/SCK31 ^{Note}	8-C			
P40/AD0 to P47/AD7	5-H		Input: Independently connect to V _{DD0} or V _{DD1} via a resistor. Output: Leave open.	
P50/A8 to P57/A15				
P64/RD				
P65/WR				
P66/WAIT				
P67/ASTB				
P70/TI00/TO0		8-C		Input: Independently connect to V _{DD0} , V _{DD1} , V _{SS0} , or V _{SS1} via a resistor. Output: Leave open.
P71/TI01				
P72/TI50/TO50				
P73/TI51/TO51				
P74/PCL	5-H	Input: Independently connect to V _{DD0} , V _{DD1} , V _{SS0} , or V _{SS1} via a resistor. Output: Leave open.		
P75/BUZ				
RESET	2	Input	—	
XT1	16	—	Connect directly to V _{DD0} or V _{DD1} .	
XT2			Leave open.	
AV _{DD}	—	—	Connect to directly V _{DD0} or V _{DD1} .	
AV _{REF}			Connect to directly V _{SS0} or V _{SS1} .	
AV _{SS}				
IC				

Note SI31, SO31, and SCK31 are incorporated only in the μPD780024A Subseries.

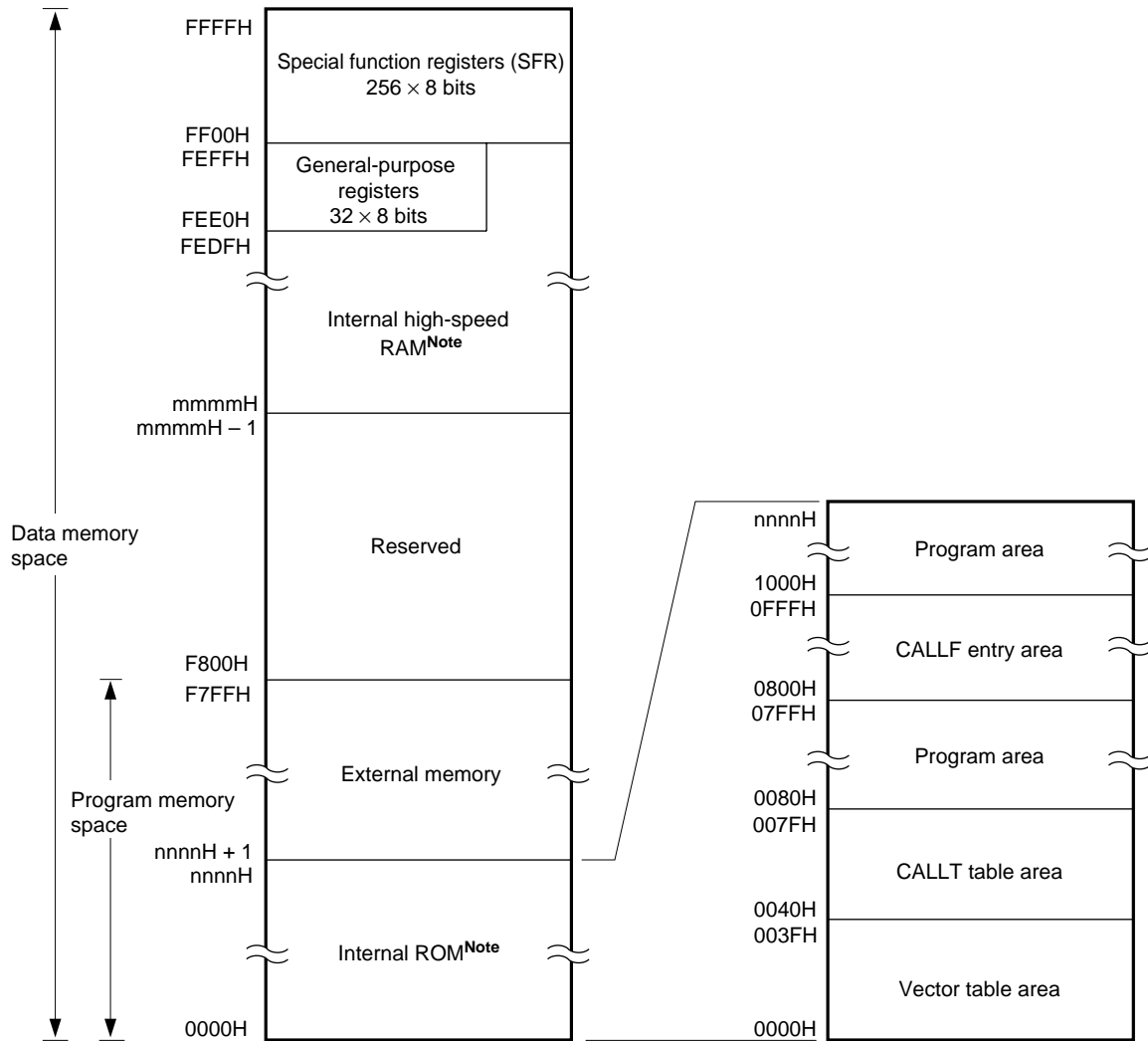
Figure 3-1. Pin I/O Circuits



4. MEMORY SPACE

Figure 4-1 shows the memory map of the μPD780021A, 780022A, 780023A, 780024A, 780021AY, 780022AY, 780023AY, and 780024AY.

Figure 4-1. Memory Map



Note The internal ROM and internal high-speed RAM capacities vary depending on the product (see the following table).

Part Number	Last Address of Internal ROM nnnnH	Start Address of Internal High-Speed RAM mmmmH
μPD780021A, 780021AY	1FFFH	FD00H
μPD780022A, 780022AY	3FFFH	
μPD780023A, 780023AY	5FFFH	FB00H
μPD780024A, 780024AY	7FFFH	

5. PERIPHERAL HARDWARE FUNCTION FEATURES

5.1 Ports

The following 3 types of I/O ports are available.

• CMOS input (port 1):	8
• CMOS I/O (ports 0, 2, 4 to 7, P34 to P36):	39
• N-channel open-drain I/O (P30 to P33):	4
Total:	51

Table 5-1. Port Functions

Name	Pin Name	Function
Port 0	P00 to P03	I/O port. Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.
Port 1	P10 to P17	Input-only port.
Port 2	P20 to P25	I/O port. Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.
Port 3	P30 to P33	N-channel open-drain I/O port. Input/output can be specified in 1-bit units. A pull-up resistor can be specified by mask option. LEDs can be driven directly.
	P34 to P36	I/O port. Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.
Port 4	P40 to P47	I/O port. Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software. The interrupt request flag (KRIF) is set to 1 by falling edge detection.
Port 5	P50 to P57	I/O port. Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software. LEDs can be driven directly.
Port 6	P64 to P67	I/O port. Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.
Port 7	P70 to P75	I/O port. Input/output can be specified in 1-bit units. An on-chip pull-up resistor can be used by setting software.

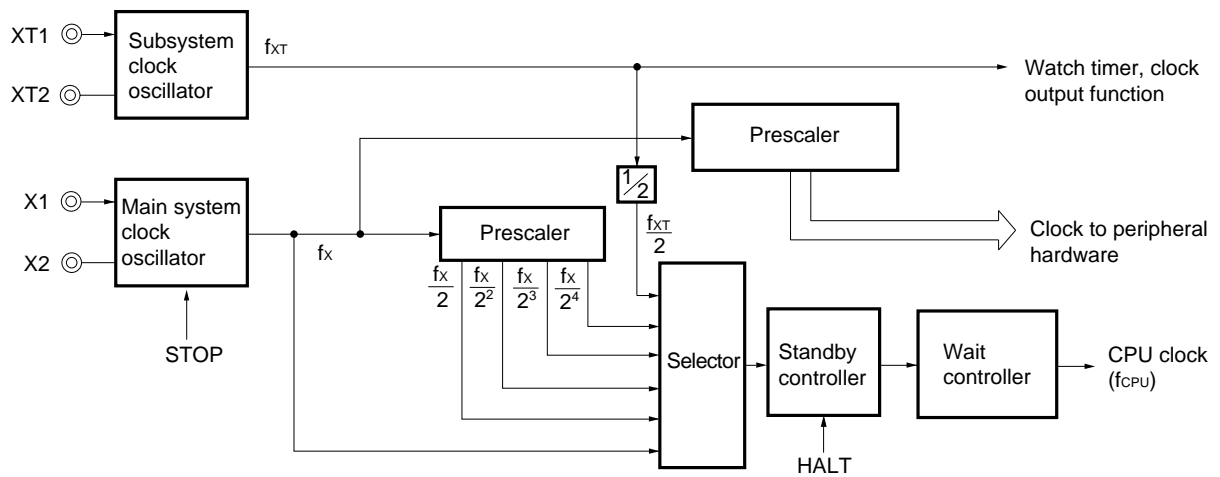
5.2 Clock Generator

A system clock generator is incorporated.

The minimum instruction execution time can be changed.

- ★
 - Expanded-specification products of μ PD780021A, 780022A, 780023A, 780024A
 0.166 μ s/0.333 μ s/0.666 μ s/1.33 μ s/2.66 μ s
 (@12 MHz, V_{DD} = 4.5 to 5.5 V operation with main system clock)
 122 μ s (@32.768 kHz, V_{DD} = 4.0 to 5.5 V operation with subsystem clock)
 - μ PD780021AY, 780022AY, 780023AY, 780024AY, and conventional products of μ PD780021A, 780022A, 780023A, 780024A
 0.238 μ s/0.48 μ s/0.95 μ s/1.91 μ s/3.81 μ s (@8.38 MHz, V_{DD} = 4.0 to 5.5 V operation with main system clock)
 122 μ s (@32.768 kHz, V_{DD} = 4.0 to 5.5 V operation with subsystem clock)

Figure 5-1. Clock Generator Block Diagram



5.3 Timer/Counter

Five timer/counter channels are incorporated.

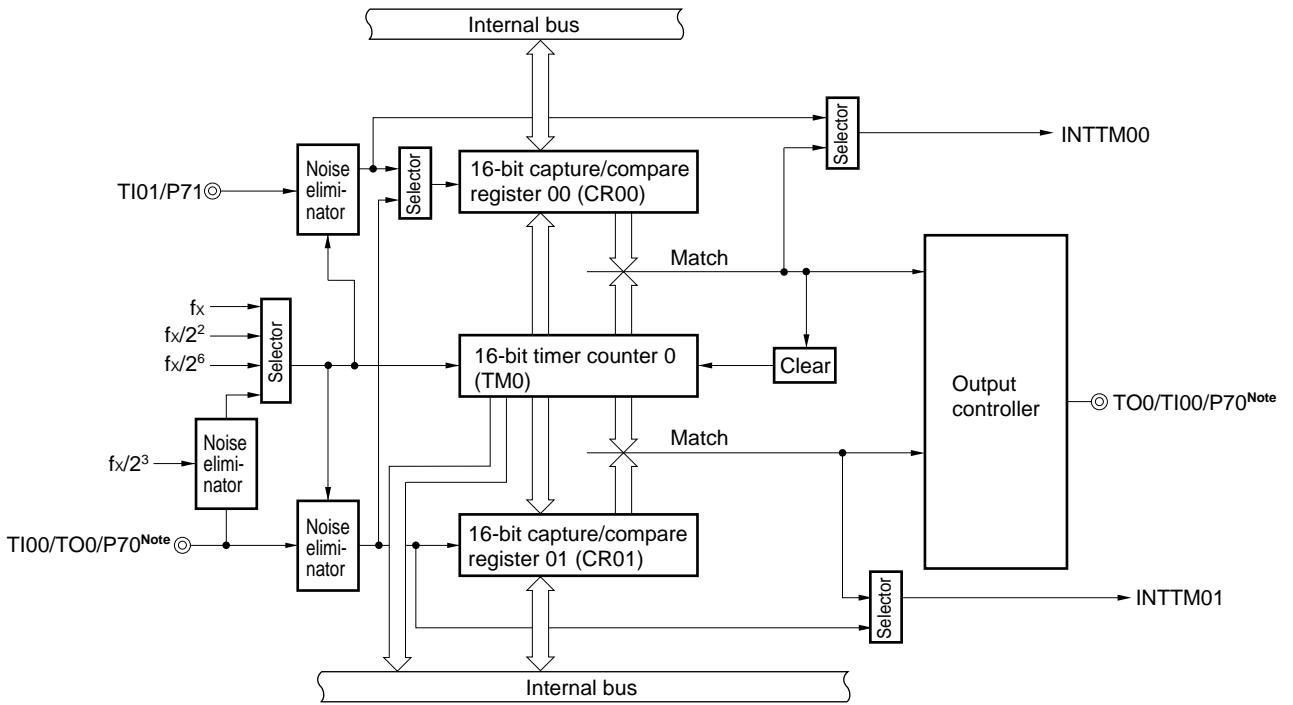
- 16-bit timer/event counter: 1 channel
- 8-bit timer/event counter: 2 channels
- Watch timer: 1 channel
- Watchdog timer: 1 channel

Table 5-2. Operations of Timer/Event Counter

	16-Bit Timer/ Event Counter 0	8-Bit Timer/ Event Counters 50, 51	Watch Timer	Watchdog Timer
Operation mode				
Interval timer	1 channel	2 channels	1 channel ^{Note 1}	1 channel ^{Note 2}
External event counter	1 channel	2 channels	—	—
Function				
Timer outputs	1	2	—	—
PPG outputs	1	—	—	—
PWM output	—	2	—	—
Pulse width measurement	2 inputs	—	—	—
Square wave outputs	1	2	—	—
Interrupt sources	2	2	2	1

- Notes**
1. The watch timer can perform both watch timer and interval timer functions at the same time.
 2. The watchdog timer has watchdog timer and interval timer functions. However, use the watchdog timer by selecting either the watchdog timer function or the interval timer function.

Figure 5-2. Block Diagram of 16-Bit Timer/Event Counter 0



★ **Note** TI00 input and TO0 output cannot be used at the same time.

Figure 5-3. Block Diagram of 8-Bit Timer/Event Counter 50

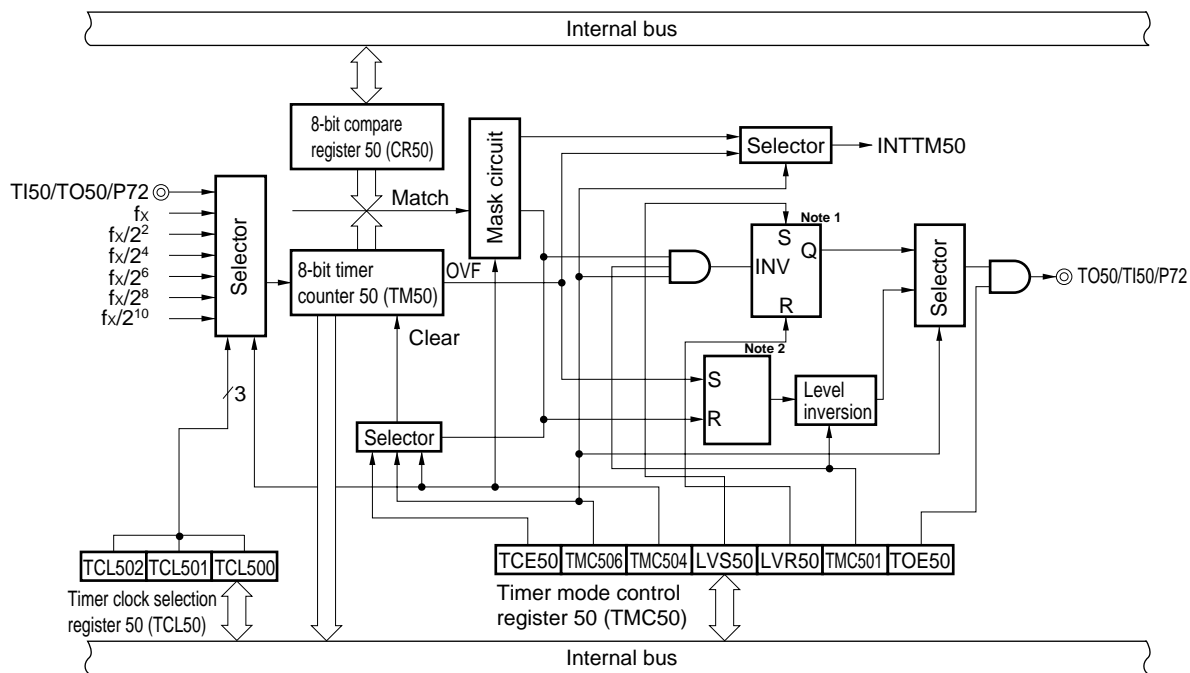
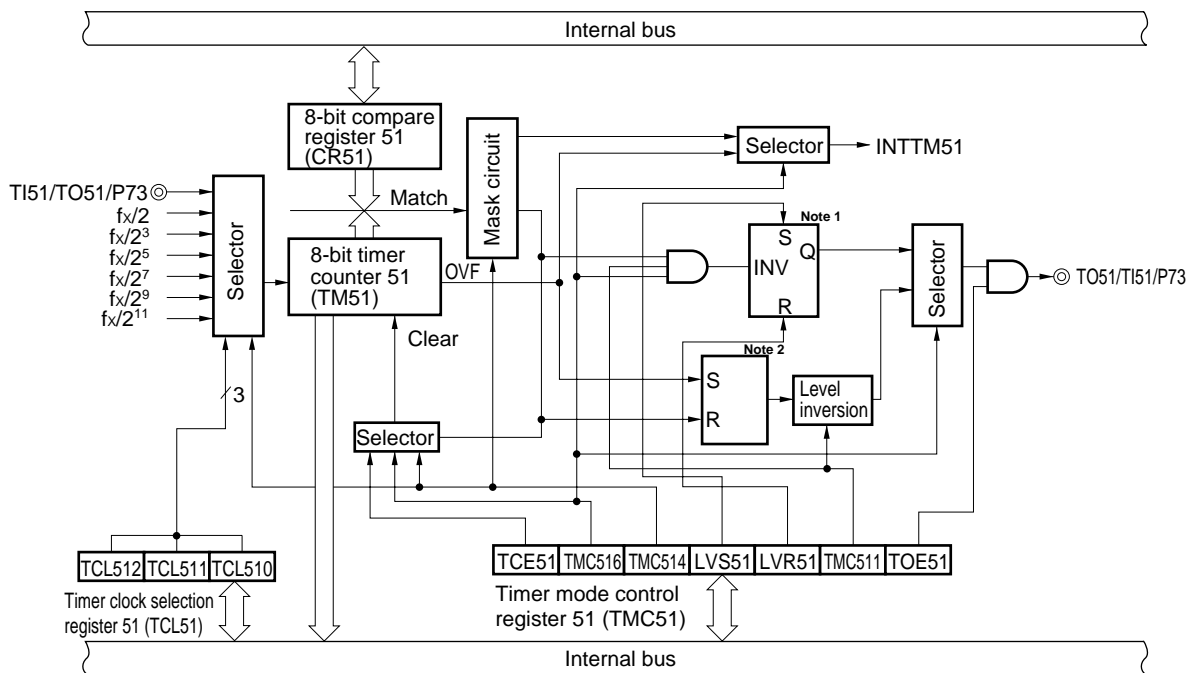


Figure 5-4. Block Diagram of 8-Bit Timer/Event Counter 51



- Notes**
1. Timer output F/F
 2. PWM output F/F

Figure 5-5. Watch Timer Block Diagram

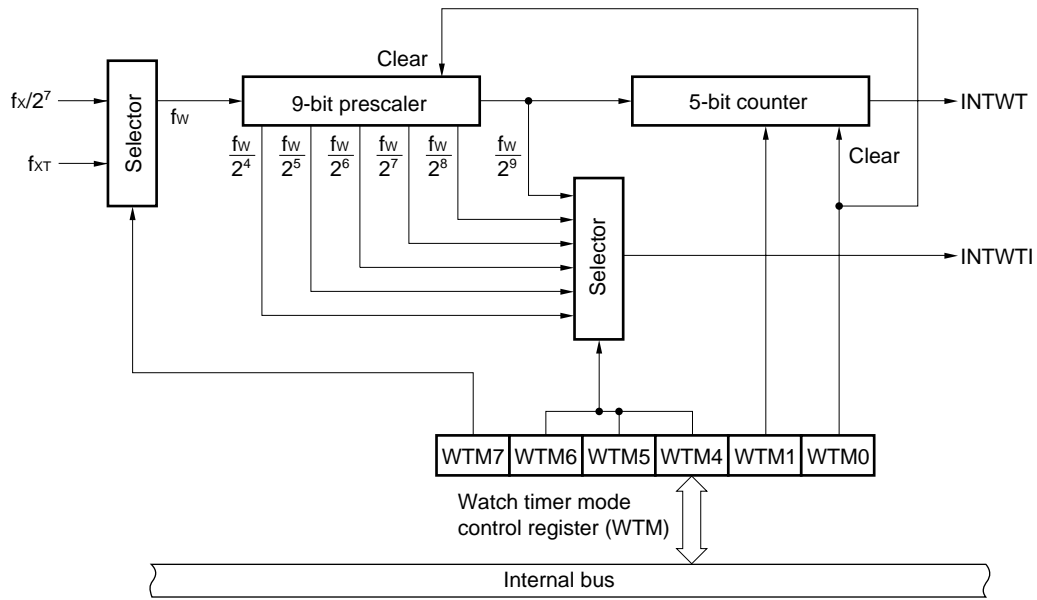
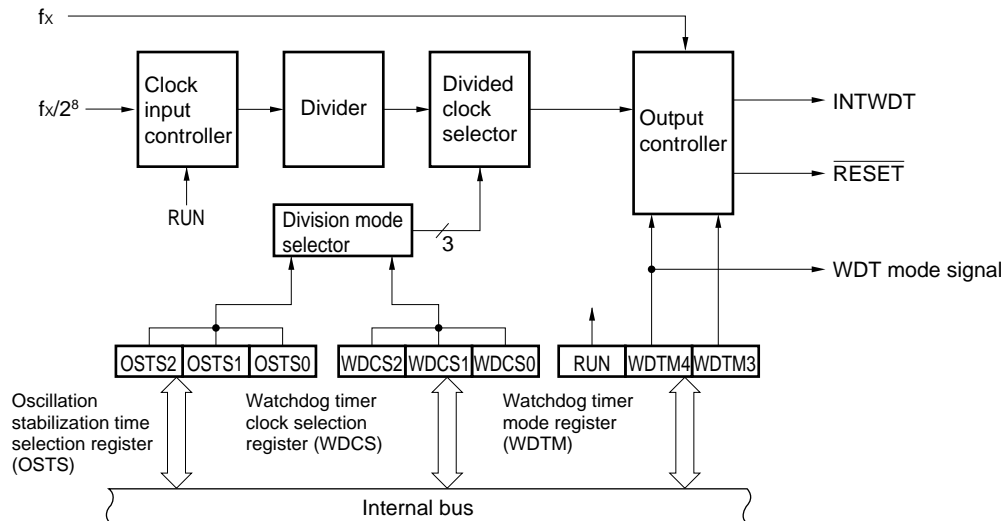


Figure 5-6. Watchdog Timer Block Diagram



5.4 Clock Output/Buzzer Output Controller

A clock output/buzzer output controller is incorporated.

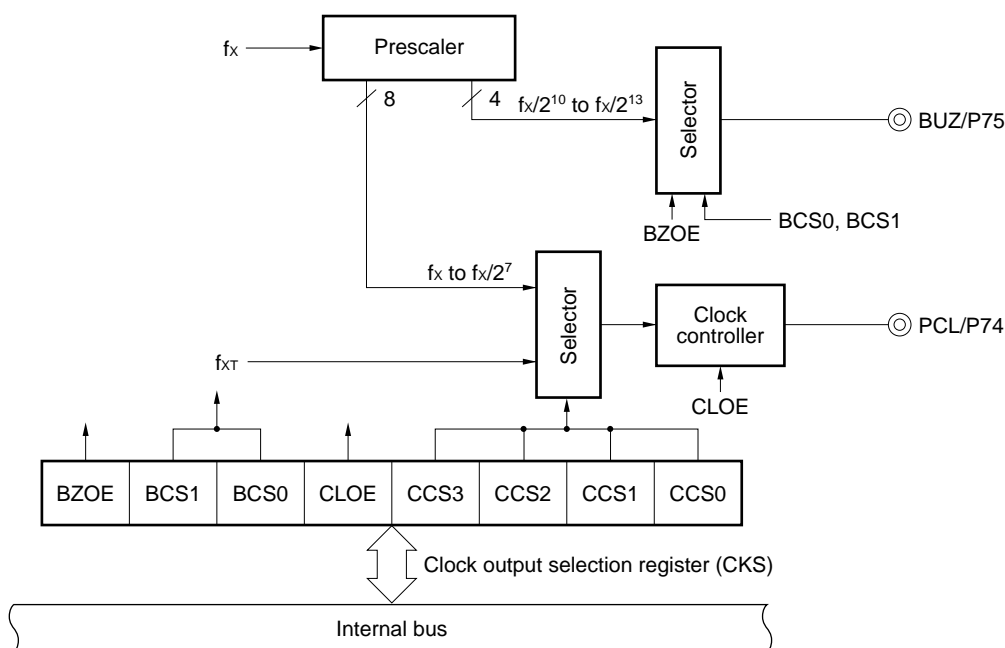
Clocks with the following frequencies can be output as clock output.

- ★ • **Expanded-specification products of μPD780021A, 780022A, 780023A, 780024A**
 - 93.75 kHz/187.5 kHz/375 kHz/750 kHz/1.25 MHz/3 MHz/6 MHz/12 MHz (@12 MHz operation with main system clock)
 - 32.768 kHz (@32.768 kHz operation with subsystem clock)
- **μPD780021AY, 780022AY, 780023AY, 780024AY, and conventional products of μPD780021A, 780022A, 780023A, 780024A**
 - 65.5 kHz/131 kHz/262 kHz/524 kHz/1.05 MHz/2.10 MHz/4.19 MHz/8.38 MHz (@8.38 MHz operation with main system clock)
 - 32.768 kHz (@32.768 kHz operation with subsystem clock)

Clocks with the following frequencies can be output as buzzer output.

- ★ • **Expanded-specification products of μPD780021A, 780022A, 780023A, 780024A**
 - 1.46 kHz/2.93 kHz/5.86 kHz/11.7 kHz (@12 MHz operation with main system clock)
- **μPD780021AY, 780022AY, 780023AY, 780024AY, and conventional products of μPD780021A, 780022A, 780023A, 780024A**
 - 1.02 kHz/2.05 kHz/4.10 kHz/8.19 kHz (@8.38 MHz operation with subsystem clock)

Figure 5-7. Block Diagram of Clock Output/Buzzer Output Control Circuit



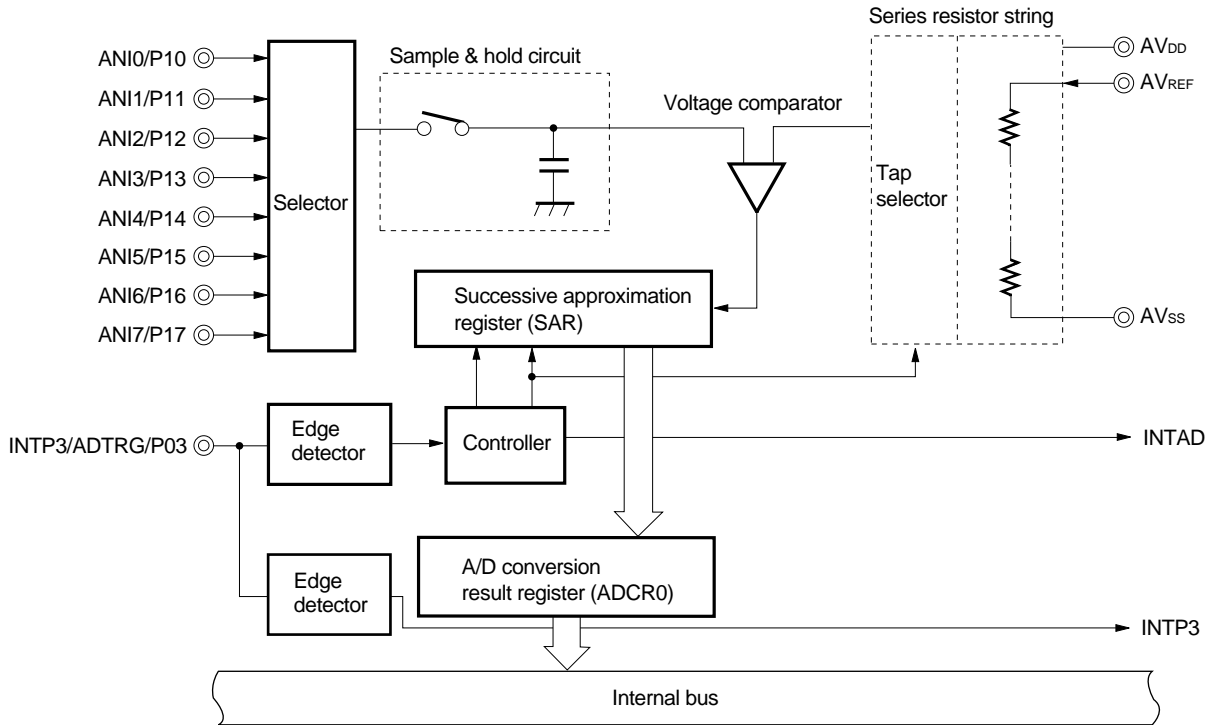
5.5 A/D Converter

An A/D converter consisting of eight 8-bit resolution channels is incorporated.

The following two A/D conversion operation startup methods are available.

- Hardware start
- Software start

Figure 5-8. A/D Converter Block Diagram



5.6 Serial Interface

Three serial interface channels are incorporated.

- μPD780024A Subseries
 - Serial interface UART0: 1 channel
 - Serial interface SIO30, SIO31: 2 channels
- μPD780024AY Subseries
 - Serial interface UART0: 1 channel
 - Serial interface SIO30: 1 channel
 - Serial interface IIC0 1 channel

(1) Serial interface UART0

Serial interface UART0 has two modes: asynchronous serial interface (UART) mode and infrared data transfer mode.

• **Asynchronous serial interface (UART) mode**

This mode enables full-duplex operation wherein one byte of data starting from the start bit is transmitted and received.

The on-chip UART-dedicated baud-rate generator enables communication using a wide range of selectable baud rates. In addition, a baud rate can also be defined by dividing the clock input to the ASCK0 pin.

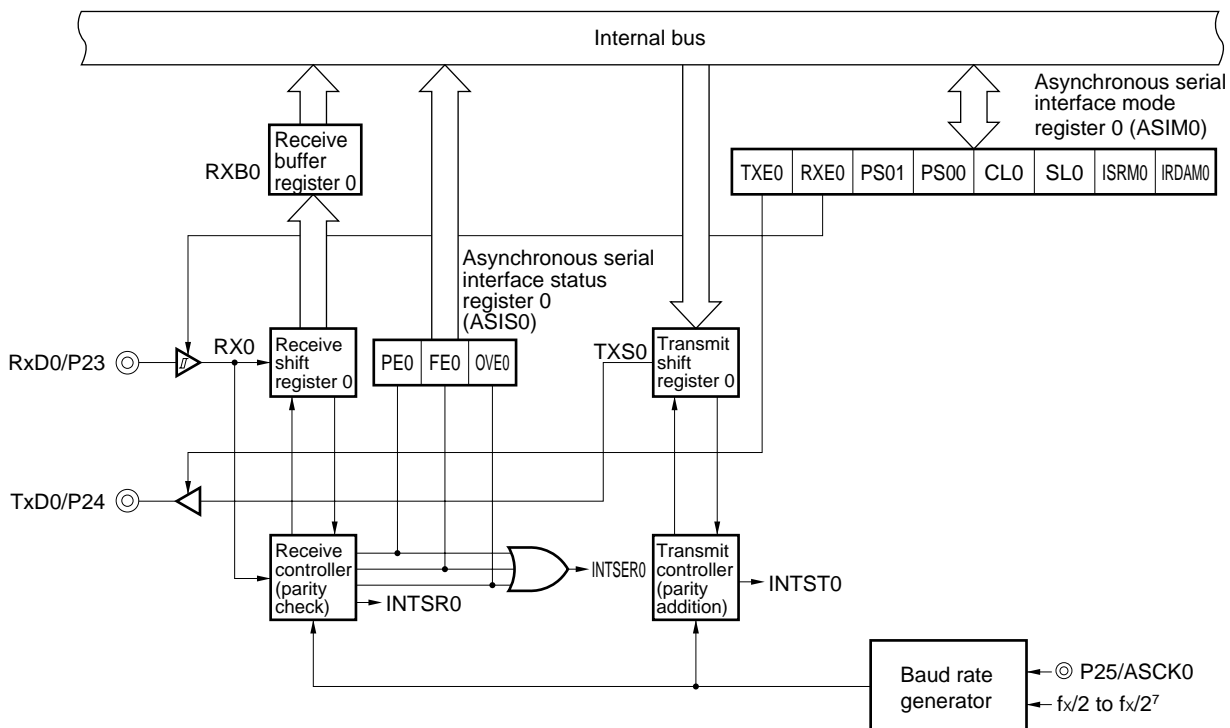
The UART-dedicated baud-rate generator can also be used to generate a MIDI-standard baud rate (31.25 kbps).

• **Infrared data transfer mode**

This mode enables pulse output and pulse reception in data format.

This mode can be used for office equipment applications such as personal computers.

Figure 5-9. Block Diagram of Serial Interface UART0



(2) Serial interface SIO3n

Serial interface SIO3n has one mode: 3-wire serial I/O mode.

- 3-wire serial I/O mode (fixed as MSB first)

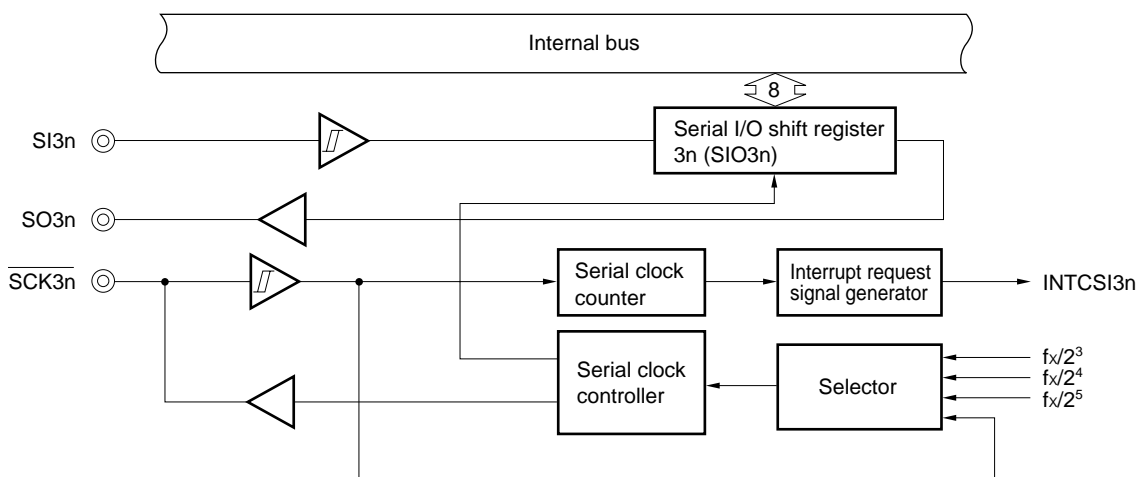
This is an 8-bit data transfer mode using three lines: a serial clock line ($\overline{SCK3n}$), serial output line (SO3n), and serial input line (SI3n).

Since simultaneous transmit and receive operations are enabled in the 3-wire serial I/O mode, the processing time for data transfer is reduced.

The first bit in 8-bit data in the serial transfer is fixed as MSB.

The 3-wire serial I/O mode is useful for connection to peripheral I/O devices, and display controllers, etc., that include a clocked serial interface.

Figure 5-10. Block Diagram of Serial Interface SIO3n



Remark μPD780024A Subseries: n = 0, 1
 μPD780024AY Subseries: n = 0

(3) Serial interface IIC0 (μPD780024AY Subseries only)

Serial interface IIC0 has one mode: I²C (Inter IC) bus mode (supporting multimaster).

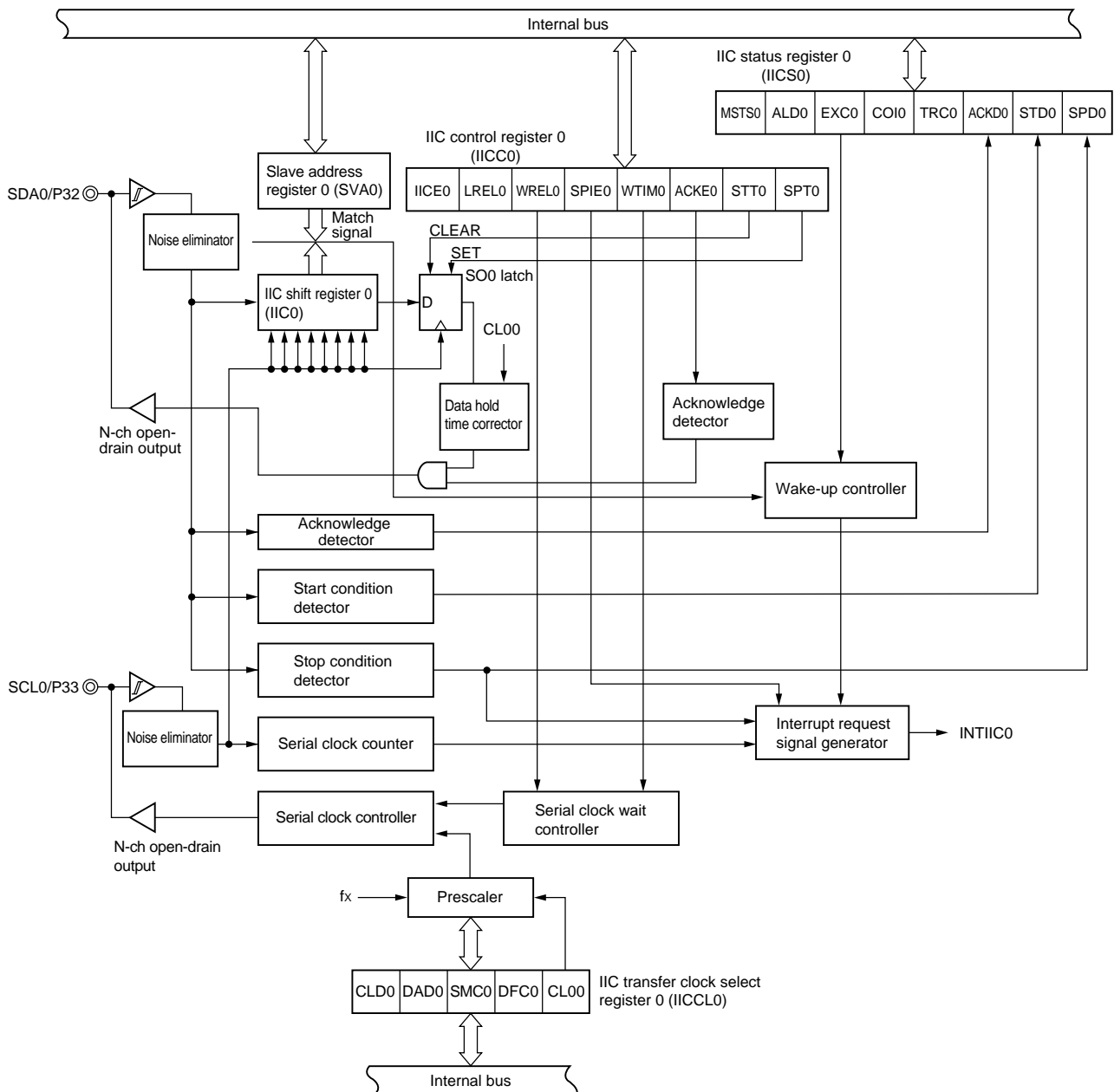
I²C bus mode (supporting multimaster)

This is an 8-bit data transfer mode using two lines: a serial clock line (SCL0) and a serial data bus line (SDA0).

This mode complies with the I²C bus format, and can output a “start condition”, “data”, and a “stop condition” during transmission via the serial data bus. This data is automatically detected by hardware during reception.

Since SCL0 and SDA0 are open-drain outputs in IIC0, pull-up resistors for the serial clock line and the serial data bus line are required.

Figure 5-11. Block Diagram of Serial Interface IIC0



6. INTERRUPT FUNCTIONS

A total of 20 interrupt sources are provided, divided into the following three types.

- Non-maskable: 1
- Maskable: 18
- Software: 1

Table 6-1. Interrupt Source List

Interrupt Type	Default Priority ^{Note 1}	Interrupt Source		Internal/External	Vector Table Address	Basic Configuration Type ^{Note 2}
		Name	Trigger			
Non-maskable	—	INTWDT	Watchdog timer overflow (with watchdog timer mode 1 selected)	Internal	0004H	(A)
Maskable	0	INTWDT	Watchdog timer overflow (with interval timer mode selected)			
	1	INTP0	Pin input edge detection	External	0006H	(C)
	2	INTP1			0008H	
	3	INTP2			000AH	
	4	INTP3			000CH	
	5	INTSER0	Serial interface UART0 reception error generation	Internal	000EH	(B)
	6	INTSR0	End of serial interface UART0 reception		0010H	
	7	INTST0	End of serial interface UART0 transmission		0012H	
	8	INTCSI30	End of serial interface SIO30 transfer		0014H	
	9	INTCSI31	End of serial interface SIO31 transfer [Only for μPD780024A Subseries]		0016H	
	10	INTIIC0	End of serial interface IIC0 transfer [Only for μPD780024AY Subseries]		0018H	
	11	INTWTI	Reference time interval signal from watch timer		001AH	
	12	INTTM00	Match between TM0 and CR00 (when CR00 is specified as compare register) Detection of TI01 valid edge (when CR00 is specified as capture register)		001CH	
	13	INTTM01	Match between TM0 and CR01 (when CR01 is specified as compare register) Detection of TI00 valid edge (when CR01 is specified as capture register)		001EH	
	14	INTTM50	Match between TM50 and CR50		0020H	
	15	INTTM51	Match between TM51 and CR51		0022H	
	16	INTAD0	End of A/D conversion		0024H	
	17	INTWT	Watch timer overflow		0026H	
	18	INTKR	Port 4 falling edge detection	External	0028H	(D)
Software	—	BRK	BRK instruction execution	—	003EH	(E)

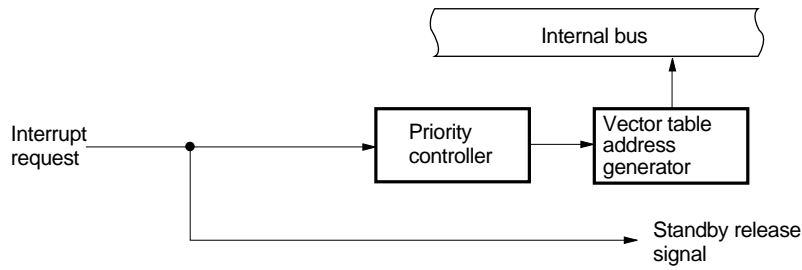
Notes 1. The default priority is the priority when several maskable interrupt requests are generated at the same time. 0 is the highest, and 18 is the lowest.

2. Basic configuration types (A) to (E) correspond to (A) to (E) in Figure 6-1.

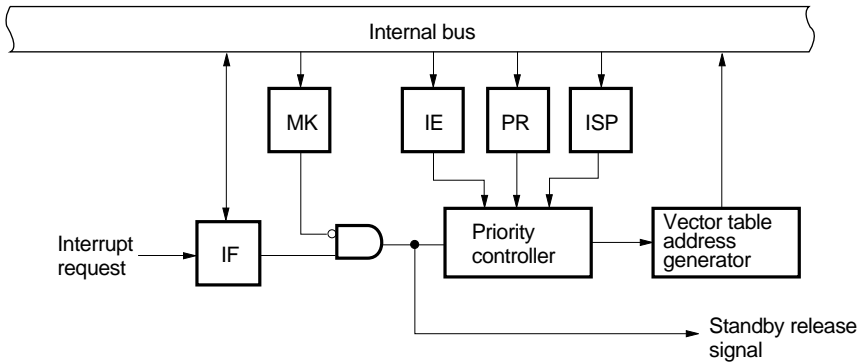
Remark The watchdog timer interrupt (INTWDT) can be selected from a non-maskable interrupt or a maskable interrupt (internal).

Figure 6-1. Basic Configuration of Interrupt Function (1/2)

(A) Internal non-maskable interrupt



(B) Internal maskable interrupt



(C) External maskable interrupt (INTP0 to INTP3)

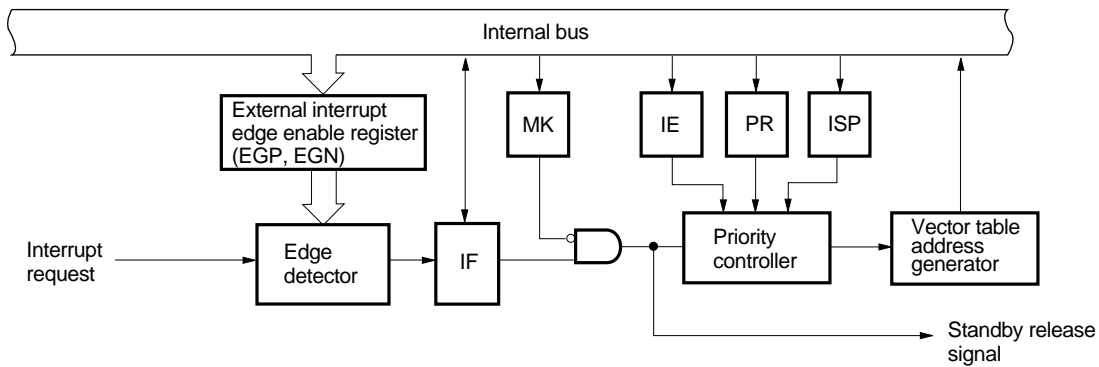
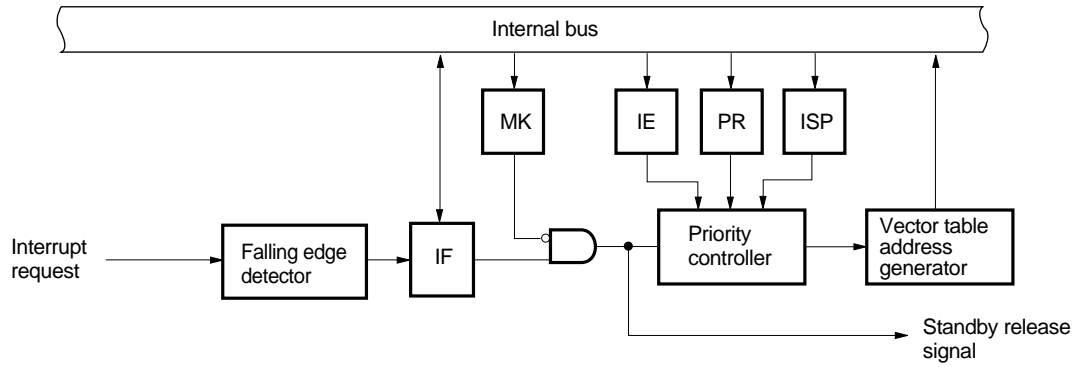
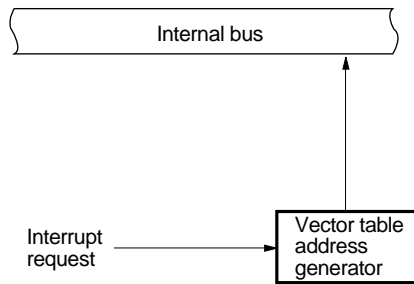


Figure 6-1. Basic Configuration of Interrupt Function (2/2)

(D) External maskable interrupt (INTKR)



(E) Software interrupt



- IF: Interrupt request flag
- IE: Interrupt enable flag
- ISP: In-service priority flag
- MK: Interrupt mask flag
- PR: Priority specification flag

7. EXTERNAL DEVICE EXPANSION FUNCTION

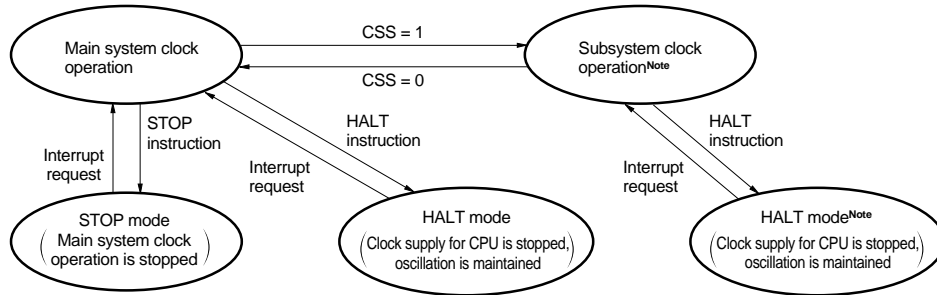
The external device expansion function is for connecting external devices to areas other than the internal ROM, RAM, and SFR areas. Ports 4 to 6 are used for external device connection.

8. STANDBY FUNCTION

The following two standby modes are available for further reduction of system power consumption.

- HALT mode: In this mode, the CPU operation clock is stopped. The average power consumption can be reduced by intermittent operation by combining this mode with the normal operation mode.
- STOP mode: In this mode, oscillation of the main system clock is stopped. All the operations performed on the main system clock are suspended, and only the subsystem clock is used, resulting in extremely small power consumption. This can be used only when the main system clock is operating (the subsystem clock oscillation cannot be stopped).

Figure 8-1. Standby Function



Note The power consumption can be reduced by stopping the main system clock. When the CPU is operating on the subsystem clock, set bit 7 (MCC) of the processor clock control register (PCC). The STOP instruction cannot be used.

Caution When the main system clock is stopped and the device is operating on the subsystem clock, wait until the oscillation stabilization time has been secured by the program before switching back to the main system clock.

9. RESET FUNCTION

The following two reset methods are available.

- External reset by $\overline{\text{RESET}}$ signal input
- Internal reset by watchdog timer program loop time detection

10. MASK OPTION

Table 10-1 Pin Mask Option Selection

Subseries Name	Pins	Mask Option
μPD780024A Subseries	P30 to P33	An on-chip pull-up resistor can be specified in 1-bit units.
μPD780024AY Subseries	P30 and P31	

The mask option can be used to specify the connection of an on-chip pull-up resistor to P30 to P33^{Note}, in 1-bit units.

Note The μPD780024AY Subseries has P30 and P31 only.

11. INSTRUCTION SET

(1) 8-bit instructions

MOV, XCH, ADD, ADDC, SUB, SUBC, AND, OR, XOR, CMP, MULU, DIVUW, INC, DEC, ROR, ROL, RORC, ROLC, ROR4, ROL4, PUSH, POP, DBNZ

2nd Operand 1st Operand	#byte	A	r ^{Note}	sfr	saddr	!addr16	PSW	[DE]	[HL]	[HL + byte] [HL + B] [HL + C]	\$addr16	1	None
A	ADD ADDC SUB SUBC AND OR XOR CMP		MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP	MOV XCH	MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP	MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP	MOV	MOV XCH	MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP	MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP		ROR ROL RORC ROLC	
r	MOV	MOV ADD ADDC SUB SUBC AND OR XOR CMP											INC DEC
B, C											DBNZ		
sfr	MOV	MOV											
saddr	MOV ADD ADDC SUB SUBC AND OR XOR CMP	MOV									DBNZ		INC DEC
!addr16		MOV											
PSW	MOV	MOV											PUSH POP
[DE]		MOV											
[HL]		MOV											ROR4 ROL4
[HL + byte] [HL + B] [HL + C]		MOV											
X													MULU
C													DIVUW

Note Except r = A

(2) 16-bit instructions

MOVW, XCHW, ADDW, SUBW, CMPW, PUSH, POP, INCW, DECW

2nd Operand 1st Operand	#word	AX	rp ^{Note}	sfrp	saddrp	!addr16	SP	None
AX	ADDW SUBW CMPW		MOVW XCHW	MOVW	MOVW	MOVW	MOVW	
rp	MOVW	MOVW ^{Note}						INCW, DECW PUSH, POP
sfrp	MOVW	MOVW						
saddrp	MOVW	MOVW						
!addr16		MOVW						
SP	MOVW	MOVW						

Note Only when rp = BC, DE or HL

(3) Bit manipulation instructions

MOV1, AND1, OR1, XOR1, SET1, CLR1, NOT1, BT, BF, BTCLR

2nd Operand 1st Operand	A.bit	sfr.bit	saddr.bit	PSW.bit	[HL].bit	CY	\$addr16	None
A.bit						MOV1	BT BF BTCLR	SET1 CLR1
sfr.bit						MOV1	BT BF BTCLR	SET1 CLR1
saddr.bit						MOV1	BT BF BTCLR	SET1 CLR1
PSW.bit						MOV1	BT BF BTCLR	SET1 CLR1
[HL].bit						MOV1	BT BF BTCLR	SET1 CLR1
CY	MOV1 AND1 OR1 XOR1	MOV1 AND1 OR1 XOR1	MOV1 AND1 OR1 XOR1	MOV1 AND1 OR1 XOR1	MOV1 AND1 OR1 XOR1			SET1 CLR1 NOT1

(4) Call instructions/branch instructions

CALL, CALLF, CALLT, BR, BC, BNC, BZ, BNZ, BT, BF, BTCLR, DBNZ

2nd Operand 1st Operand	AX	!addr16	!addr11	[addr5]	\$addr16
Basic instruction	BR	CALL BR	CALLF	CALLT	BR, BC, BNC BZ, BNZ
Compound instruction					BT, BF BTCLR DBNZ

(5) Other instructions

ADJBA, ADJBS, BRK, RET, RETI, RETB, SEL, NOP, EI, DI, HALT, STOP

★ 12. ELECTRICAL SPECIFICATIONS

12.1 Expanded-Specification Products of μPD780021A, 780022A, 780023A, 780024A

Absolute Maximum Ratings (T_A = 25°C)

Parameter	Symbol	Conditions		Ratings	Unit	
Supply voltage	V _{DD}			-0.3 to +6.5	V	
	AV _{DD}			-0.3 to V _{DD} + 0.3 ^{Note}	V	
	AV _{REF}			-0.3 to V _{DD} + 0.3 ^{Note}	V	
	AV _{SS}			-0.3 to +0.3	V	
Input voltage	V _{I1}	P00 to P03, P10 to P17, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75, X1, X2, XT1, XT2, RESET		-0.3 to V _{DD} + 0.3 ^{Note}	V	
	V _{I2}	P30 to P33	N-ch open-drain	Without pull-up resistor	-0.3 to + 6.5	V
				With pull-up resistor	-0.3 to V _{DD} + 0.3 ^{Note}	V
Output voltage	V _O			-0.3 to V _{DD} + 0.3 ^{Note}	V	
Analog input voltage	V _{AN}	P10 to P17	Analog input pin	AV _{SS} - 0.3 to AV _{REF0} + 0.3 ^{Note} and -0.3 to V _{DD} + 0.3 ^{Note}	V	
Output current, high	I _{OH}	Per pin		-10	mA	
		Total for P00 to P03, P40 to P47, P50 to P57, P64 to P67, P70 to P75		-15	mA	
		Total for P20 to P25, P30 to P36		-15	mA	
Output current, low	I _{OL}	Per pin for P00 to P03, P20 to P25, P34 to P36, P40 to P47, P64 to P67, P70 to P75		20	mA	
		Per pin for P30 to P33, P50 to P57		30	mA	
		Total for P00 to P03, P40 to P47, P64 to P67, P70 to P75		50	mA	
		Total for P20 to P25		20	mA	
		Total for P30 to P36		100	mA	
		Total for P50 to P57		100	mA	
Operating ambient temperature	T _A			-40 to +85	°C	
Storage temperature	T _{stg}			-65 to +150	°C	

Note 6.5 V or below

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

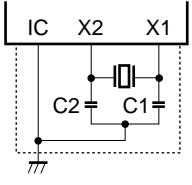
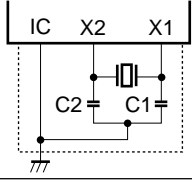
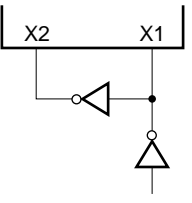
Remark Unless otherwise specified, the characteristic of alternate-function pins are the same as those of port pins.

Capacitance (T_A = 25°C, V_{DD} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input capacitance	C _{IN}	f = 1 MHz Unmeasured pins returned to 0 V.			15	pF
I/O capacitance	C _{IO}	f = 1 MHz Unmeasured pins returned to 0 V.	P00 to P03, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75		15	pF
			P30 to P33		20	pF

Remark Unless otherwise specified, the characteristic of alternate-function pins are the same as those of port pins.

Main System Clock Oscillator Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
Ceramic resonator		Oscillation frequency (f _x) ^{Note 1}	4.5 V ≤ V _{DD} ≤ 5.5 V	1.0		12.0	MHz
			3.0 V ≤ V _{DD} < 4.5 V	1.0		8.38	
			1.8 V ≤ V _{DD} < 3.0 V	1.0		5.0	
		Oscillation stabilization time ^{Note 2}	After V _{DD} reaches oscillation voltage range MIN.			4	ms
Crystal resonator		Oscillation frequency (f _x) ^{Note 1}	4.5 V ≤ V _{DD} ≤ 5.5 V	1.0		12.0	MHz
			3.0 V ≤ V _{DD} < 4.5 V	1.0		8.38	
			1.8 V ≤ V _{DD} < 3.0 V	1.0		5.0	
		Oscillation stabilization time ^{Note 2}	4.0 V ≤ V _{DD} ≤ 5.5 V			10	ms
			1.8 V ≤ V _{DD} < 4.0 V			30	
External clock		X1 input frequency (f _x) ^{Note 1}	4.5 V ≤ V _{DD} ≤ 5.5 V	1.0		12.0	MHz
			3.0 V ≤ V _{DD} < 4.5 V	1.0		8.38	
			1.8 V ≤ V _{DD} < 3.0 V	1.0		5.0	
		X1 input high-/low-level width (t _{xH} , t _{xL})	4.5 V ≤ V _{DD} ≤ 5.5 V	38		500	ns
			3.0 V ≤ V _{DD} < 4.5 V	50		500	
	1.8 V ≤ V _{DD} < 3.0 V	85		500			

Notes 1. Indicates only oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.

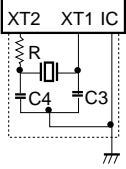
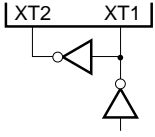
2. Time required to stabilize oscillation after reset or STOP mode release.

Cautions 1. When using the main system clock oscillator, wire as follows in the area enclosed by the broken lines in the above figures to avoid an adverse effect from wiring capacitance.

- Keep the wiring length as short as possible.
- Do not cross the wiring with the other signal lines.
- Do not route the wiring near a signal line through which a high fluctuating current flows.
- Always make the ground point of the oscillator capacitor the same potential as V_{SS1}.
- Do not ground the capacitor to a ground pattern through which a high current flows.
- Do not fetch signals from the oscillator.

2. When the main system clock is stopped and the system is operating on the subsystem clock, wait until the oscillation stabilization time has been secured by the program before switching back to the main system clock.

Subsystem Clock Oscillator Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
Crystal resonator		Oscillation frequency (f _{XT}) ^{Note 1}		32	32.768	35	kHz
		Oscillation stabilization time ^{Note 2}	4.0 V ≤ V _{DD} ≤ 5.5 V		1.2	2	s
			1.8 V ≤ V _{DD} < 4.0 V			10	
External clock		XT1 input frequency (f _{XT}) ^{Note 1}		32		38.5	kHz
		XT1 input high-/low-level width (t _{XTH} , t _{XTL})		12		15	μs

Notes 1. Indicates only oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.

2. Time required to stabilize oscillation after V_{DD} reaches oscillation voltage range MIN.

Cautions 1. When using the subsystem clock oscillator, wire as follows in the area enclosed by the broken lines in the above figures to avoid an adverse effect from wiring capacitance.

- Keep the wiring length as short as possible.
- Do not cross the wiring with the other signal lines.
- Do not route the wiring near a signal line through which a high fluctuating current flows.
- Always make the ground point of the oscillator capacitor the same potential as V_{SS1}.
- Do not ground the capacitor to a ground pattern through which a high current flows.
- Do not fetch signals from the oscillator.

2. The subsystem clock oscillator is designed as a low-amplitude circuit for reducing power consumption, and is more prone to malfunction due to noise than the main system clock oscillator. Particular care is therefore required with the wiring method when the subsystem clock is used.

Remark For the resonator selection and oscillator constant, customers are required to either evaluate the oscillation themselves or apply to the resonator manufacturer for evaluation.

Recommended Oscillator Constant

Main system clock: Ceramic resonator ($T_A = -40$ to $+85^\circ\text{C}$)

Manufacturer	Part Number	Frequency (MHz)	Recommended Circuit Constant			Oscillation Voltage Range	
			C1 (pF)	C2 (pF)	R1 (k Ω)	MIN. (V)	MAX. (V)
Murata Mfg. Co., Ltd.	CSBFB1M00J58	1.00	100	100	2.2	1.8	5.5
	CSBLA1M00J58	1.00	100	100	2.2	1.8	5.5
	CSTCC2M00G56	2.00	On-chip	On-chip	0	1.8	5.5
	CSTLS2M00G56	2.00	On-chip	On-chip	0	1.8	5.5
	CSTCC3M58G53	3.58	On-chip	On-chip	0	1.8	5.5
	CSTLS3M58G53	3.58	On-chip	On-chip	0	1.8	5.5
	CSTCR4M00G53	4.00	On-chip	On-chip	0	1.8	5.5
	CSTLS4M00G53	4.00	On-chip	On-chip	0	1.8	5.5
	CSTCR4M19G53	4.19	On-chip	On-chip	0	1.8	5.5
	CSTLS4M19G53	4.19	On-chip	On-chip	0	1.8	5.5
	CSTCR4M91G53	4.91	On-chip	On-chip	0	1.8	5.5
	CSTLS4M91G53	4.91	On-chip	On-chip	0	1.8	5.5
	CSTCR5M00G53	5.00	On-chip	On-chip	0	1.8	5.5
	CSTLS5M00G53	5.00	On-chip	On-chip	0	1.8	5.5
	CSTCE8M00G52	8.00	On-chip	On-chip	0	3.0	5.5
	CSTLS8M00G53	8.00	On-chip	On-chip	0	3.0	5.5
	CSTCE8M38G52	8.38	On-chip	On-chip	0	3.0	5.5
	CSTLS8M38G53	8.38	On-chip	On-chip	0	3.0	5.5
	CSTCE10M0G52	10.00	On-chip	On-chip	0	4.5	5.5
	CSTLS10M0G53	10.00	On-chip	On-chip	0	4.5	5.5
CSTCE12M0G52	12.00	On-chip	On-chip	0	4.5	5.5	
CSTLA12M0T55	12.00	On-chip	On-chip	0	4.5	5.5	
TDK	CCR3.58MC3	3.58	On-chip	On-chip	0	1.8	5.5
	CCR4.19MC3	4.19	On-chip	On-chip	0	1.8	5.5
	CCR5.0MC3	5.00	On-chip	On-chip	0	1.8	5.5
	CCR8.0MC5	8.00	On-chip	On-chip	0	2.0	5.5
	CCR8.38MC5	8.38	On-chip	On-chip	0	2.0	5.5

Caution The oscillator constant is a reference value based on evaluation in specific environments by the resonator manufacturer. If the oscillator characteristics need to be optimized in the actual application, request the resonator manufacturer for evaluation on the implementation circuit. Note that the oscillation voltage and oscillation frequency merely indicate the characteristics of the oscillator. Use the internal operation conditions of the μ PD780024A Subseries within the specifications of the DC and AC characteristics.

DC Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Output current, high	I _{OH}	Per pin				-1	mA
		All pins				-15	mA
Output current, low	I _{OL}	Per pin for P00 to P03, P20 to P25, P34 to P36, P40 to P47, P64 to P67, P70 to P75				10	mA
		Per pin for P30 to P33, P50 to P57				15	mA
		Total for P00 to P03, P40 to P47, P64 to P67, P70 to P75				20	mA
		Total for P20 to P25				10	mA
		Total for P30 to P36				70	mA
		Total for P50 to P57				70	mA
Input voltage, high	V _{IH1}	P10 to P17, P21, P24, P35, P40 to P47, P50 to P57, P64 to P67, P74, P75	2.7 V ≤ V _{DD} ≤ 5.5 V	0.7V _{DD}		V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0.8V _{DD}		V _{DD}	V
	V _{IH2}	P00 to P03, P20, P22, P23, P25, P34, P36, P70 to P73, RESET	2.7 V ≤ V _{DD} ≤ 5.5 V	0.8V _{DD}		V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0.85V _{DD}		V _{DD}	V
	V _{IH3}	P30 to P33 (N-ch open-drain)	2.7 V ≤ V _{DD} ≤ 5.5 V	0.7V _{DD}		5.5	V
			1.8 V ≤ V _{DD} < 2.7 V	0.8V _{DD}		5.5	V
	V _{IH4}	X1, X2	2.7 V ≤ V _{DD} ≤ 5.5 V	V _{DD} - 0.5		V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	V _{DD} - 0.2		V _{DD}	V
	V _{IH5}	XT1, XT2	4.0 V ≤ V _{DD} ≤ 5.5 V	0.8V _{DD}		V _{DD}	V
			1.8 V ≤ V _{DD} < 4.0 V	0.9V _{DD}		V _{DD}	V
Input voltage, low	V _{IL1}	P10 to P17, P21, P24, P35, P40 to P47, P50 to P57, P64 to P67, P74, P75	2.7 V ≤ V _{DD} ≤ 5.5 V	0		0.3V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0		0.2V _{DD}	V
	V _{IL2}	P00 to P03, P20, P22, P23, P25, P34, P36, P70 to P73, RESET	2.7 V ≤ V _{DD} ≤ 5.5 V	0		0.2V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0		0.15V _{DD}	V
	V _{IL3}	P30 to P33	4.0 V ≤ V _{DD} ≤ 5.5 V	0		0.3V _{DD}	V
			2.7 V ≤ V _{DD} < 4.0 V	0		0.2V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0		0.1V _{DD}	V
	V _{IL4}	X1, X2	2.7 V ≤ V _{DD} ≤ 5.5 V	0		0.4	V
			1.8 V ≤ V _{DD} < 2.7 V	0		0.2	V
	V _{IL5}	XT1, XT2	4.0 V ≤ V _{DD} ≤ 5.5 V	0		0.2V _{DD}	V
1.8 V ≤ V _{DD} < 4.0 V			0		0.1V _{DD}	V	
Output voltage, high	V _{OH1}	4.0 V ≤ V _{DD} ≤ 5.5 V, I _{OH} = -1 mA		V _{DD} - 1.0		V _{DD}	V
		1.8 V ≤ V _{DD} < 4.0 V, I _{OH} = -100 μA		V _{DD} - 0.5		V _{DD}	V
Output voltage, low	V _{OL1}	P30 to P33	4.0 V ≤ V _{DD} ≤ 5.5 V,			2.0	V
		P50 to P57	I _{OL} = 15 mA		0.4	2.0	V
		P00 to P03, P20 to P25, P34 to P36, P40 to P47, P64 to P67, P70 to P75	4.0 V ≤ V _{DD} ≤ 5.5 V, I _{OL} = 1.6 mA			0.4	V
	V _{OL2}	I _{OL} = 400 μA				0.5	V

Remark Unless otherwise specified, the characteristics of alternate-function pins are the same as those of port pins.

DC Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Input leakage current, high	I _{LIH1}	V _{IN} = V _{DD}	P00 to P03, P10 to P17, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P60 to P67, P70 to P75, <u>RESET</u>			3	μA
	I _{LIH2}		X1, X2, XT1, XT2			20	μA
	I _{LIH3}	V _{IN} = 5.5 V	P30 to P33 ^{Note}			3	μA
Input leakage current, low	I _{LIL1}	V _{IN} = 0 V	P00 to P03, P10 to P17, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75, <u>RESET</u>			-3	μA
	I _{LIL2}		X1, X2, XT1, XT2			-20	μA
	I _{LIL3}		P30 to P33 ^{Note}			-3	μA
Output leakage current, high	I _{LOH}	V _{OUT} = V _{DD}				3	μA
Output leakage current, low	I _{LOL}	V _{OUT} = 0 V				-3	μA
Mask option pull-up resistance	R ₁	V _{IN} = 0 V, P30, P31, P32, P33		15	30	90	kΩ
Software pull-up resistance	R ₂	V _{IN} = 0 V, P00 to P03, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75		15	30	90	kΩ

Note When pull-up resistors are not connected to P30 to P33 (specified by the mask option).

Remark Unless otherwise specified, the characteristics of alternate-function pins are the same as those of port pins.

DC Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit		
Power supply current ^{Note 1}	I _{DD1} ^{Note 2}	12.0 MHz crystal oscillation operating mode	V _{DD} = 5.0 V ±10% ^{Note 3}	When A/D converter is stopped		8.5	17	mA	
				When A/D converter is operating ^{Note 7}		9.5	19	mA	
		8.38 MHz crystal oscillation operating mode	V _{DD} = 5.0 V ±10% ^{Note 3}	When A/D converter is stopped		5.5	11	mA	
				When A/D converter is operating ^{Note 7}		6.5	13	mA	
			V _{DD} = 3.0 V + 10% ^{Notes 3, 6}	When A/D converter is stopped		3	6	mA	
				When A/D converter is operating ^{Note 7}		4	8	mA	
		5.00 MHz crystal oscillation operating mode	V _{DD} = 3.0 V ±10% ^{Note 3}	When A/D converter is stopped		2	4	mA	
				When A/D converter is operating ^{Note 7}		3	6	mA	
			V _{DD} = 2.0 V ±10% ^{Note 4}	When A/D converter is stopped		0.4	1.5	mA	
				When A/D converter is operating ^{Note 7}		1.4	4.2	mA	
		I _{DD2}	12.0 MHz crystal oscillation HALT mode	V _{DD} = 5.0 V ±10% ^{Note 3}	When peripheral functions are stopped		2	4	mA
					When peripheral functions are operating			10	mA
	8.38 MHz crystal oscillation HALT mode		V _{DD} = 5.0 V ±10% ^{Note 3}	When peripheral functions are stopped		1.1	2.2	mA	
				When peripheral functions are operating			4.7	mA	
			V _{DD} = 3.0 V + 10% ^{Notes 3, 6}	When peripheral functions are stopped		0.5	1	mA	
	5.00 MHz crystal oscillation HALT mode		V _{DD} = 3.0 V ±10% ^{Note 3}	When peripheral functions are stopped		0.35	0.7	mA	
				When peripheral functions are operating			1.7	mA	
			V _{DD} = 2.0 V ±10% ^{Note 4}	When peripheral functions are stopped		0.15	0.4	mA	
				When peripheral functions are operating			1.1	mA	
	I _{DD3}		32.768 kHz crystal oscillation operating mode ^{Note 5}	V _{DD} = 5.0 V ±10%		40	80	μA	
V _{DD} = 3.0 V ±10%					20	40	μA		
V _{DD} = 2.0 V ±10%					10	20	μA		
I _{DD4}	32.768 kHz crystal oscillation HALT mode ^{Note 5}	V _{DD} = 5.0 V ±10%		30	60	μA			
		V _{DD} = 3.0 V ±10%		6	18	μA			
		V _{DD} = 2.0 V ±10%		2	10	μA			
I _{DD5}	XT1 = V _{DD} STOP mode When feedback resistor is not used	V _{DD} = 5.0 V ±10%		0.1	30	μA			
		V _{DD} = 3.0 V ±10%		0.05	10	μA			
		V _{DD} = 2.0 V ±10%		0.05	10	μA			

- Notes**
1. Total current through the internal power supply (V_{DD0} , V_{DD1}) (except the current through pull-up resistors of ports).
 2. I_{DD1} includes the peripheral operation current.
 3. When the processor clock control register (PCC) is set to 00H.
 4. When PCC is set to 02H.
 5. When main system clock operation is stopped.
 6. The values show the specifications when $V_{DD} = 3.0$ to 3.3 V. The value in the TYP. column show the specifications when $V_{DD} = 3.0$ V.
 7. Includes the current through the AV_{DD} pin.

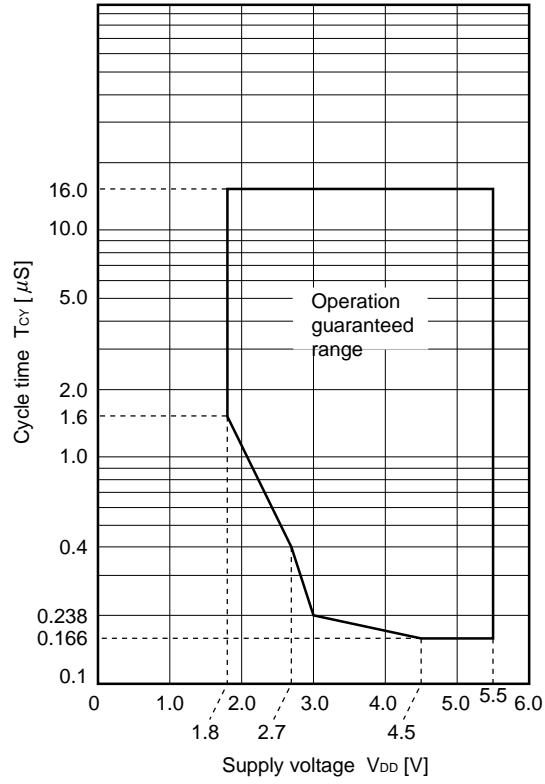
AC Characteristics

(1) Basic Operation (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Cycle time (Min. instruction execution time)	T _{CY}	Operating with main system clock	4.5 V ≤ V _{DD} ≤ 5.5 V	0.166		16	μs
			3.0 V ≤ V _{DD} ≤ 4.5 V	0.238		16	μs
			2.7 V ≤ V _{DD} ≤ 3.0 V	0.4		16	μs
			1.8 V ≤ V _{DD} ≤ 2.7 V	1.6		16	μs
		Operating with subsystem clock	103.9 ^{Note 1}	122	125	μs	
TI00, TI01 input high-/low-level width	t _{TIH0} , t _{TIL0}	3.0 V ≤ V _{DD} ≤ 5.5 V		2/f _{sam} +0.1 ^{Note 2}			μs
		2.7 V ≤ V _{DD} < 3.0 V		2/f _{sam} +0.2 ^{Note 2}			μs
		1.8 V ≤ V _{DD} < 2.7 V		2/f _{sam} +0.5 ^{Note 2}			μs
TI50, TI51 input frequency	f _{TI5}	2.7 V ≤ V _{DD} ≤ 5.5 V		0		4	MHz
		1.8 V ≤ V _{DD} < 2.7 V		0		275	kHz
TI50, TI51 input high-/low-level width	t _{TIH5} , t _{TIL5}	2.7 V ≤ V _{DD} ≤ 5.5 V		100			ns
		1.8 V ≤ V _{DD} < 2.7 V		1.8			ns
Interrupt request input high-/low- level width	t _{INTH} , t _{INTL}	INTP0 to INTP3, P40 to P47	2.7 V ≤ V _{DD} ≤ 5.5 V	1			μs
			1.8 V ≤ V _{DD} < 2.7 V	2			μs
RESET low-level width	t _{RSL}	2.7 V ≤ V _{DD} ≤ 5.5 V		10			μs
		1.8 V ≤ V _{DD} < 2.7 V		20			μs

- Notes**
1. Value when the external clock is used. When a crystal resonator is used, it is 114 μs (MIN.).
 2. Selection of f_{sam} = f_x, f_x/4, f_x/64 is possible using bits 0 and 1 (PRM00, PRM01) of prescaler mode register 0 (PRM0). However, if the TI00 valid edge is selected as the count clock, the value becomes f_{sam} = f_x/8.

T_{CY} vs. V_{DD} (main system clock operation)



(2) Read/Write Operation (T_A = -40 to +85°C, V_{DD} = 4.0 to 5.5 V)

(1/3)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASTB high-level width	t _{ASTH}		0.3t _{cy}		ns
Address setup time	t _{ADS}		20		ns
Address hold time	t _{ADH}		6		ns
Data input time from address	t _{ADD1}			(2 + 2n)t _{cy} - 54	ns
	t _{ADD2}			(3 + 2n)t _{cy} - 60	ns
Address output time from $\overline{RD}\downarrow$	t _{RDAD}		0	100	ns
Data input time from $\overline{RD}\downarrow$	t _{RDD1}			(2 + 2n)t _{cy} - 87	ns
	t _{RDD2}			(3 + 2n)t _{cy} - 93	ns
Read data hold time	t _{RDH}		0		ns
\overline{RD} low-level width	t _{RDL1}		(1.5 + 2n)t _{cy} - 33		ns
	t _{RDL2}		(2.5 + 2n)t _{cy} - 33		ns
Input time from $\overline{RD}\downarrow$ to $\overline{WAIT}\downarrow$	t _{RDWT1}			t _{cy} - 43	ns
	t _{RDWT2}			t _{cy} - 43	ns
Input time from $\overline{WR}\downarrow$ to $\overline{WAIT}\downarrow$	t _{WRWT}			t _{cy} - 25	ns
\overline{WAIT} low-level width	t _{WTL}		(0.5 + n)t _{cy} + 10	(2 + 2n)t _{cy}	ns
Write data setup time	t _{WDS}		60		ns
Write data hold time	t _{WDH}		6		ns
\overline{WR} low-level width	t _{WRL1}		(1.5 + 2n)t _{cy} - 15		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{RD}\downarrow$	t _{ASTRD}		6		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{WR}\downarrow$	t _{ASTWR}		2t _{cy} - 15		ns
Delay time from $\overline{RD}\uparrow$ to $\overline{ASTB}\uparrow$ at external fetch	t _{RDAST}		0.8t _{cy} - 15	1.2t _{cy}	ns
Address hold time from $\overline{RD}\uparrow$ at external fetch	t _{RDADH}		0.8t _{cy} - 15	1.2t _{cy} + 30	ns
Write data output time from $\overline{RD}\uparrow$	t _{RDWD}		40		ns
Write data output time from $\overline{WR}\downarrow$	t _{WRWD}		10	60	ns
Address hold time from $\overline{WR}\uparrow$	t _{WRADH}		0.8t _{cy} - 15	1.2t _{cy} + 30	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{RD}\uparrow$	t _{WTRD}		0.8t _{cy}	2.5t _{cy} + 25	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{WR}\uparrow$	t _{WTWR}		0.8t _{cy}	2.5t _{cy} + 25	ns

Caution T_{cy} can only be used when the MIN. value is 0.238 μs.

- Remarks**
1. t_{cy} = T_{cy}/4
 2. n indicates the number of waits.
 3. C_L = 100 pF (C_L indicates the load capacitance of the AD0 to AD7, A8 to A15, \overline{RD} , \overline{WR} , \overline{WAIT} , and \overline{ASTB} pins.)

(2) Read/Write Operation ($T_A = -40$ to $+85^\circ\text{C}$, $V_{DD} = 2.7$ to 4.0 V)

(2/3)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASTB high-level width	t_{ASTH}		$0.3t_{CY}$		ns
Address setup time	t_{ADS}		30		ns
Address hold time	t_{ADH}		10		ns
Input time from address to data	t_{ADD1}			$(2 + 2n)t_{CY} - 108$	ns
	t_{ADD2}			$(3 + 2n)t_{CY} - 120$	ns
Output time from $\overline{RD}\downarrow$ to address	t_{RDAD}		0	200	ns
Input time from $\overline{RD}\downarrow$ to data	t_{RDD1}			$(2 + 2n)t_{CY} - 148$	ns
	t_{RDD2}			$(3 + 2n)t_{CY} - 162$	ns
Read data hold time	t_{RDH}		0		ns
\overline{RD} low-level width	t_{RD1}		$(1.5 + 2n)t_{CY} - 40$		ns
	t_{RD2}		$(2.5 + 2n)t_{CY} - 40$		ns
Input time from $\overline{RD}\downarrow$ to $\overline{WAIT}\downarrow$	t_{RDWT1}			$t_{CY} - 75$	ns
	t_{RDWT2}			$t_{CY} - 60$	ns
Input time from $\overline{WR}\downarrow$ to $\overline{WAIT}\downarrow$	t_{WRWT}			$t_{CY} - 50$	ns
\overline{WAIT} low-level width	t_{WTL}		$(0.5 + 2n)t_{CY} + 10$	$(2 + 2n)t_{CY}$	ns
Write data setup time	t_{WDS}		60		ns
Write data hold time	t_{WDH}		10		ns
\overline{WR} low-level width	t_{WRL1}		$(1.5 + 2n)t_{CY} - 30$		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{RD}\downarrow$	t_{ASTRD}		10		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{WR}\downarrow$	t_{ASTWR}		$2t_{CY} - 30$		ns
Delay time from $\overline{RD}\uparrow$ to $\overline{ASTB}\uparrow$ at external fetch	t_{RDAST}		$0.8t_{CY} - 30$	$1.2t_{CY}$	ns
Hold time from $\overline{RD}\uparrow$ to address at external fetch	t_{RDADH}		$0.8t_{CY} - 30$	$1.2t_{CY} + 60$	ns
Write data output time from $\overline{RD}\uparrow$	t_{RDWD}		40		ns
Write data output time from $\overline{WR}\downarrow$	t_{WRWD}		20	120	ns
Hold time from $\overline{WR}\uparrow$ to address	t_{WRADH}		$0.8t_{CY} - 30$	$1.2t_{CY} + 60$	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{RD}\uparrow$	t_{WTRD}		$0.5t_{CY}$	$2.5t_{CY} + 50$	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{WR}\uparrow$	t_{WTWR}		$0.5t_{CY}$	$2.5t_{CY} + 50$	ns

Caution t_{CY} can only be used when the MIN. value is $0.4 \mu\text{s}$.

- Remarks**
- $t_{CY} = T_{CY}/4$
 - n indicates the number of waits.
 - $C_L = 100$ pF (C_L indicates the load capacitance of the AD0 to AD7, AD8 to AD15, \overline{RD} , \overline{WR} , \overline{WAIT} , and \overline{ASTB} pins.)

(2) Read/Write Operation (T_A = -40 to +85°C, V_{DD} = 1.8 to 2.7 V)

(3/3)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASTB high-level width	t _{ASTH}		0.3t _{cy}		ns
Address setup time	t _{ADS}		120		ns
Address hold time	t _{ADH}		20		ns
Input time from address to data	t _{ADD1}			(2 + 2n)t _{cy} - 233	ns
	t _{ADD2}			(3 + 2n)t _{cy} - 240	ns
Output time from $\overline{RD}\downarrow$ to address	t _{RDAD}		0	400	ns
Input time from $\overline{RD}\downarrow$ to data	t _{RDD1}			(2 + 2n)t _{cy} - 325	ns
	t _{RDD2}			(3 + 2n)t _{cy} - 332	ns
Read data hold time	t _{RDH}		0		ns
\overline{RD} low-level width	t _{RD1}		(1.5 + 2n)t _{cy} - 92		ns
	t _{RD2}		(2.5 + 2n)t _{cy} - 92		ns
Input time from $\overline{RD}\downarrow$ to $\overline{WAIT}\downarrow$	t _{RDWT1}			t _{cy} - 350	ns
	t _{RDWT2}			t _{cy} - 132	ns
Input time from $\overline{WR}\downarrow$ to $\overline{WAIT}\downarrow$	t _{WRWT}			t _{cy} - 100	ns
\overline{WAIT} low-level width	t _{WTL}		(0.5 + 2n)t _{cy} + 10	(2 + 2n)t _{cy}	ns
Write data setup time	t _{WDS}		60		ns
Write data hold time	t _{WDH}		20		ns
\overline{WR} low-level width	t _{WRL1}		(1.5 + 2n)t _{cy} - 60		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{RD}\downarrow$	t _{ASTRD}		20		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{WR}\downarrow$	t _{ASTWR}		2t _{cy} - 60		ns
Delay time from $\overline{RD}\uparrow$ to $\overline{ASTB}\uparrow$ at external fetch	t _{RDAST}		0.8t _{cy} - 60	1.2t _{cy}	ns
Hold time from $\overline{RD}\uparrow$ to address at external fetch	t _{RDADH}		0.8t _{cy} - 60	1.2t _{cy} + 120	ns
Write data output time from $\overline{RD}\uparrow$	t _{RDWD}		40		ns
Write data output time from $\overline{WR}\downarrow$	t _{WRWD}		40	240	ns
Hold time from $\overline{WR}\uparrow$ to address	t _{WRADH}		0.8t _{cy} - 60	1.2t _{cy} + 120	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{RD}\uparrow$	t _{WTRD}		0.5t _{cy}	2.5t _{cy} + 100	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{WR}\uparrow$	t _{WTWR}		0.5t _{cy}	2.5t _{cy} + 100	ns

Caution T_{cy} can only be used when the MIN. value is 1.6 μs.

- Remarks**
1. t_{cy} = T_{cy}/4
 2. n indicates the number of waits.
 3. C_L = 100 pF (C_L indicates the load capacitance of the AD0 to AD7, AD8 to AD15, \overline{RD} , \overline{WR} , \overline{WAIT} , and \overline{ASTB} pins.)

(3) Serial Interface (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

(a) 3-wire serial I/O mode ($\overline{\text{SCK3n}}$... Internal clock output)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
$\overline{\text{SCK3n}}$ cycle time	t _{KCY1}	4.5 V ≤ V _{DD} ≤ 5.5 V	666			ns
		3.0 V ≤ V _{DD} < 4.5 V	954			ns
		2.7 V ≤ V _{DD} < 3.0 V	1600			ns
		1.8 V ≤ V _{DD} < 2.7 V	3200			ns
$\overline{\text{SCK3n}}$ high-/ low-level width	t _{KH1} , t _{KL1}	3.0 V ≤ V _{DD} ≤ 5.5 V	t _{KCY1} /2 - 50			ns
		1.8 V ≤ V _{DD} < 3.0 V	t _{KCY1} /2 - 100			ns
SI3n setup time (to $\overline{\text{SCK3n}}$ ↑)	t _{SIK1}	3.0 V ≤ V _{DD} ≤ 5.5 V	100			ns
		2.7 V ≤ V _{DD} < 3.0 V	150			ns
		1.8 V ≤ V _{DD} < 2.7 V	300			ns
SI3n hold time (from $\overline{\text{SCK3n}}$ ↑)	t _{KH1}	4.5 V ≤ V _{DD} ≤ 5.5 V	300			ns
		1.8 V ≤ V _{DD} < 4.5 V	400			ns
Delay time from $\overline{\text{SCK3n}}$ ↓ to SO3n output	t _{KSO1}	C = 100 pF ^{Note}	4.5 V ≤ V _{DD} ≤ 5.5 V		200	ns
			1.8 V ≤ V _{DD} < 4.5 V		300	ns

Note C is the load capacitance of the $\overline{\text{SCK3n}}$ and SO3n output lines.

(b) 3-wire serial I/O mode ($\overline{\text{SCK3n}}$... External clock input)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
$\overline{\text{SCK3n}}$ cycle time	t _{KCY2}	4.5 V ≤ V _{DD} ≤ 5.5 V	666			ns
		3.0 V ≤ V _{DD} < 4.5 V	800			ns
		2.7 V ≤ V _{DD} < 3.0 V	1600			ns
		1.8 V ≤ V _{DD} < 2.7 V	3200			ns
$\overline{\text{SCK3n}}$ high-/ low-level width	t _{KH2} , t _{KL2}	4.5 V ≤ V _{DD} ≤ 5.5 V	333			ns
		3.0 V ≤ V _{DD} < 4.5 V	400			ns
		2.7 V ≤ V _{DD} < 3.0 V	800			ns
		1.8 V ≤ V _{DD} < 2.7 V	1600			ns
SI3n setup time (to $\overline{\text{SCK3n}}$ ↑)	t _{SIK2}		100			ns
SI3n hold time (from $\overline{\text{SCK3n}}$ ↑)	t _{KH2}	4.5 V ≤ V _{DD} ≤ 5.5 V	300			ns
		1.8 V ≤ V _{DD} < 4.5 V	400			ns
Delay time from $\overline{\text{SCK3n}}$ ↓ to SO3n output	t _{KSO2}	C = 100 pF ^{Note}	4.5 V ≤ V _{DD} ≤ 5.5 V		200	ns
			1.8 V ≤ V _{DD} < 4.5 V		300	ns

Note C is the load capacitance of the SO3n output line.

Remark n = 0, 1

(c) UART mode (dedicated baud-rate generator output)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		$4.5\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			187500	bps
		$3.0\text{ V} \leq V_{DD} < 4.5\text{ V}$			131031	bps
		$2.7\text{ V} \leq V_{DD} < 3.0\text{ V}$			78125	bps
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$			39063	bps

(d) UART mode (external clock input)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
ASCK0 cycle time	t_{KCY3}	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	800			ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$	1600			ns
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$	3200			ns
ASCK0 high-/low-level width	t_{KH3} ,	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	400			ns
	t_{KL3}	$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$	800			ns
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$	1600			ns
Transfer rate		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			39063	bps
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$			19531	bps
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$			9766	bps

(e) UART mode (infrared data transfer mode)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Transfer rate		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		131031	bps
Allowable bit rate error		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		±0.87	%
Output pulse width		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	1.2	$0.24/f_{br}$ ^{Note}	μs
Input pulse width		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	$4/f_x$		μs

Note fbr: Specified baud rate

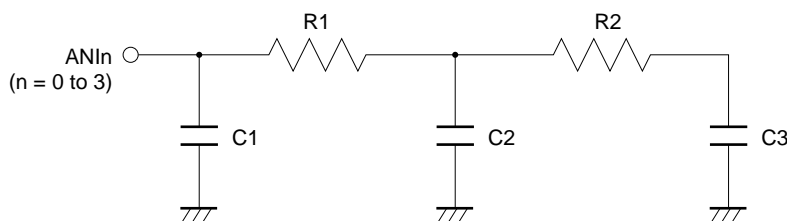
A/D Converter Characteristics (T_A = -40 to +85°C, V_{DD} = AV_{DD} = 1.8 to 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution			8	8	8	bit
Overall error ^{Note}		4.0 V ≤ AV _{REF} ≤ 5.5 V			±0.4	%FSR
		2.7 V ≤ AV _{REF} < 4.0 V			±0.6	%FSR
		1.8 V ≤ AV _{REF} < 2.7 V			±1.2	%FSR
Conversion time	t _{CONV}	4.5 V ≤ AV _{DD} ≤ 5.5 V	12		96	μs
		4.0 V ≤ AV _{DD} < 4.5 V	14		96	μs
		2.7 V ≤ AV _{DD} < 4.0 V	17		96	μs
		1.8 V ≤ AV _{DD} < 2.7 V	28		96	μs
Analog input voltage	V _{IAN}		0		AV _{REF}	V
Reference voltage	AV _{REF}		1.8		AV _{DD}	V
Resistance between AV _{REF} and AV _{SS}	R _{REF}	When A/D converter not operating	20	40		kΩ

Note Excludes quantization error (±1/2 LSB). This value is indicated as a ratio (%FSR) to the full-scale value.

Remark The impedance of the analog input pins is shown below.

[Equivalent circuit]



[Parameter value]

(TYP.)

AV _{DD}	R1	R2	C1	C2	C3
2.7 V	12 kΩ	8.0 kΩ	3.0 pF	3.0 pF	2.0 pF
4.5 V	4 kΩ	2.7 kΩ	3.0 pF	1.4 pF	2.0 pF

Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics (T_A = -40 to +85°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention power supply voltage	V _{DDDR}		1.6		5.5	V
Data retention power supply current	I _{DDDR}	Subsystem clock stop (XT1 = V _{DD}) and feed-back resistor disconnected		0.1	30	μA
Release signal set time	t _{SREL}		0			μs
Oscillation stabilization time	t _{WAIT}	Release by $\overline{\text{RESET}}$		2 ¹⁷ /f _x		s
		Release by interrupt request		Note		s

Note Selection of 2¹²/f_x and 2¹⁴/f_x to 2¹⁷/f_x is possible using bits 0 to 2 (OSTS0 to OSTS2) of the oscillation stabilization time select register (OSTS).

12.2 μPD780021AY, 780022AY, 780023AY, 780024AY, and Conventional Products of μPD780021A, 780022A, 780023A, 780024A

Absolute Maximum Ratings (T_A = 25°C)

Parameter	Symbol	Conditions		Ratings	Unit	
Supply voltage	V _{DD}			-0.3 to +6.5	V	
	AV _{DD}			-0.3 to V _{DD} + 0.3 ^{Note}	V	
	AV _{REF}			-0.3 to V _{DD} + 0.3 ^{Note}	V	
	AV _{SS}			-0.3 to +0.3	V	
Input voltage	V _{I1}	P00 to P03, P10 to P17, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75, X1, X2, XT1, XT2, RESET		-0.3 to V _{DD} + 0.3 ^{Note}	V	
	V _{I2}	P30 to P33	N-ch open-drain	Without pull-up resistor	-0.3 to + 6.5	V
				With pull-up resistor	-0.3 to V _{DD} + 0.3 ^{Note}	V
Output voltage	V _O			-0.3 to V _{DD} + 0.3 ^{Note}	V	
Analog input voltage	V _{AN}	P10 to P17	Analog input pin	AV _{SS} - 0.3 to AV _{REF0} + 0.3 ^{Note} and -0.3 to V _{DD} + 0.3 ^{Note}	V	
Output current, high	I _{OH}	Per pin		-10	mA	
		Total for P00 to P03, P40 to P47, P50 to P57, P64 to P67, P70 to P75		-15	mA	
		Total for P20 to P25, P30 to P36		-15	mA	
Output current, low	I _{OL}	Per pin for P00 to P03, P20 to P25, P34 to P36, P40 to P47, P64 to P67, P70 to P75		20	mA	
		Per pin for P30 to P33, P50 to P57		30	mA	
		Total for P00 to P03, P40 to P47, P64 to P67, P70 to P75		50	mA	
		Total for P20 to P25		20	mA	
		Total for P30 to P36		100	mA	
		Total for P50 to P57		100	mA	
Operating ambient temperature	T _A			-40 to +85	°C	
Storage temperature	T _{stg}			-65 to +150	°C	

Note 6.5 V or below

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

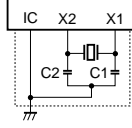
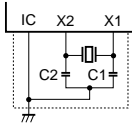
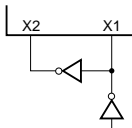
Remark Unless otherwise specified, the characteristic of alternate-function pins are the same as those of port pins.

Capacitance (T_A = 25°C, V_{DD} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Input capacitance	C _{IN}	f = 1 MHz Unmeasured pins returned to 0 V.				15	pF
I/O capacitance	C _{IO}	f = 1 MHz Unmeasured pins returned to 0 V.	P00 to P03, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75			15	pF
			P30 to P33			20	pF

Remark Unless otherwise specified, the characteristic of alternate-function pins are the same as those of port pins.

Main System Clock Oscillator Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
Ceramic resonator		Oscillation frequency (f _x) ^{Note 1}	4.0 V ≤ V _{DD} ≤ 5.5 V	1.0		8.38	MHz
			1.8 V ≤ V _{DD} < 4.0 V	1.0		5.0	
		Oscillation stabilization time ^{Note 2}	After V _{DD} reaches oscillation voltage range MIN.			4	ms
Crystal resonator		Oscillation frequency (f _x) ^{Note 1}	4.0 V ≤ V _{DD} ≤ 5.5 V	1.0		8.38	MHz
			1.8 V ≤ V _{DD} < 4.0 V	1.0		5.0	
		Oscillation stabilization time ^{Note 2}	4.0 V ≤ V _{DD} ≤ 5.5 V			10	ms
			1.8 V ≤ V _{DD} < 4.0 V			30	
External clock		X1 input frequency (f _x) ^{Note 1}	4.0 V ≤ V _{DD} ≤ 5.5 V	1.0		8.38	MHz
			1.8 V ≤ V _{DD} < 4.0 V	1.0		5.0	
		X1 input high-/low-level width (t _{xH} , t _{xL})	4.0 V ≤ V _{DD} ≤ 5.5 V	50		500	ns
			1.8 V ≤ V _{DD} < 4.0 V	85		500	

- Notes**
1. Indicates only oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.
 2. Time required to stabilize oscillation after reset or STOP mode release.

Cautions 1. When using the main system clock oscillator, wire as follows in the area enclosed by the broken lines in the above figures to avoid an adverse effect from wiring capacitance.

- Keep the wiring length as short as possible.
- Do not cross the wiring with the other signal lines.
- Do not route the wiring near a signal line through which a high fluctuating current flows.
- Always make the ground point of the oscillator capacitor the same potential as V_{SS1}.
- Do not ground the capacitor to a ground pattern through which a high current flows.
- Do not fetch signals from the oscillator.

2. When the main system clock is stopped and the system is operating on the subsystem clock, wait until the oscillation stabilization time has been secured by the program before switching back to the main system clock.

Subsystem Clock Oscillator Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
Crystal resonator		Oscillation frequency (f _{XT}) ^{Note 1}		32	32.768	35	kHz
		Oscillation stabilization time ^{Note 2}	4.0 V ≤ V _{DD} ≤ 5.5 V		1.2	2	s
			1.8 V ≤ V _{DD} < 4.0 V			10	
External clock		XT1 input frequency (f _{XT}) ^{Note 1}		32		38.5	kHz
		XT1 input high-/low-level width (t _{XTH} , t _{XTL})		12		15	μs

- Notes**
1. Indicates only oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.
 2. Time required to stabilize oscillation after V_{DD} reaches oscillation voltage range MIN.

Cautions 1. When using the subsystem clock oscillator, wire as follows in the area enclosed by the broken lines in the above figures to avoid an adverse effect from wiring capacitance.

- Keep the wiring length as short as possible.
- Do not cross the wiring with the other signal lines.
- Do not route the wiring near a signal line through which a high fluctuating current flows.
- Always make the ground point of the oscillator capacitor the same potential as V_{SS1}.
- Do not ground the capacitor to a ground pattern through which a high current flows.
- Do not fetch signals from the oscillator.

2. The subsystem clock oscillator is designed as a low-amplitude circuit for reducing power consumption, and is more prone to malfunction due to noise than the main system clock oscillator. Particular care is therefore required with the wiring method when the subsystem clock is used.

Remark For the resonator selection and oscillator constant, customers are required to either evaluate the oscillation themselves or apply to the resonator manufacturer for evaluation.

Recommended Oscillator Constant

Main system clock: Ceramic resonator (T_A = -40 to +85°C)

Manufacturer	Part Number	Frequency (MHz)	Recommended Circuit Constant			Oscillation Voltage Range	
			C1 (pF)	C2 (pF)	R1 (kΩ)	MIN. (V)	MAX. (V)
Murata Mfg. Co., Ltd.	CSBFB1M00J58	1.00	100	100	2.2	1.8	5.5
	CSBLA1M00J58	1.00	100	100	2.2	1.8	5.5
	CSTCC2M00G56	2.00	On-chip	On-chip	0	1.8	5.5
	CSTLS2M00G56	2.00	On-chip	On-chip	0	1.8	5.5
	CSTCC3M58G53	3.58	On-chip	On-chip	0	1.8	5.5
	CSTLS3M58G53	3.58	On-chip	On-chip	0	1.8	5.5
	CSTCR4M00G53	4.00	On-chip	On-chip	0	1.8	5.5
	CSTLS4M00G53	4.00	On-chip	On-chip	0	1.8	5.5
	CSTCR4M19G53	4.19	On-chip	On-chip	0	1.8	5.5
	CSTLS4M19G53	4.19	On-chip	On-chip	0	1.8	5.5
	CSTCR4M91G53	4.91	On-chip	On-chip	0	1.8	5.5
	CSTLS4M91G53	4.91	On-chip	On-chip	0	1.8	5.5
	CSTCR5M00G53	5.00	On-chip	On-chip	0	1.8	5.5
	CSTLS5M00G53	5.00	On-chip	On-chip	0	1.8	5.5
	CSTCE8M00G52	8.00	On-chip	On-chip	0	3.0	5.5
	CSTLS8M00G53	8.00	On-chip	On-chip	0	3.0	5.5
	CSTCE8M38G52	8.38	On-chip	On-chip	0	3.0	5.5
	CSTLS8M38G53	8.38	On-chip	On-chip	0	3.0	5.5
	CSTCE10M0G52	10.00	On-chip	On-chip	0	4.5	5.5
	CSTLS10M0G53	10.00	On-chip	On-chip	0	4.5	5.5
TDK	CCR3.58MC3	3.58	On-chip	On-chip	0	1.8	5.5
	CCR4.19MC3	4.19	On-chip	On-chip	0	1.8	5.5
	CCR5.0MC3	5.00	On-chip	On-chip	0	1.8	5.5
	CCR8.0MC5	8.00	On-chip	On-chip	0	2.0	5.5
	CCR8.38MC5	8.38	On-chip	On-chip	0	2.0	5.5

Caution The oscillator constant is a reference value based on evaluation in specific environments by the resonator manufacturer. If the oscillator characteristics need to be optimized in the actual application, request the resonator manufacturer for evaluation on the implementation circuit. Note that the oscillation voltage and oscillation frequency merely indicate the characteristics of the oscillator. Use the internal operation conditions of the μPD780024A, 780024AY Subseries within the specifications of the DC and AC characteristics.

DC Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Output current, high	I _{OH}	Per pin				-1	mA
		All pins				-15	mA
Output current, low	I _{OL}	Per pin for P00 to P03, P20 to P25, P34 to P36, P40 to P47, P64 to P67, P70 to P75				10	mA
		Per pin for P30 to P33, P50 to P57				15	mA
		Total for P00 to P03, P40 to P47, P64 to P67, P70 to P75				20	mA
		Total for P20 to P25				10	mA
		Total for P30 to P36				70	mA
		Total for P50 to P57				70	mA
Input voltage, high	V _{IH1}	P10 to P17, P21, P24, P35, P40 to P47, P50 to P57, P64 to P67, P74, P75	2.7 V ≤ V _{DD} ≤ 5.5 V	0.7V _{DD}		V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0.8V _{DD}		V _{DD}	V
	V _{IH2}	P00 to P03, P20, P22, P23, P25, P34, P36, P70 to P73, RESET	2.7 V ≤ V _{DD} ≤ 5.5 V	0.8V _{DD}		V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0.85V _{DD}		V _{DD}	V
	V _{IH3}	P30 to P33 (N-ch open-drain)	2.7 V ≤ V _{DD} ≤ 5.5 V	0.7V _{DD}		5.5	V
			1.8 V ≤ V _{DD} < 2.7 V	0.8V _{DD}		5.5	V
	V _{IH4}	X1, X2	2.7 V ≤ V _{DD} ≤ 5.5 V	V _{DD} - 0.5		V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	V _{DD} - 0.2		V _{DD}	V
	V _{IH5}	XT1, XT2	4.0 V ≤ V _{DD} ≤ 5.5 V	0.8V _{DD}		V _{DD}	V
			1.8 V ≤ V _{DD} < 4.0 V	0.9V _{DD}		V _{DD}	V
Input voltage, low	V _{IL1}	P10 to P17, P21, P24, P35, P40 to P47, P50 to P57, P64 to P67, P74, P75	2.7 V ≤ V _{DD} ≤ 5.5 V	0		0.3V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0		0.2V _{DD}	V
	V _{IL2}	P00 to P03, P20, P22, P23, P25, P34, P36, P70 to P73, RESET	2.7 V ≤ V _{DD} ≤ 5.5 V	0		0.2V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0		0.15V _{DD}	V
	V _{IL3}	P30 to P33	4.0 V ≤ V _{DD} ≤ 5.5 V	0		0.3V _{DD}	V
			2.7 V ≤ V _{DD} < 4.0 V	0		0.2V _{DD}	V
			1.8 V ≤ V _{DD} < 2.7 V	0		0.1V _{DD}	V
	V _{IL4}	X1, X2	2.7 V ≤ V _{DD} ≤ 5.5 V	0		0.4	V
			1.8 V ≤ V _{DD} < 2.7 V	0		0.2	V
	V _{IL5}	XT1, XT2	4.0 V ≤ V _{DD} ≤ 5.5 V	0		0.2V _{DD}	V
1.8 V ≤ V _{DD} < 4.0 V			0		0.1V _{DD}	V	
Output voltage, high	V _{OH1}	4.0 V ≤ V _{DD} ≤ 5.5 V, I _{OH} = -1 mA		V _{DD} - 1.0		V _{DD}	V
		1.8 V ≤ V _{DD} < 4.0 V, I _{OH} = -100 μA		V _{DD} - 0.5		V _{DD}	V
Output voltage, low	V _{OL1}	P30 to P33	4.0 V ≤ V _{DD} ≤ 5.5 V,			2.0	V
		P50 to P57	I _{OL} = 15 mA		0.4	2.0	V
		P00 to P03, P20 to P25, P34 to P36, P40 to P47, P64 to P67, P70 to P75	4.0 V ≤ V _{DD} ≤ 5.5 V,			0.4	V
	V _{OL2}	I _{OL} = 400 μA				0.5	V

Remark Unless otherwise specified, the characteristics of alternate-function pins are the same as those of port pins.

DC Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Input leakage current, high	I _{LIH1}	V _{IN} = V _{DD}	P00 to P03, P10 to P17, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P60 to P67, P70 to P75, <u>RESET</u>			3	μA
	I _{LIH2}		X1, X2, XT1, XT2			20	μA
	I _{LIH3}	V _{IN} = 5.5 V	P30 to P33 ^{Note 1}			3	μA
Input leakage current, low	I _{LIL1}	V _{IN} = 0 V	P00 to P03, P10 to P17, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75, <u>RESET</u>			-3	μA
	I _{LIL2}		X1, X2, XT1, XT2			-20	μA
	I _{LIL3}		P30 to P33 ^{Note 1}			-3	μA
Output leakage current, high	I _{LOH}	V _{OUT} = V _{DD}				3	μA
Output leakage current, low	I _{LOL}	V _{OUT} = 0 V				-3	μA
Mask option pull-up resistance	R ₁	V _{IN} = 0 V, P30, P31, P32 ^{Note 2} , P33 ^{Note 2}		15	30	90	kΩ
Software pull-up resistance	R ₂	V _{IN} = 0 V, P00 to P03, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75		15	30	90	kΩ

Notes 1. μPD780021A, 780022A, 780023A, 780024A: When pull-up resistors are not connected to P30 to P33 (specified by the mask option).

μPD780021AY, 780022AY, 780023AY, 780024AY: When pull-up resistors are not connected to P30 and P31 (specified by the mask option).

2. Only for the μPD780021A, 780022A, 780023A, and 780024A.

Remark Unless otherwise specified, the characteristics of alternate-function pins are the same as those of port pins.

DC Characteristics (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit	
Power supply current ^{Note 1}	I _{DD1} ^{Note 2}	8.38 MHz crystal oscillation operating mode	V _{DD} = 5.0 V ±10% ^{Note 3}	When A/D converter is stopped		5.5	11	mA
				When A/D converter is operating ^{Note 6}		6.5	13	mA
		5.00 MHz crystal oscillation operating mode	V _{DD} = 3.0 V ±10% ^{Note 3}	When A/D converter is stopped		2	4	mA
				When A/D converter is operating ^{Note 6}		3	6	mA
			V _{DD} = 2.0 V ±10% ^{Note 4}	When A/D converter is stopped		0.4	1.5	mA
				When A/D converter is operating ^{Note 6}		1.4	4.2	mA
	I _{DD2}	8.38 MHz crystal oscillation HALT mode	V _{DD} = 5.0 V ±10% ^{Note 3}	When peripheral functions are stopped		1.1	2.2	mA
				When peripheral functions are operating			4.7	mA
		5.00 MHz crystal oscillation HALT mode	V _{DD} = 3.0 V ±10% ^{Note 3}	When peripheral functions are stopped		0.35	0.7	mA
				When peripheral functions are operating			1.7	mA
			V _{DD} = 2.0 V ±10% ^{Note 4}	When peripheral functions are stopped		0.15	0.4	mA
				When peripheral functions are operating			1.1	mA
	I _{DD3}	32.768 kHz crystal oscillation operating mode ^{Note 5}	V _{DD} = 5.0 V ±10%		40	80	μA	
			V _{DD} = 3.0 V ±10%		20	40	μA	
			V _{DD} = 2.0 V ±10%		10	20	μA	
I _{DD4}	32.768 kHz crystal oscillation HALT mode ^{Note 5}	V _{DD} = 5.0 V ±10%		30	60	μA		
		V _{DD} = 3.0 V ±10%		6	18	μA		
		V _{DD} = 2.0 V ±10%		2	10	μA		
I _{DD5}	XT1 = V _{DD} STOP mode When feedback resistor is not used	V _{DD} = 5.0 V ±10%		0.1	30	μA		
		V _{DD} = 3.0 V ±10%		0.05	10	μA		
		V _{DD} = 2.0 V ±10%		0.05	10	μA		

- Notes**
1. Total current through the internal power supply (V_{DD0}, V_{DD1}) (except the current through pull-up resistors of ports).
 2. I_{DD1} includes the peripheral operation current.
 3. When the processor clock control register (PCC) is set to 00H.
 4. When PCC is set to 02H.
 5. When main system clock operation is stopped.
 6. Includes the current through the AV_{DD} pin.

AC Characteristics

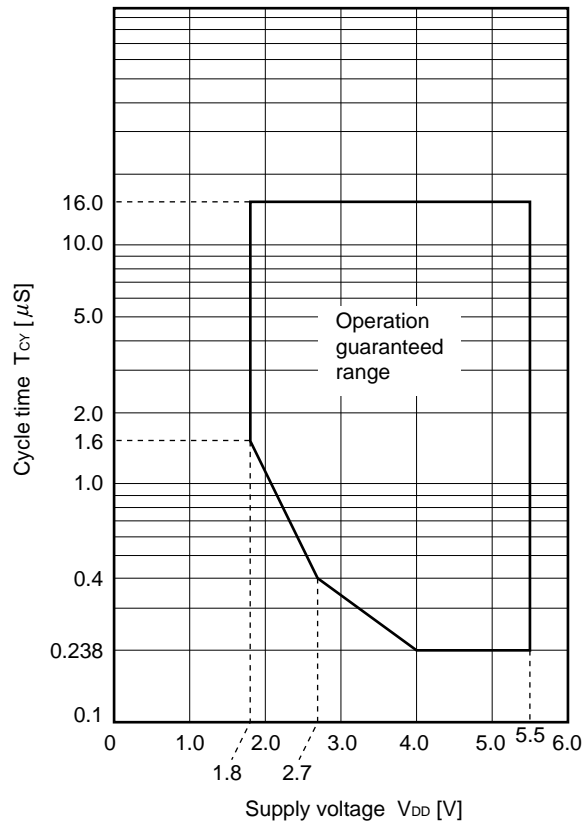
(1) Basic Operation (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Cycle time (Min. instruction execution time)	T _{CY}	Operating with main system clock	4.0 V ≤ V _{DD} ≤ 5.5 V	0.238		16	μs
			2.7 V ≤ V _{DD} < 4.0 V	0.4		16	μs
			1.8 V ≤ V _{DD} < 2.7 V	1.6		16	μs
		Operating with subsystem clock		103.9 ^{Note 1}	122	125	μs
TI00, TI01 input high-/low-level width	t _{TIH0} , t _{TIL0}	4.0 V ≤ V _{DD} ≤ 5.5 V		2/f _{sam} +0.1 ^{Note 2}			μs
		2.7 V ≤ V _{DD} < 4.0 V		2/f _{sam} +0.2 ^{Note 2}			μs
		1.8 V ≤ V _{DD} < 2.7 V		2/f _{sam} +0.5 ^{Note 2}			μs
TI50, TI51 input frequency	f _{TI5}	2.7 V ≤ V _{DD} ≤ 5.5 V		0		4	MHz
		1.8 V ≤ V _{DD} < 2.7 V		0		275	kHz
TI50, TI51 input high-/low-level width	t _{TIH5} , t _{TIL5}	2.7 V ≤ V _{DD} ≤ 5.5 V		100			ns
		1.8 V ≤ V _{DD} < 2.7 V		1.8			ns
Interrupt request input high-/low- level width	t _{INTH} , t _{INTL}	INTP0 to INTP3, P40 to P47	2.7 V ≤ V _{DD} ≤ 5.5 V	1			μs
			1.8 V ≤ V _{DD} < 2.7 V	2			μs
RESET low-level width	t _{RSL}	2.7 V ≤ V _{DD} ≤ 5.5 V		10			μs
		1.8 V ≤ V _{DD} < 2.7 V		20			μs

Notes 1. Value when the external clock is used. When a crystal resonator is used, it is 114 μs (MIN.).

2. Selection of f_{sam} = f_x, f_x/4, f_x/64 is possible using bits 0 and 1 (PRM00, PRM01) of prescaler mode register 0 (PRM0). However, if the TI00 valid edge is selected as the count clock, the value becomes f_{sam} = f_x/8.

T_{CY} vs. V_{DD} (main system clock operation)



(2) Read/Write Operation ($T_A = -40$ to $+85^\circ\text{C}$, $V_{DD} = 4.0$ to 5.5 V)

(1/3)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASTB high-level width	t_{ASTH}		$0.3t_{CY}$		ns
Address setup time	t_{ADS}		20		ns
Address hold time	t_{ADH}		6		ns
Data input time from address	t_{ADD1}			$(2 + 2n)t_{CY} - 54$	ns
	t_{ADD2}			$(3 + 2n)t_{CY} - 60$	ns
Address output time from $\overline{RD}\downarrow$	t_{RDAD}		0	100	ns
Data input time from $\overline{RD}\downarrow$	t_{RDD1}			$(2 + 2n)t_{CY} - 87$	ns
	t_{RDD2}			$(3 + 2n)t_{CY} - 93$	ns
Read data hold time	t_{RDH}		0		ns
\overline{RD} low-level width	t_{RDL1}		$(1.5 + 2n)t_{CY} - 33$		ns
	t_{RDL2}		$(2.5 + 2n)t_{CY} - 33$		ns
Input time from $\overline{RD}\downarrow$ to $\overline{WAIT}\downarrow$	t_{RDWT1}			$t_{CY} - 43$	ns
	t_{RDWT2}			$t_{CY} - 43$	ns
Input time from $\overline{WR}\downarrow$ to $\overline{WAIT}\downarrow$	t_{WRWT}			$t_{CY} - 25$	ns
\overline{WAIT} low-level width	t_{WTL}		$(0.5 + n)t_{CY} + 10$	$(2 + 2n)t_{CY}$	ns
Write data setup time	t_{WDS}		60		ns
Write data hold time	t_{WDH}		6		ns
\overline{WR} low-level width	t_{WRL1}		$(1.5 + 2n)t_{CY} - 15$		ns
Delay time from $ASTB\downarrow$ to $\overline{RD}\downarrow$	t_{ASTRD}		6		ns
Delay time from $ASTB\downarrow$ to $\overline{WR}\downarrow$	t_{ASTWR}		$2t_{CY} - 15$		ns
Delay time from $\overline{RD}\uparrow$ to $ASTB\uparrow$ at external fetch	t_{RDAST}		$0.8t_{CY} - 15$	$1.2t_{CY}$	ns
Address hold time from $\overline{RD}\uparrow$ at external fetch	t_{RDADH}		$0.8t_{CY} - 15$	$1.2t_{CY} + 30$	ns
Write data output time from $\overline{RD}\uparrow$	t_{RDWD}		40		ns
Write data output time from $\overline{WR}\downarrow$	t_{WRWD}		10	60	ns
Address hold time from $\overline{WR}\uparrow$	t_{WRADH}		$0.8t_{CY} - 15$	$1.2t_{CY} + 30$	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{RD}\uparrow$	t_{WTRD}		$0.8t_{CY}$	$2.5t_{CY} + 25$	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{WR}\uparrow$	t_{WTWR}		$0.8t_{CY}$	$2.5t_{CY} + 25$	ns

Caution t_{CY} can only be used when the MIN. value is $0.238 \mu\text{s}$.

- Remarks**
- $t_{CY} = T_{CY}/4$
 - n indicates the number of waits.
 - $C_L = 100 \text{ pF}$ (C_L indicates the load capacitance of the AD0 to AD7, A8 to A15, \overline{RD} , \overline{WR} , \overline{WAIT} , and ASTB pins.)

(2) Read/Write Operation (T_A = -40 to +85°C, V_{DD} = 2.7 to 4.0 V)

(2/3)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASTB high-level width	t _{ASTH}		0.3t _{cy}		ns
Address setup time	t _{ADS}		30		ns
Address hold time	t _{ADH}		10		ns
Input time from address to data	t _{ADD1}			(2 + 2n)t _{cy} - 108	ns
	t _{ADD2}			(3 + 2n)t _{cy} - 120	ns
Output time from $\overline{RD}\downarrow$ to address	t _{RDAD}		0	200	ns
Input time from $\overline{RD}\downarrow$ to data	t _{RDD1}			(2 + 2n)t _{cy} - 148	ns
	t _{RDD2}			(3 + 2n)t _{cy} - 162	ns
Read data hold time	t _{RDH}		0		ns
\overline{RD} low-level width	t _{RDL1}		(1.5 + 2n)t _{cy} - 40		ns
	t _{RDL2}		(2.5 + 2n)t _{cy} - 40		ns
Input time from $\overline{RD}\downarrow$ to $\overline{WAIT}\downarrow$	t _{RDWT1}			t _{cy} - 75	ns
	t _{RDWT2}			t _{cy} - 60	ns
Input time from $\overline{WR}\downarrow$ to $\overline{WAIT}\downarrow$	t _{WRWT}			t _{cy} - 50	ns
\overline{WAIT} low-level width	t _{WTL}		(0.5 + 2n)t _{cy} + 10	(2 + 2n)t _{cy}	ns
Write data setup time	t _{WDS}		60		ns
Write data hold time	t _{WDH}		10		ns
\overline{WR} low-level width	t _{WRL1}		(1.5 + 2n)t _{cy} - 30		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{RD}\downarrow$	t _{ASTRD}		10		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{WR}\downarrow$	t _{ASTWR}		2t _{cy} - 30		ns
Delay time from $\overline{RD}\uparrow$ to $\overline{ASTB}\uparrow$ at external fetch	t _{RDAST}		0.8t _{cy} - 30	1.2t _{cy}	ns
Hold time from $\overline{RD}\uparrow$ to address at external fetch	t _{RDADH}		0.8t _{cy} - 30	1.2t _{cy} + 60	ns
Write data output time from $\overline{RD}\uparrow$	t _{RDWD}		40		ns
Write data output time from $\overline{WR}\downarrow$	t _{WRWD}		20	120	ns
Hold time from $\overline{WR}\uparrow$ to address	t _{WRADH}		0.8t _{cy} - 30	1.2t _{cy} + 60	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{RD}\uparrow$	t _{WTRD}		0.5t _{cy}	2.5t _{cy} + 50	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{WR}\uparrow$	t _{WTWR}		0.5t _{cy}	2.5t _{cy} + 50	ns

Caution T_{cy} can only be used when the MIN. value is 0.4 μs.

- Remarks**
1. t_{cy} = T_{cy}/4
 2. n indicates the number of waits.
 3. C_L = 100 pF (C_L indicates the load capacitance of the AD0 to AD7, AD8 to AD15, \overline{RD} , \overline{WR} , \overline{WAIT} , and ASTB pins.)

(2) Read/Write Operation ($T_A = -40$ to $+85^\circ\text{C}$, $V_{DD} = 1.8$ to 2.7 V)

(3/3)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASTB high-level width	t_{ASTH}		$0.3t_{CY}$		ns
Address setup time	t_{ADS}		120		ns
Address hold time	t_{ADH}		20		ns
Input time from address to data	t_{ADD1}			$(2 + 2n)t_{CY} - 233$	ns
	t_{ADD2}			$(3 + 2n)t_{CY} - 240$	ns
Output time from $\overline{RD}\downarrow$ to address	t_{RDAD}		0	400	ns
Input time from $\overline{RD}\downarrow$ to data	t_{RDD1}			$(2 + 2n)t_{CY} - 325$	ns
	t_{RDD2}			$(3 + 2n)t_{CY} - 332$	ns
Read data hold time	t_{RDH}		0		ns
\overline{RD} low-level width	t_{RD1}		$(1.5 + 2n)t_{CY} - 92$		ns
	t_{RD2}		$(2.5 + 2n)t_{CY} - 92$		ns
Input time from $\overline{RD}\downarrow$ to $\overline{WAIT}\downarrow$	t_{RDWT1}			$t_{CY} - 350$	ns
	t_{RDWT2}			$t_{CY} - 132$	ns
Input time from $\overline{WR}\downarrow$ to $\overline{WAIT}\downarrow$	t_{WRWT}			$t_{CY} - 100$	ns
\overline{WAIT} low-level width	t_{WTL}		$(0.5 + 2n)t_{CY} + 10$	$(2 + 2n)t_{CY}$	ns
Write data setup time	t_{WDS}		60		ns
Write data hold time	t_{WDH}		20		ns
\overline{WR} low-level width	t_{WRL1}		$(1.5 + 2n)t_{CY} - 60$		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{RD}\downarrow$	t_{ASTRD}		20		ns
Delay time from $\overline{ASTB}\downarrow$ to $\overline{WR}\downarrow$	t_{ASTWR}		$2t_{CY} - 60$		ns
Delay time from $\overline{RD}\uparrow$ to $\overline{ASTB}\uparrow$ at external fetch	t_{RDAST}		$0.8t_{CY} - 60$	$1.2t_{CY}$	ns
Hold time from $\overline{RD}\uparrow$ to address at external fetch	t_{RDADH}		$0.8t_{CY} - 60$	$1.2t_{CY} + 120$	ns
Write data output time from $\overline{RD}\uparrow$	t_{RDWD}		40		ns
Write data output time from $\overline{WR}\downarrow$	t_{WRWD}		40	240	ns
Hold time from $\overline{WR}\uparrow$ to address	t_{WRADH}		$0.8t_{CY} - 60$	$1.2t_{CY} + 120$	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{RD}\uparrow$	t_{WTRD}		$0.5t_{CY}$	$2.5t_{CY} + 100$	ns
Delay time from $\overline{WAIT}\uparrow$ to $\overline{WR}\uparrow$	t_{WTWR}		$0.5t_{CY}$	$2.5t_{CY} + 100$	ns

Caution t_{CY} can only be used when the MIN. value is $1.6 \mu\text{s}$.

- Remarks**
- $t_{CY} = T_{CY}/4$
 - n indicates the number of waits.
 - $C_L = 100$ pF (C_L indicates the load capacitance of the AD0 to AD7, AD8 to AD15, \overline{RD} , \overline{WR} , \overline{WAIT} , and \overline{ASTB} pins.)

(3) Serial Interface (T_A = -40 to +85°C, V_{DD} = 1.8 to 5.5 V)

(a) 3-wire serial I/O mode ($\overline{\text{SCK3n}}$... Internal clock output)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
$\overline{\text{SCK3n}}$ cycle time	t _{KCY1}	4.0 V ≤ V _{DD} ≤ 5.5 V	954			ns
		2.7 V ≤ V _{DD} < 4.0 V	1600			ns
		1.8 V ≤ V _{DD} < 2.7 V	3200			ns
$\overline{\text{SCK3n}}$ high-/ low-level width	t _{KH1} , t _{KL1}	4.0 V ≤ V _{DD} ≤ 5.5 V	t _{KCY1} /2 - 50			ns
		1.8 V ≤ V _{DD} < 4.0 V	t _{KCY1} /2 - 100			ns
SI3n setup time (to $\overline{\text{SCK3n}}$ ↑)	t _{SIK1}	4.0 V ≤ V _{DD} ≤ 5.5 V	100			ns
		2.7 V ≤ V _{DD} < 4.0 V	150			ns
		1.8 V ≤ V _{DD} < 2.7 V	300			ns
SI3n hold time (from $\overline{\text{SCK3n}}$ ↑)	t _{KS11}		400			ns
Delay time from $\overline{\text{SCK3n}}$ ↓ to SO3n output	t _{KSO1}	C = 100 pF ^{Note}			300	ns

Note C is the load capacitance of the $\overline{\text{SCK3n}}$ and SO3n output lines.

(b) 3-wire serial I/O mode ($\overline{\text{SCK3n}}$... External clock input)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
$\overline{\text{SCK3n}}$ cycle time	t _{KCY2}	4.0 V ≤ V _{DD} ≤ 5.5 V	800			ns
		2.7 V ≤ V _{DD} < 4.0 V	1600			ns
		1.8 V ≤ V _{DD} < 2.7 V	3200			ns
$\overline{\text{SCK3n}}$ high-/ low-level width	t _{KH2} , t _{KL2}	4.0 V ≤ V _{DD} ≤ 5.5 V	400			ns
		2.7 V ≤ V _{DD} < 4.0 V	800			ns
		1.8 V ≤ V _{DD} < 2.7 V	1600			ns
SI3n setup time (to $\overline{\text{SCK3n}}$ ↑)	t _{SIK2}		100			ns
SI3n hold time (from $\overline{\text{SCK3n}}$ ↑)	t _{KS12}		400			ns
Delay time from $\overline{\text{SCK3n}}$ ↓ to SO3n output	t _{KSO2}	C = 100 pF ^{Note}			300	ns

Note C is the load capacitance of the SO3n output line.

Remark Conventional products of μPD780021A, 780022A, 780023A, 780024A: n = 0 or 1
μPD780021AY, 780022AY, 780023AY, 780024AY: n = 0

(c) UART mode (dedicated baud-rate generator output)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			131031	bps
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$			78125	bps
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$			39063	bps

(d) UART mode (external clock input)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
ASCK0 cycle time	t_{KCY3}	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	800			ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$	1600			ns
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$	3200			ns
ASCK0 high-/low-level width	t_{KH3} ,	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	400			ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$	800			ns
	t_{KL3}	$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$	1600			ns
Transfer rate		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			39063	bps
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$			19531	bps
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$			9766	bps

(e) UART mode (infrared data transfer mode)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Transfer rate		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		131031	bps
Allowable bit rate error		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		± 0.87	%
Output pulse width		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	1.2	$0.24/f_{br}$ ^{Note}	μs
Input pulse width		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	$4/f_x$		μs

Note fbr: Specified baud rate

(f) I²C bus mode (μ PD780021AY, 780022AY, 780023AY, 780024AY only)

Parameter	Symbol	Standard Mode		High-Speed Mode		Unit
		MIN.	MAX.	MIN.	MAX.	
SCL0 clock frequency	f _{CLK}	0	100	0	400	kHz
Bus free time (between stop and start conditions)	t _{BUF}	4.7	—	1.3	—	μ s
Hold time ^{Note 1}	t _{HD:STA}	4.0	—	0.6	—	μ s
SCL0 clock low-level width	t _{LOW}	4.7	—	1.3	—	μ s
SCL0 clock high-level width	t _{HIGH}	4.0	—	0.6	—	μ s
Start/restart condition setup time	t _{SU:STA}	4.7	—	0.6	—	μ s
Data hold time	CBUS-compatible master	t _{HD:DAT}	5.0	—	—	μ s
	I ² C bus	0 ^{Note 2}	—	0 ^{Note 2}	0.9 ^{Note 3}	μ s
Data setup time	t _{SU:DAT}	250	—	100 ^{Note 4}	—	ns
SDA0 and SCL0 signal rise time	t _R	—	1000	20 + 0.1Cb ^{Note 5}	300	ns
SDA0 and SCL0 signal fall time	t _F	—	300	20 + 0.1Cb ^{Note 5}	300	ns
Stop condition setup time	t _{SU:STO}	4.0	—	0.6	—	μ s
Spike pulse width controlled by input filter	t _{SP}	—	—	0	50	ns
Capacitive load per bus line	C _b	—	400	—	400	pF

- Notes**
- In the start condition, the first clock pulse is generated after this hold time.
 - To fill in the undefined area of the SCL0 falling edge, it is necessary for the device to internally provide at least 300 ns of hold time for the SDA0 signal (which is V_{IHmin.} of the SCL0 signal).
 - If the device does not extend the SCL0 signal low hold time (t_{LOW}), only the maximum data hold time t_{HD:DAT} needs to be fulfilled.
 - The high-speed mode I²C bus is available in a standard mode I²C bus system. At this time, the conditions described below must be satisfied.
 - If the device does not extend the SCL0 signal low state hold time
t_{SU:DAT} ≥ 250 ns
 - If the device extends the SCL0 signal low state hold time
Be sure to transmit the next data bit to the SDA0 line before the SCL0 line is released (t_{Rmax.} + t_{SU:DAT} = 1000 + 250 = 1250 ns by standard mode I²C bus specification).
 - C_b: Total capacitance per bus line (unit: pF)

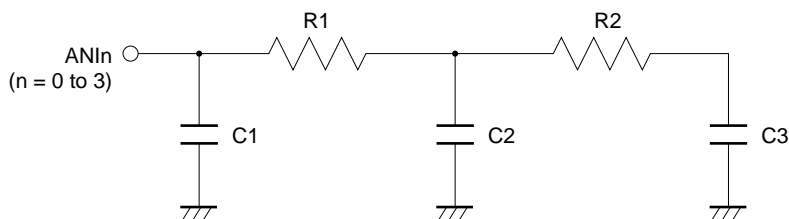
A/D Converter Characteristics (T_A = -40 to +85°C, V_{DD} = AV_{DD} = 1.8 to 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution			8	8	8	bit
Overall error ^{Note}		4.0 V ≤ AV _{REF} ≤ 5.5 V			±0.4	%FSR
		2.7 V ≤ AV _{REF} < 4.0 V			±0.6	%FSR
		1.8 V ≤ AV _{REF} < 2.7 V			±1.2	%FSR
Conversion time	t _{CONV}	4.0 V ≤ AV _{DD} ≤ 5.5 V	14		96	μs
		2.7 V ≤ AV _{DD} < 4.0 V	19		96	μs
		1.8 V ≤ AV _{DD} < 2.7 V	28		96	μs
Analog input voltage	V _{IAN}		0		AV _{REF}	V
Reference voltage	AV _{REF}		1.8		AV _{DD}	V
Resistance between AV _{REF} and AV _{SS}	R _{REF}	When A/D converter not operating	20	40		kΩ

Note Excludes quantization error (±1/2 LSB). This value is indicated as a ratio (%FSR) to the full-scale value.

Remark The impedance of the analog input pins is shown below.

[Equivalent circuit]



[Parameter value]

AV _{DD}	R1	R2	C1	C2	C3
2.7 V	12 kΩ	8.0 kΩ	3.0 pF	3.0 pF	2.0 pF
4.5 V	4 kΩ	2.7 kΩ	3.0 pF	1.4 pF	2.0 pF

(TYP.)

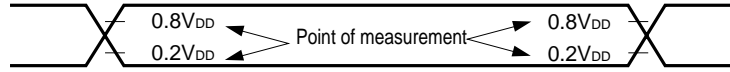
Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics (T_A = -40 to +85°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention power supply voltage	V _{DDDR}		1.6		5.5	V
Data retention power supply current	I _{DDDR}	Subsystem clock stop (XT1 = V _{DD}) and feed-back resistor disconnected		0.1	30	μA
Release signal set time	t _{SREL}		0			μs
Oscillation stabilization time	t _{WAIT}	Release by $\overline{\text{RESET}}$		2 ¹⁷ /f _x		s
		Release by interrupt request		Note		s

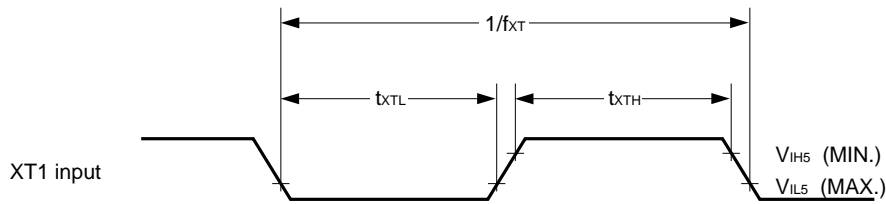
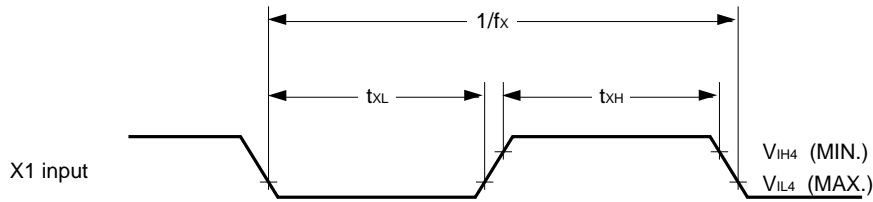
Note Selection of 2¹²/f_x and 2¹⁴/f_x to 2¹⁷/f_x is possible using bits 0 to 2 (OSTS0 to OSTs2) of the oscillation stabilization time select register (OSTS).

12.3 Timing Chart

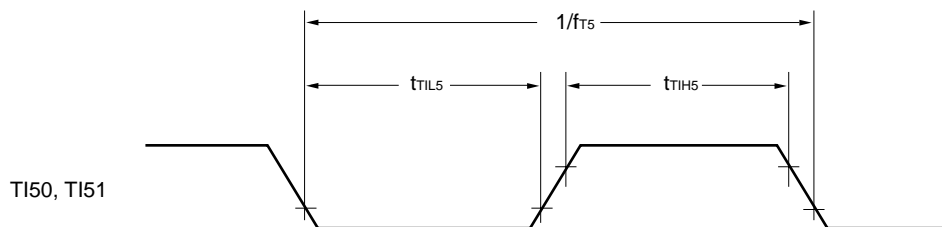
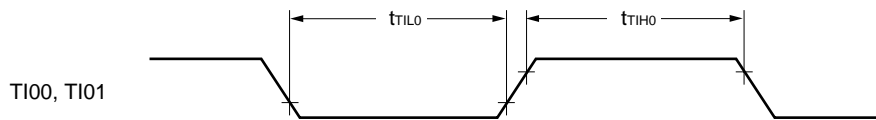
AC Timing Test Points (excluding X1, XT1 inputs)



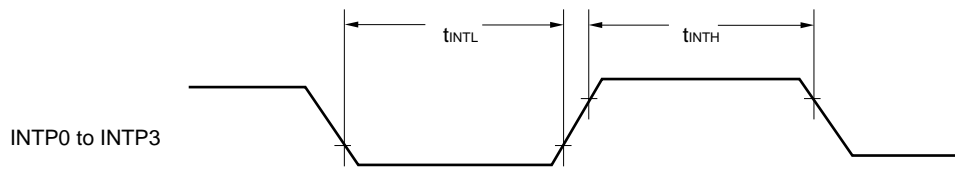
Clock Timing



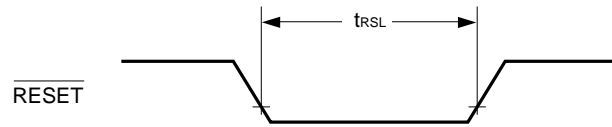
TI Timing



Interrupt Request Input Timing

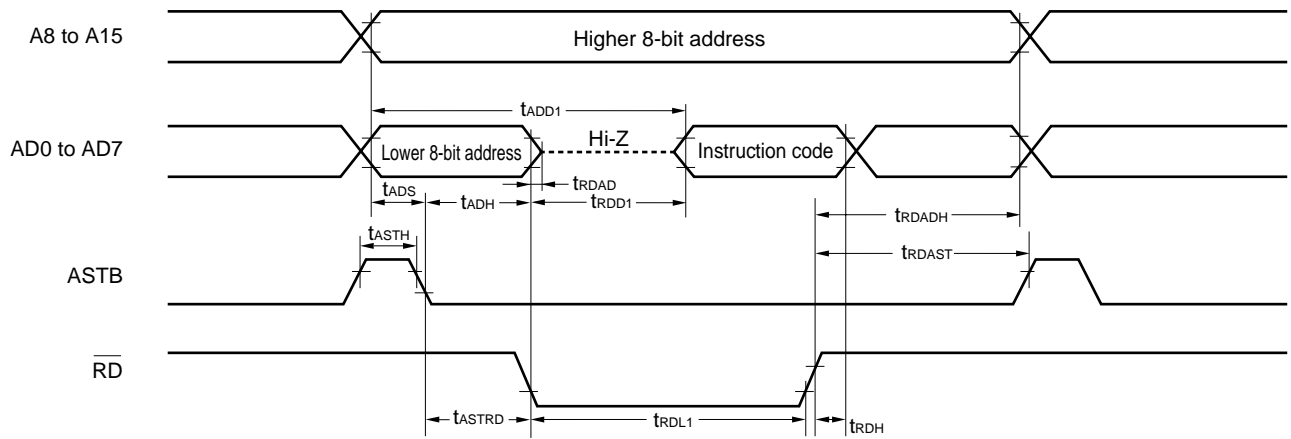


RESET Input Timing

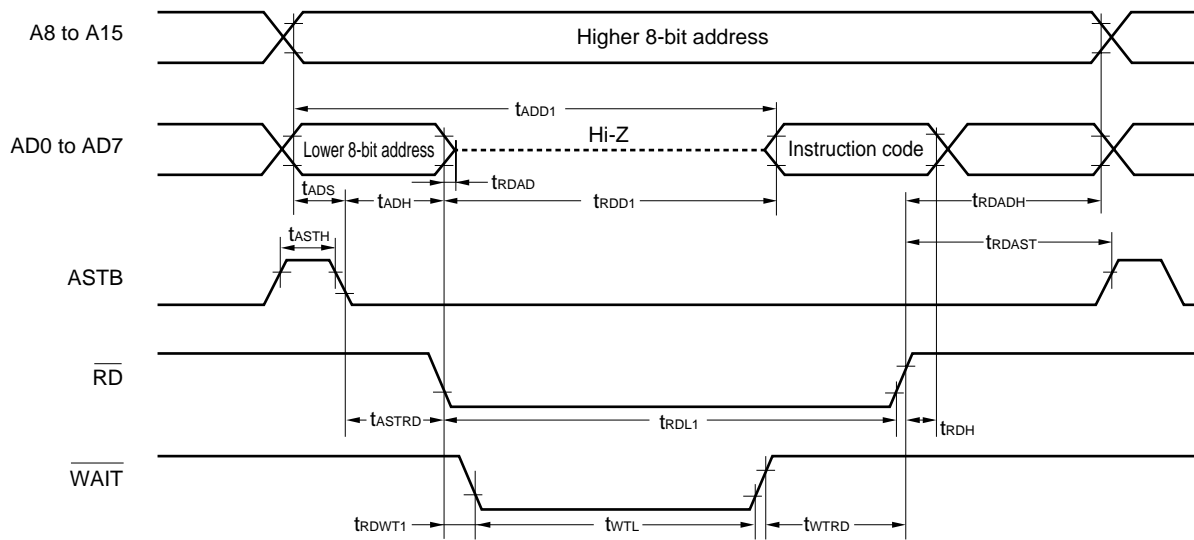


Read/Write Operation

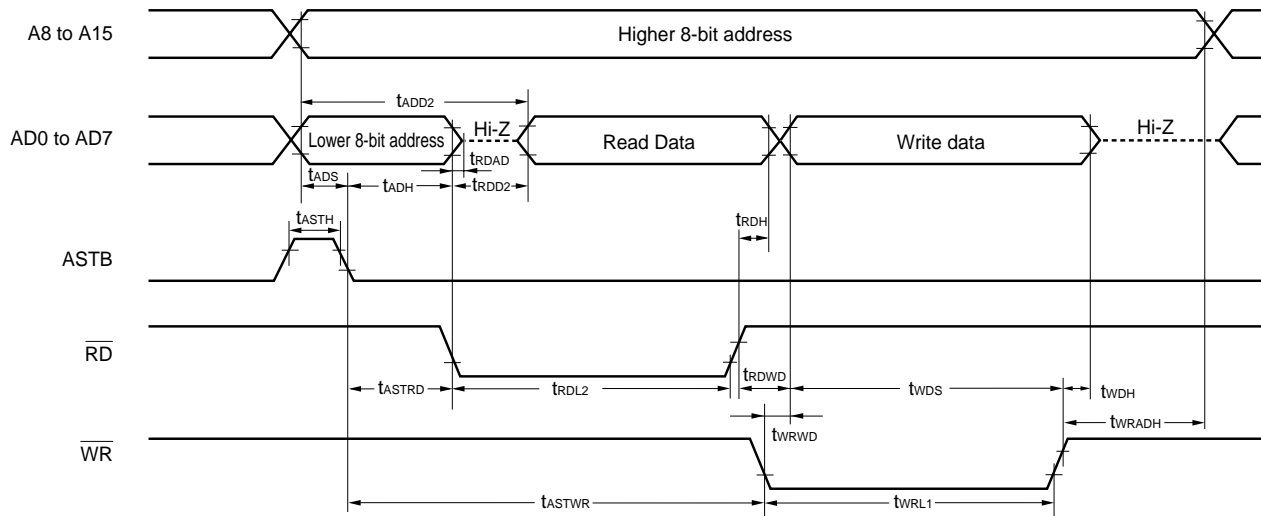
External fetch (no wait):



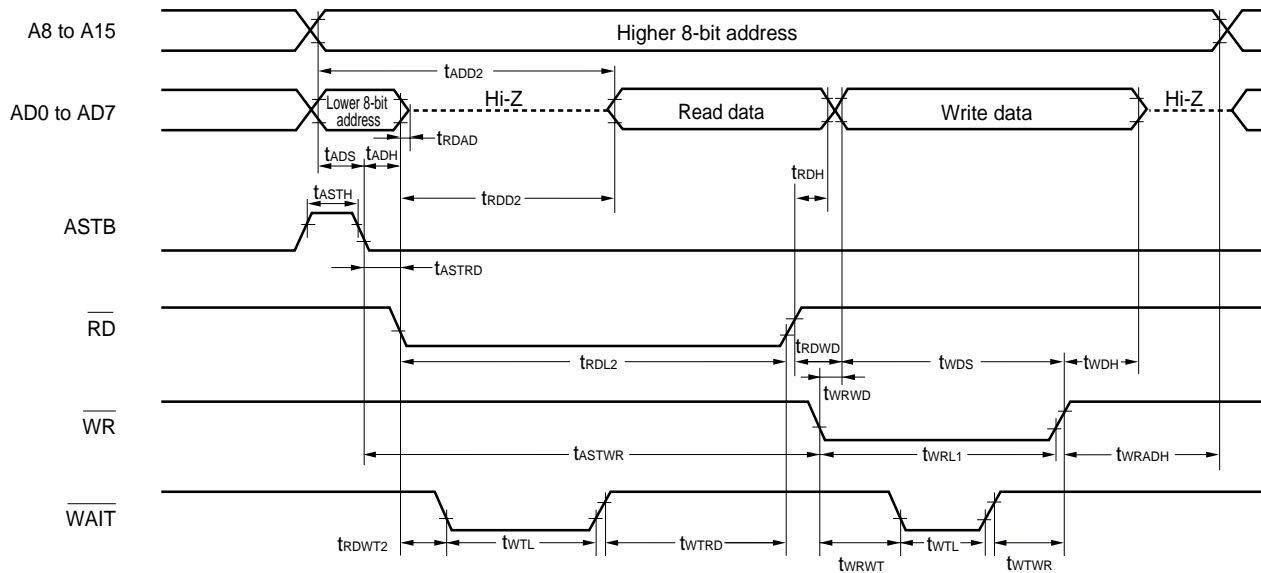
External fetch (wait insertion):



External data access (no wait):

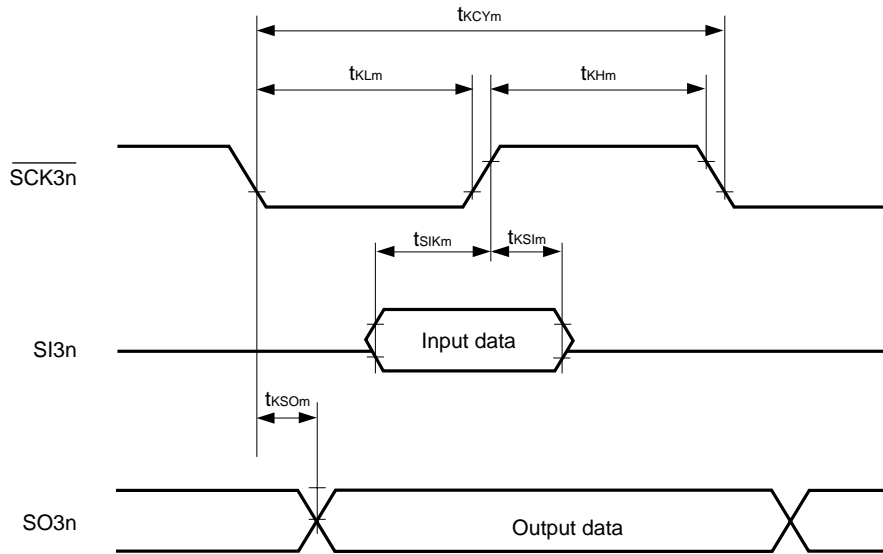


External data access (wait insertion):



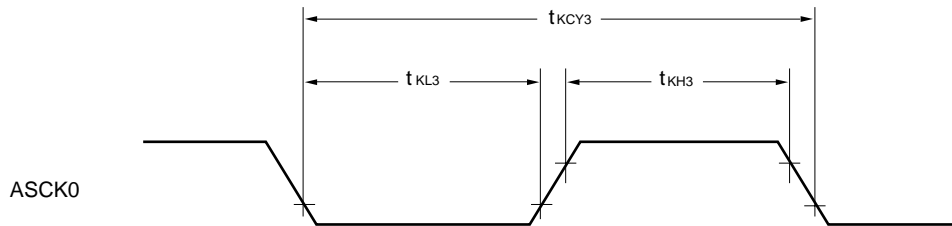
Serial Transfer Timing

3-wire serial I/O mode:

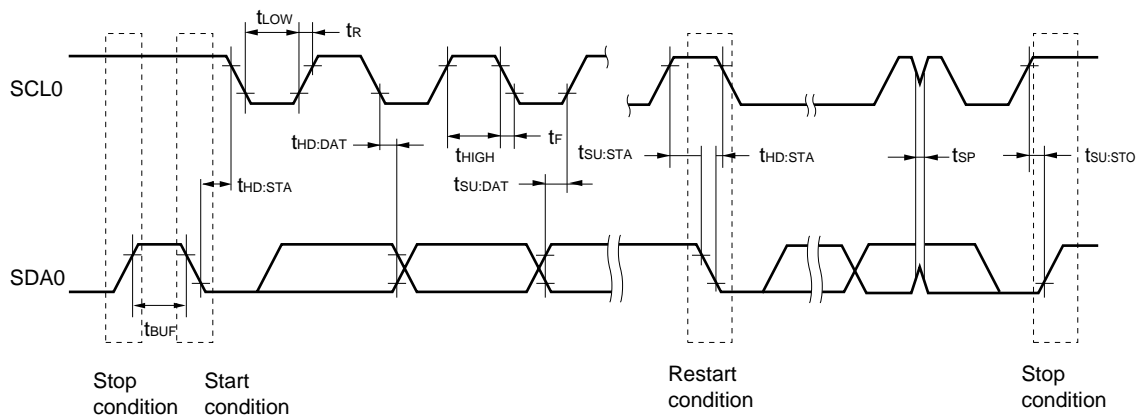


- Remarks 1. $m = 1, 2$
 2. μ PD780021A, 780022A, 780023A, 780024A: $n = 0, 1$
 μ PD780021AY, 780022AY, 780023AY, 780024AY: $n = 0$

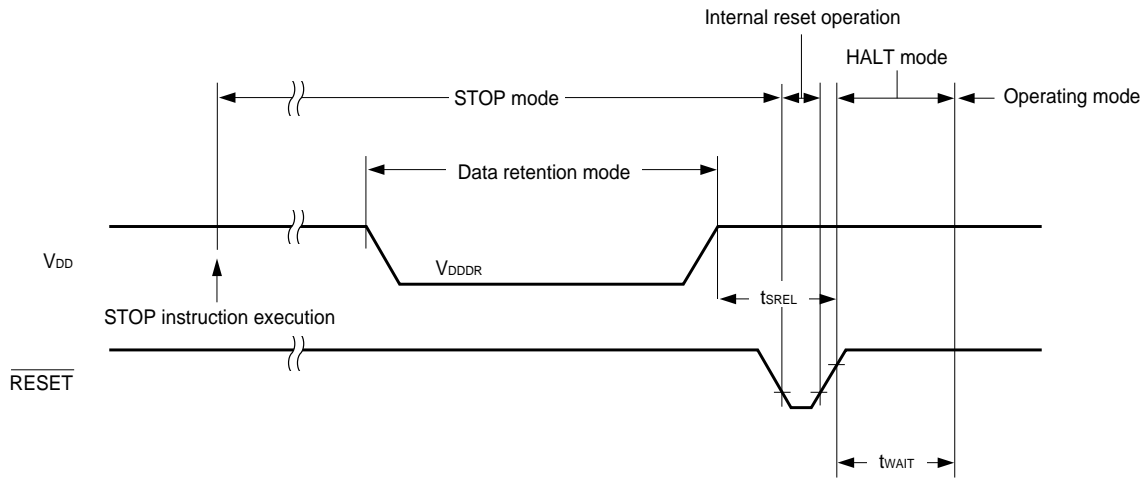
UART mode (external clock input):



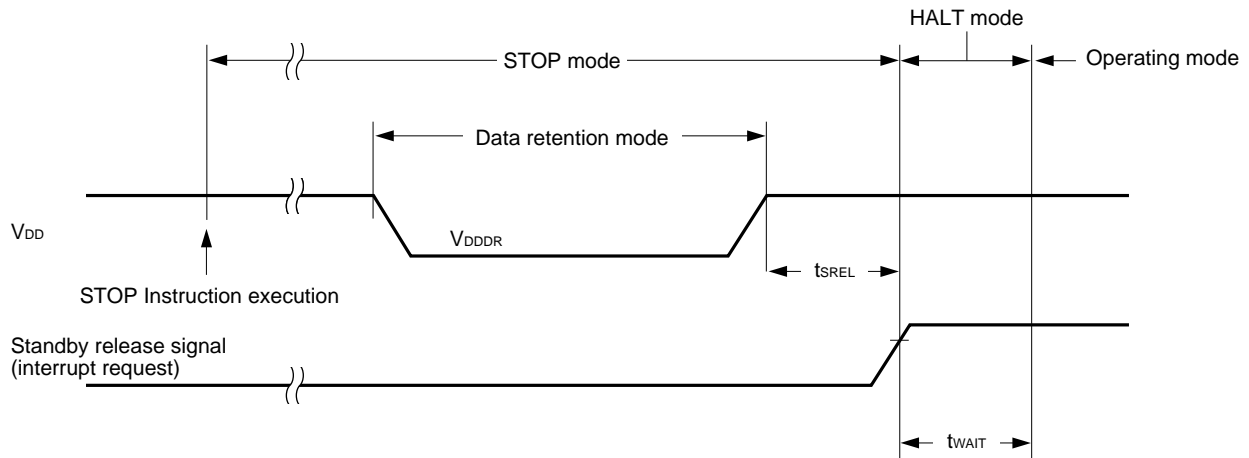
I²C bus mode (μ PD780021AY, 780022AY, 780023AY, 780024AY only):



Data Retention Timing (STOP Mode Release by $\overline{\text{RESET}}$)

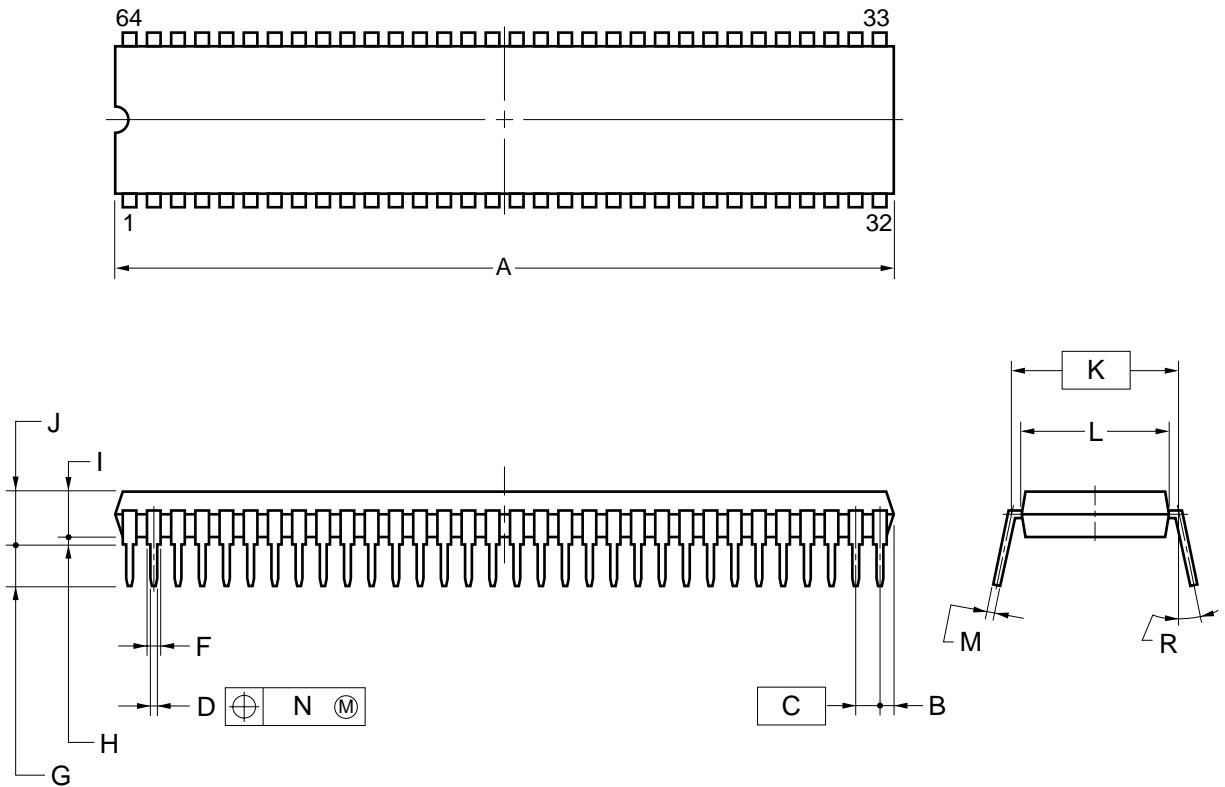


Data Retention Timing (Standby Release Signal: STOP Mode Release by Interrupt Request Signal)



13. PACKAGE DRAWINGS

64-PIN PLASTIC SDIP (19.05mm(750))



NOTES

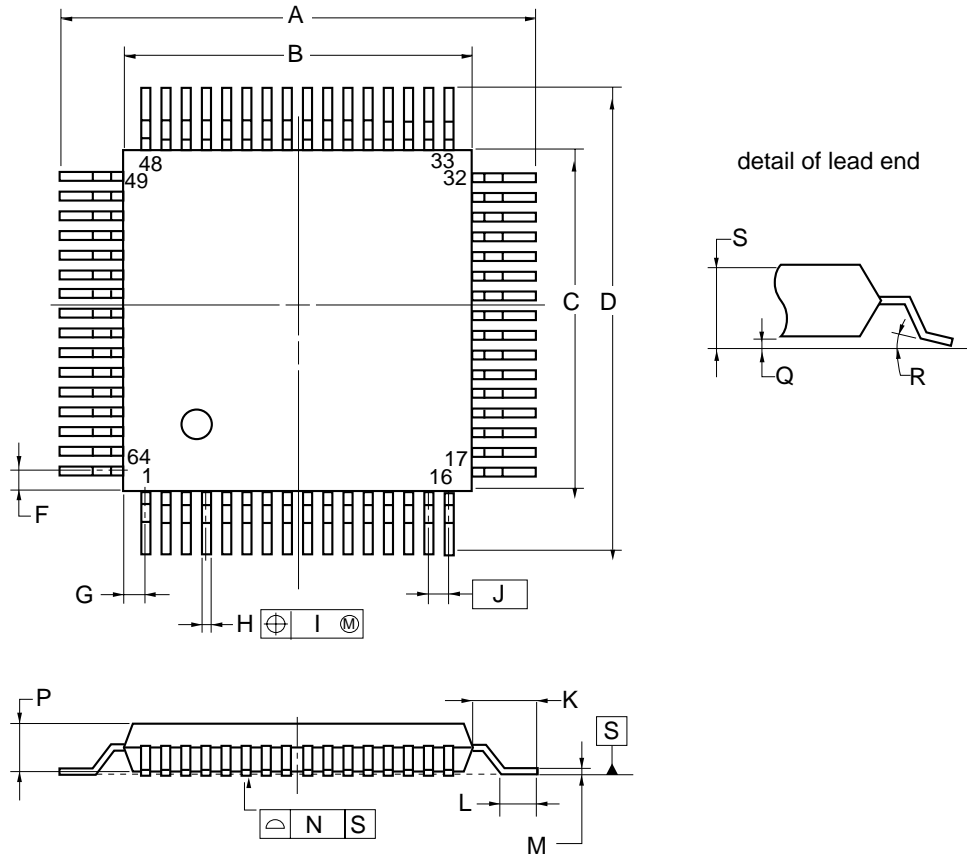
1. Each lead centerline is located within 0.17 mm of its true position (T.P.) at maximum material condition.
2. Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS
A	58.0 ^{+0.68} _{-0.20}
B	1.78 MAX.
C	1.778 (T.P.)
D	0.50±0.10
F	0.9 MIN.
G	3.2±0.3
H	0.51 MIN.
I	4.05 ^{+0.26} _{-0.20}
J	5.08 MAX.
K	19.05 (T.P.)
L	17.0±0.2
M	0.25 ^{+0.10} _{-0.05}
N	0.17
R	0 ~ 15°

P64C-70-750A,C-4

Remark The external dimensions and materials of the ES version are the same as those of the mass-produced version.

64-PIN PLASTIC QFP (14x14)



NOTE

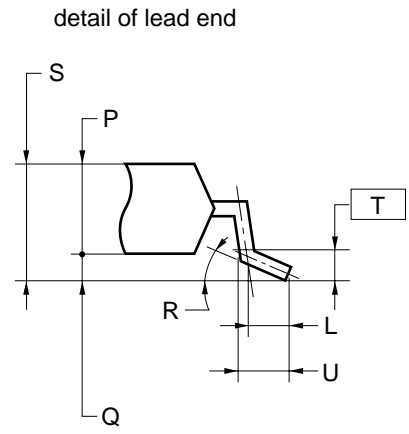
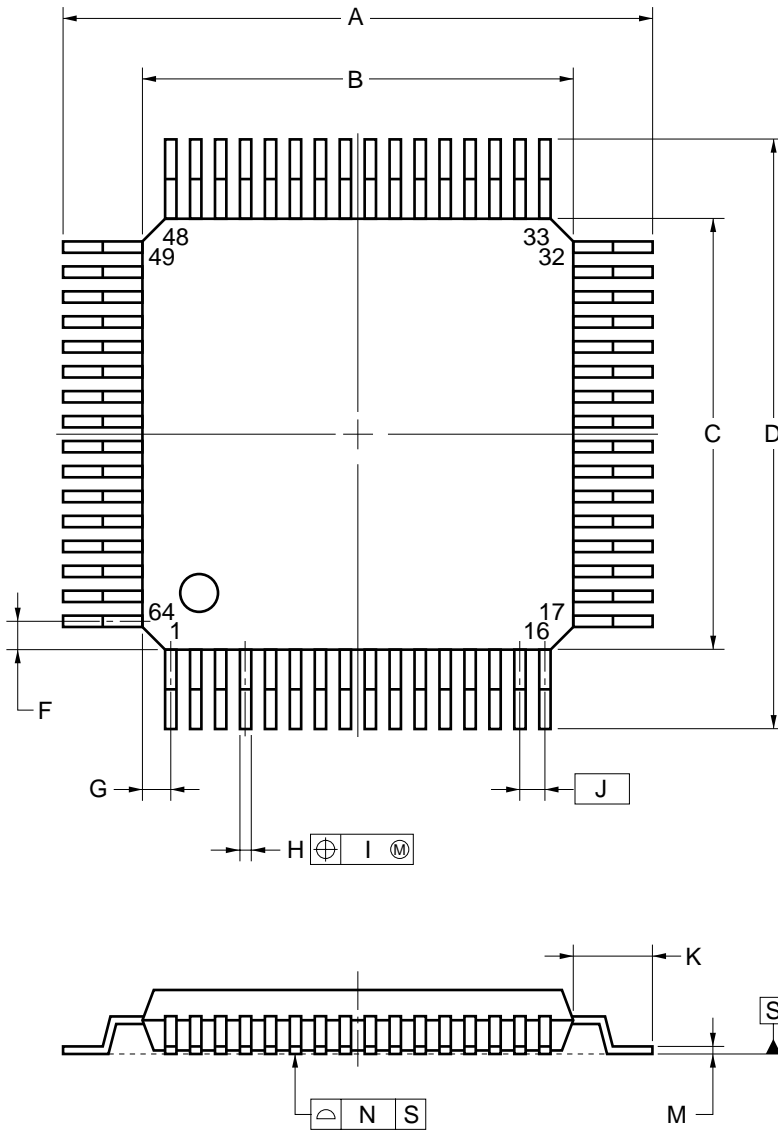
Each lead centerline is located within 0.15 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	17.6±0.4
B	14.0±0.2
C	14.0±0.2
D	17.6±0.4
F	1.0
G	1.0
H	0.37 ^{+0.08} _{-0.07}
I	0.15
J	0.8 (T.P.)
K	1.8±0.2
L	0.8±0.2
M	0.17 ^{+0.08} _{-0.07}
N	0.10
P	2.55±0.1
Q	0.1±0.1
R	5°± 5°
S	2.85 MAX.

P64GC-80-AB8-5

Remark The external dimensions and materials of the ES version are the same as those of the mass-produced version.

★ 64-PIN PLASTIC LQFP (14x14)



ITEM	MILLIMETERS
A	17.2±0.2
B	14.0±0.2
C	14.0±0.2
D	17.2±0.2
F	1.0
G	1.0
H	0.37 ^{+0.08} _{-0.07}
I	0.20
J	0.8 (T.P.)
K	1.6±0.2
L	0.8
M	0.17 ^{+0.03} _{-0.06}
N	0.10
P	1.4±0.1
Q	0.127±0.075
R	3° ^{+4°} _{-3°}
S	1.7 MAX.
T	0.25
U	0.886±0.15

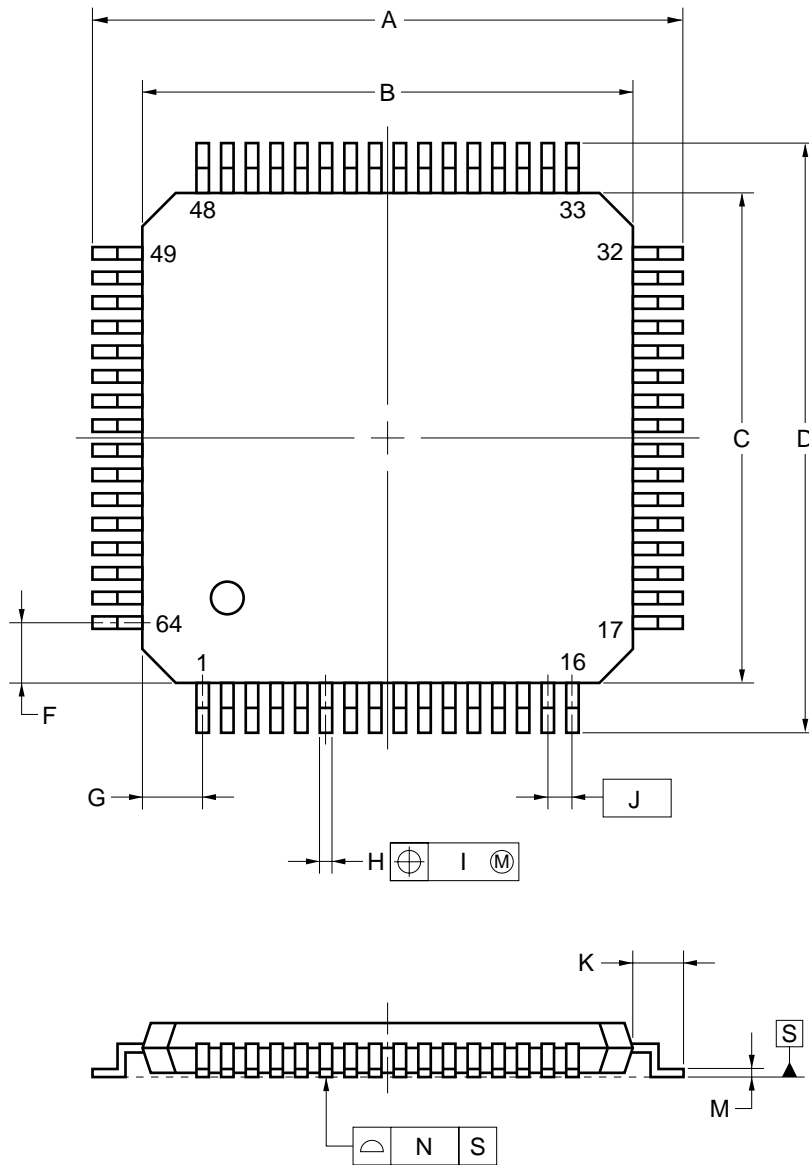
P64GC-80-8BS

NOTE

Each lead centerline is located within 0.20 mm of its true position (T.P.) at maximum material condition.

Remark The external dimensions and materials of the ES version are the same as those of the mass-produced version.

64-PIN PLASTIC TQFP (12x12)



ITEM	MILLIMETERS
A	14.0±0.2
B	12.0±0.2
C	12.0±0.2
D	14.0±0.2
F	1.125
G	1.125
H	0.32 ^{+0.06} _{-0.10}
I	0.13
J	0.65 (T.P.)
K	1.0±0.2
L	0.5
M	0.17 ^{+0.03} _{-0.07}
N	0.10
P	1.0
Q	0.1±0.05
R	3° ^{+4°} _{-3°}
S	1.1±0.1
T	0.25
U	0.6±0.15

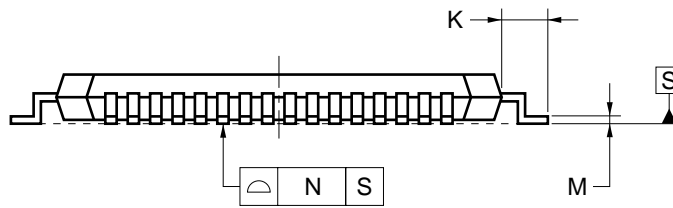
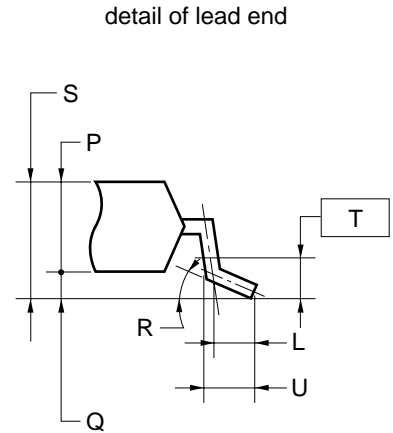
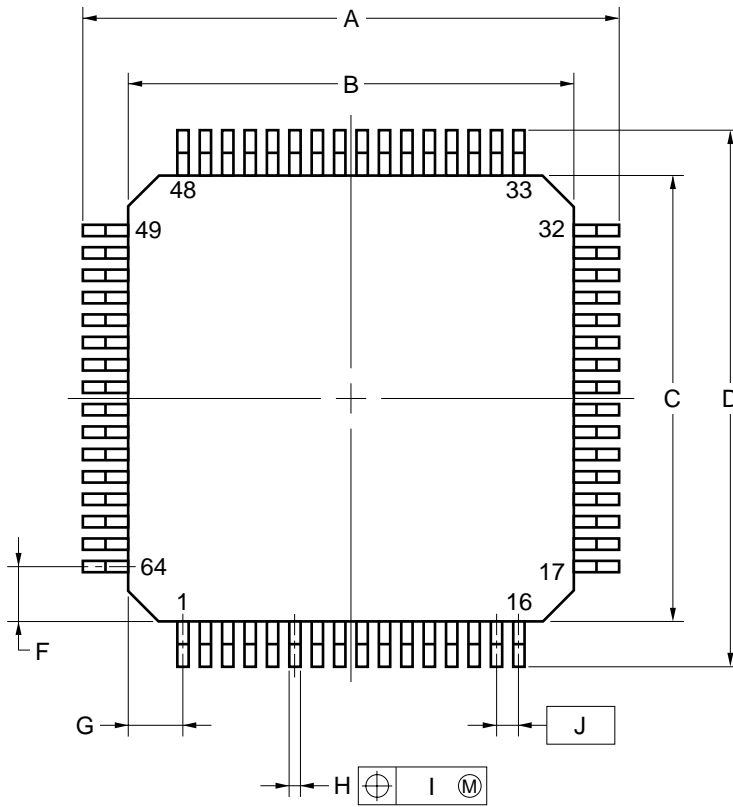
P64GK-65-9ET-3

NOTE

Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

Remark The external dimensions and materials of the ES version are the same as those of the mass-produced version.

★ 64-PIN PLASTIC LQFP (10x10)

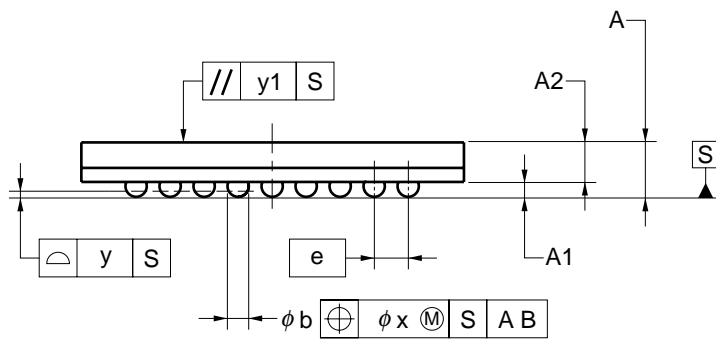
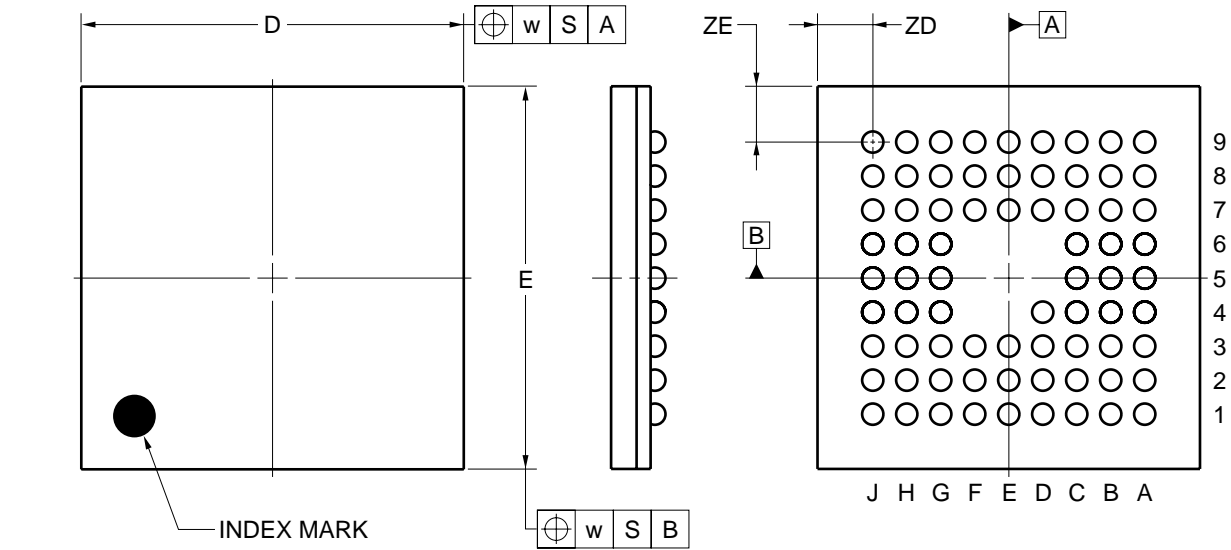


ITEM	MILLIMETERS
A	12.0±0.2
B	10.0±0.2
C	10.0±0.2
D	12.0±0.2
F	1.25
G	1.25
H	0.22±0.05
I	0.08
J	0.5 (T.P.)
K	1.0±0.2
L	0.5
M	0.17 ^{+0.03} _{-0.07}
N	0.08
P	1.4
Q	0.1±0.05
R	3° ^{+4°} _{-3°}
S	1.5±0.10
T	0.25
U	0.6±0.15

S64GB-50-8EU-1

Remark The external dimensions and materials of the ES version are the same as those of the mass-produced version.

★ 73-PIN PLASTIC FBGA (9x9)



(UNIT:mm)

ITEM	DIMENSIONS
D	9.00±0.10
E	9.00±0.10
w	0.20
A	1.28±0.10
A1	0.35±0.06
A2	0.93
e	0.80
b	0.50 ^{+0.05} _{-0.10}
x	0.08
y	0.10
y1	0.20
ZD	1.30
ZE	1.30

P73F1-80-CN3

Remark The external dimensions and materials of the ES version are the same as those of the mass-produced version.

14. RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions.

For details of the recommended soldering conditions, refer to the document **Semiconductor Device Mounting Technology Manual (C10535E)**.

For soldering methods and conditions other than those recommended below, contact an NEC Electronics sales representative.

Table 14-1. Surface Mounting Type Soldering Conditions (1/3)

- (1) μPD780021AGC-xxx-AB8: 64-pin plastic QFP (14 x 14)
- μPD780022AGC-xxx-AB8: 64-pin plastic QFP (14 x 14)
- μPD780023AGC-xxx-AB8: 64-pin plastic QFP (14 x 14)
- μPD780024AGC-xxx-AB8: 64-pin plastic QFP (14 x 14)
- μPD780021AYGC-xxx-AB8: 64-pin plastic QFP (14 x 14)
- μPD780022AYGC-xxx-AB8: 64-pin plastic QFP (14 x 14)
- μPD780023AYGC-xxx-AB8: 64-pin plastic QFP (14 x 14)
- μPD780024AYGC-xxx-AB8: 64-pin plastic QFP (14 x 14)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher), Count: Three times or less	IR35-00-3
VPS	Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Three times or less	VP15-00-3
Wave soldering	Solder bath temperature: 260°C max., Time: 10 seconds max., Count: Once, Preheating temperature: 120°C Max. (package surface temperature)	WS60-00-1
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	—

Caution Do not use different soldering methods together (except for partial heating).

- ★ (2) μPD780021AGC-xxx-8BS: 64-pin plastic LQFP (14 x 14)
- μPD780022AGC-xxx-8BS: 64-pin plastic LQFP (14 x 14)
- μPD780023AGC-xxx-8BS: 64-pin plastic LQFP (14 x 14)
- μPD780024AGC-xxx-8BS: 64-pin plastic LQFP (14 x 14)
- μPD780021AYGC-xxx-8BS: 64-pin plastic LQFP (14 x 14)
- μPD780022AYGC-xxx-8BS: 64-pin plastic LQFP (14 x 14)
- μPD780023AYGC-xxx-8BS: 64-pin plastic LQFP (14 x 14)
- μPD780024AYGC-xxx-8BS: 64-pin plastic LQFP (14 x 14)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher), Count: Two times or less	IR35-00-2
VPS	Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Two times or less	VP15-00-2
Wave soldering	Solder bath temperature: 260°C max., Time: 10 seconds max., Count: Once, Preheating temperature: 120°C Max. (package surface temperature)	WS60-00-1
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	—

Caution Do not use different soldering methods together (except for partial heating).

Table 14-1. Surface Mounting Type Soldering Conditions (2/3)

- (3) μPD780021AGK-xxx-9ET: 64-pin plastic TQFP (12 x 12)
- μPD780022AGK-xxx-9ET: 64-pin plastic TQFP (12 x 12)
- μPD780023AGK-xxx-9ET: 64-pin plastic TQFP (12 x 12)
- μPD780024AGK-xxx-9ET: 64-pin plastic TQFP (12 x 12)
- μPD780021AYGK-xxx-9ET: 64-pin plastic TQFP (12 x 12)
- μPD780022AYGK-xxx-9ET: 64-pin plastic TQFP (12 x 12)
- μPD780023AYGK-xxx-9ET: 64-pin plastic TQFP (12 x 12)
- μPD780024AYGK-xxx-9ET: 64-pin plastic TQFP (12 x 12)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher), Count: Two times or less, Exposure limit: 7 days ^{Note} (after that, prebake at 125°C for 10 hours)	IR35-107-2
VPS	Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Two times or less, Exposure limit: 7 days ^{Note} (after that, prebake at 125°C for 10 hours)	VP15-107-2
Wave soldering	Solder bath temperature: 260°C max., Time: 10 seconds max., Count: Once, Preheating temperature: 120°C Max. (package surface temperature), Exposure limit: 7 days ^{Note} (after that, prebake at 125°C for 10 hours)	WS60-107-1
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	—

Note After opening the dry pack, store it at 25°C or less and 65%RH or less for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

Table 14-1. Surface Mounting Type Soldering Conditions (3/3)

- ★ (4) μPD780021AGB-xxx-8EU: 64-pin plastic LQFP (10 x 10)
- μPD780022AGB-xxx-8EU: 64-pin plastic LQFP (10 x 10)
- μPD780023AGB-xxx-8EU: 64-pin plastic LQFP (10 x 10)
- μPD780024AGB-xxx-8EU: 64-pin plastic LQFP (10 x 10)
- μPD780021AYGB-xxx-8EU: 64-pin plastic LQFP (10 x 10)
- μPD780022AYGB-xxx-8EU: 64-pin plastic LQFP (10 x 10)
- μPD780023AYGB-xxx-8EU: 64-pin plastic LQFP (10 x 10)
- μPD780024AYGB-xxx-8EU: 64-pin plastic LQFP (10 x 10)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher), Count: Twice or less	IR35-00-2
VPS	Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Twice or less	VP15-00-2
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	—

Caution Do not use different soldering methods together (except for partial heating).

- ★ (5) μPD780021AF1-xxx-CN3: 73-pin plastic FBGA (9 x 9)
- μPD780022AF1-xxx-CN3: 73-pin plastic FBGA (9 x 9)
- μPD780023AF1-xxx-CN3: 73-pin plastic FBGA (9 x 9)
- μPD780024AF1-xxx-CN3: 73-pin plastic FBGA (9 x 9)
- μPD780021AYF1-xxx-CN3: 73-pin plastic FBGA (9 x 9)
- μPD780022AYF1-xxx-CN3: 73-pin plastic FBGA (9 x 9)
- μPD780023AYF1-xxx-CN3: 73-pin plastic FBGA (9 x 9)
- μPD780024AYF1-xxx-CN3: 73-pin plastic FBGA (9 x 9)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 260°C, Time: 60 seconds max. (at 220°C or higher), Count: Three times or less, Exposure limit: 3 days ^{Note} (after that, prebake at 125°C for 20 hours)	IR60-203-3
VPS	Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Three times or less, Exposure limit: 3 days ^{Note} (after that, prebake at 125°C for 20 hours)	VP15-203-3

Note After opening the dry pack, store it at 25°C or less and 65%RH or less for the allowable storage period.

Caution Do not use different soldering methods together.

Table 14-2. Insertion Type Soldering Conditions

- μ*PD780021ACW-xxx: 64-pin plastic SDIP (19.05 mm (750))
- μ*PD780022ACW-xxx: 64-pin plastic SDIP (19.05 mm (750))
- μ*PD780023ACW-xxx: 64-pin plastic SDIP (19.05 mm (750))
- μ*PD780024ACW-xxx: 64-pin plastic SDIP (19.05 mm (750))
- μ*PD780021AYCW-xxx: 64-pin plastic SDIP (19.05 mm (750))
- μ*PD780022AYCW-xxx: 64-pin plastic SDIP (19.05 mm (750))
- μ*PD780023AYCW-xxx: 64-pin plastic SDIP (19.05 mm (750))
- μ*PD780024AYCW-xxx: 64-pin plastic SDIP (19.05 mm (750))

Soldering Method	Soldering Conditions
Wave soldering (only for pins)	Solder bath temperature: 260°C max., Time: 10 seconds max.
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)

Caution Apply wave soldering only to the pins and be careful not to bring solder into direct contact with the package.

APPENDIX A. DEVELOPMENT TOOLS

The following development tools are available for system development using the μPD780024A, 780024AY Subseries.

Also refer to **(6) Cautions on Using Development Tools.**

(1) Software Package

SP78K0	CD-ROM in which various software tools for 78K/0 development are integrated in one package
--------	--

(2) Language Processing Software

RA78K0	Assembler package common to 78K/0 Series
CC78K0	C compiler package common to 78K/0 Series
DF780024	Device file for μPD780024A, 780024AY Subseries
CC78K0-L	C compiler library source file common to 78K/0 Series

★ **(3) Flash Memory Writing Tools**

Flashpro III (FL-PR3, PG-FP3) Flashpro IV (FL-PR4, PG-FP4)	Flash programmer dedicated to microcontrollers with on-chip flash memory
FA-64CW FA-64GC FA-64GC-8BS-A FA-64GK-9ET FA-64GB-8EU FA-73F1-CN3-A	Adapter for flash memory writing used connected to the Flashpro III/Flashpro IV. <ul style="list-style-type: none"> • FA-64CW: 64-pin plastic SDIP (CW type) • FA-64GC: 64-pin plastic QFP (GC-AB8 type) • FA-64GC-8BS-A: 64-pin plastic LQFP (GC-8BS type) • FA-64GK-9ET: 64-pin plastic TQFP (GK-9ET type) • FA-64GB-8EU: 64-pin plastic LQFP (GB-8EU type) • FA-73F1-CN3-A: 73-pin plastic FBGA (F1-CN3 type)

(4) Debugging Tools

★ • When using in-circuit emulator IE-78K0-NS or IE-78K0-NS-A

IE-78K0-NS	In-circuit emulator common to 78K/0 Series
IE-78K0-NS-PA	Performance board to enhance and expand the functions of IE-78K0-NS
IE-78K0-NS-A	Combination of IE-78K-NS and IE-78K0-NS-PA
IE-70000-MC-PS-B	Power supply unit for IE-78K0-N and IE-78K0-NS-A
IE-70000-98-IF-C	Adapter required when using PC-9800 series as host machine (excluding notebook PCs) (C bus supported)
IE-70000-CD-IF-A	PC card and interface cable when using notebook PC as host machine (PCMCIA socket supported)
IE-70000-PC-IF-C	Adapter required when using IBM PC/AT™ or compatible as host machine (ISA bus supported)
IE-70000-PCI-IF-A	Adapter required when using PC in which PCI bus is incorporated as host machine
IE-780034-NS-EM1	Emulation board to emulate μPD780024A, 780024AY Subseries
NP-64CW NP-H64CW	Emulation probe for 64-pin plastic SDIP (CW type)
NP-64GC NP-64GC-TQ NP-H64GC-TQ	Emulation probe for 64-pin plastic QFP (GC-AB8 type), 64-pin plastic LQFP (GC-8BS type)
NP-64GK NP-H64GK-TQ	Emulation probe for 64-pin plastic TQFP (GK-9ET type)
NP-H64GB-TQ	Emulation probe for 64-pin plastic LQFP (GB-8EU type)
NP-73F1-CN3 ^{Note}	Emulation probe for 73-pin plastic FBGA (F1-CN3 type)
EV-9200GC-64	Conversion socket to connect the NP64GC and a target system board on which a 64-pin plastic QFP (GC-AB8 type), 64-pin plastic LQFP (GC-8BS type) can be mounted.
TGC-064SAP	Conversion adapter to connect the NP-64GC-TQ or NP-H64GC-TQ and a target system board on which a 64-pin plastic QFP (GC-AB8 type), 64-pin plastic LQFP (GC-8BS type) can be mounted
TGK-064SBW	Conversion adapter to connect the NP-64GK or NP-H64GK-TQ and a target system on which a 64-pin plastic TQFP (GK-9ET type) can be mounted
TGB-064SDP	Conversion socket to connect the NP-H64GB-TQ and a target system board on which a 64-pin plastic LQFP (GB-8EU type) can be mounted
CSICE73A0909N01, LSPACK73A0909N01, CSSOCKET73A0909N01	Conversion socket to connect the NP-73F1-CN3 and a target system board on which a 73-pin plastic FBGA (F1-CN3 type) can be mounted
ID78K0-NS	Integrated debugger for IE-78K0-NS and IE-78K0-NS-A
SM78K0	System simulator common to 78K/0 Series
DF780024	Device file for μPD780024A, 780024AY Subseries

Note The conversion socket (CSICE73A0909N01, LSPACK73A0909N01, or CSSOCKET73A0909N01) is supplied with the emulation probe (NP-73F1-CN3).

• When using in-circuit emulator IE-78001-R-A

IE-78001-R-A	In-circuit emulator common to 78K/0 Series
IE-70000-98-IF-C	Adapter required when using PC-9800 series as host machine (excluding notebook PCs) (C bus supported)
IE-70000-PC-IF-C	Interface adapter when using IBM PC/AT or compatible as host machine (ISA bus supported)
IE-70000-PCI-IF-A	Adapter required when using PC in which PCI bus is incorporated as host machine
IE-780034-NS-EM1	Emulation board to emulate μPD780024A, 780024AY Subseries
IE-78K0-R-EX1	Emulation probe conversion board necessary when using IE-780034-NS-EM1 on IE-78001-R-A
EP-78240CW-R	Emulation probe for 64-pin plastic SDIP (CW type)
EP-78240GC-R	Emulation probe for 64-pin plastic QFP (GC-AB8 type)
EP-78012GK-R	Emulation probe for 64-pin plastic TQFP (GK-9ET type)
EV-9200GC-64	Conversion socket to connect the EP-78240GC-R and a target system board on which a 64-pin plastic QFP (GC-AB8 type) can be mounted
TGK-064SBW	Conversion adapter to connect the EP-78012GK-R and a target system board on which a 64-pin plastic TQFP (GK-9ET type) can be mounted
ID78K0	Integrated debugger for IE-78001-R-A
SM78K0	System simulator common to 78K/0 Series
DF780024	Device file for μPD780024A, 780024AY Subseries

(5) Real-Time OS

RX78K0	Real-time OS for 78K/0 Series
--------	-------------------------------

★ **Caution** The 64-pin plastic LQFP (GB-8EU type) and 73-pin plastic FBGA (F1-CN3 type) do not support the IE-78001-R-A.

★ (6) Cautions on Using Development Tools

- The ID78K0-NS, ID78K0, and SM78K0 are used in combination with the DF780024.
- The CC78K0 and RX78K0 are used in combination with the RA78K0 and the DF780024.
- FL-PR3, FL-PR4, FA-64CW, FA-64GC, FA-64GC-8BS-A, FA-64GK-9ET, FA-64GB-8EU, FA-73F1-CN3-A, NP-64CW, NP-H64CW, NP-64GC, NP-64GC-TQ, NP-H64GC-TQ, NP-64GK, NP-H64GK-TQ, NP-H64GB-TQ, and NP-73F1-CN3 are products made by Naito Densai Machida Mfg. Co., Ltd. (+81-45-475-4191).
- TGC-064SAP, TGC-064SBW, TGB-064SDP, CSICE73A0909N01, LSPACK73A0909N01, and CSSOCKET73A0909N01 are products made by TOKYO ELETECH CORPORATION.

Refer to: Daimaru Kogyo, Ltd.

Tokyo Electronic Division (+81-3-3820-7112)

Osaka Electronic Division (+81-6-6244-6672)

- For third-party development tools, see the **Single-chip Microcontroller Development Tool Selection Guide (U11069E)**.
- The host machines and OSs supporting each software are as follows.

Host Machine [OS]	PC	EWS
	PC-9800 series [Japanese Windows™] IBM PC/AT and compatibles [Japanese/English Windows]	HP9000 series 700™ [HP-UX™] SPARCstation™ [SunOS™, Solaris™]
Software		
RA78K0	√ Note	√
CC78K0	√ Note	√
ID78K0-NS	√	—
ID78K0	√	—
SM78K0	√	—
RX78K0	√ Note	√

Note DOS-based software

APPENDIX B. RELATED DOCUMENTS

The related documents indicated in this publication may include preliminary versions. However, preliminary versions are not marked as such.

Documents Related to Devices

Document Name	Document No.
μPD780024A, 780034A, 780024AY, 780034AY Subseries User's Manual	U14046E
μPD780021A, 780022A, 780023A, 780024A, 780021AY, 780022AY, 780023AY, 780024AY Data Sheet	This document
μPD780021A(A), 780022A(A), 780023A(A), 780024A(A), 780021AY(A), 780022AY(A), 780023AY(A), 780024AY(A) Data Sheet	U15131E
μPD78F0034A, 78F0034AY Data Sheet	U14040E
★ μPD78F0034B, 78F0034BY, 78F0034B(A), 78F0034BY(A) Data Sheet	To be prepared
78K/0 Series Instructions User's Manual	U12326E

★ **Documents Related to Development Software Tools (User's Manuals)**

Document Name	Document No.	
RA78K0 Assembler Package	Operation	U14445E
	Language	U14446E
	Structured Assembly Language	U11789E
CC78K0 C Compiler	Operation	U14297E
	Language	U14298E
SM78K Series System Simulator Ver. 2.30 or Later	Operation (Windows Based)	U15373E
	External Part User Open Interface Specifications	U15802E
ID78K Series Integrated Debugger Ver. 2.30 or Later	Operation (Windows Based)	U15185E
RX78K0 Real-time OS	Fundamentals	U11537E
	Installation	U11536E
Project Manager Ver. 3.12 or Later (Windows Based)	U14610E	

Documents Related to Development Hardware Tools (User's Manuals)

Document Name	Document No.
★ IE-78K0-NS In-Circuit Emulator	U13731E
★ IE-78K0-NS-A In-Circuit Emulator	U14889E
★ IE-780034-NS-EM1 Emulation Board	U14642E
★ IE-78001-R-A In-Circuit Emulator	U14142E
IE-78K0-R-EX1 In-Circuit Emulator	To be prepared

Caution The related documents listed above are subject to change without notice. Be sure to use the latest version of each document for designing.

★ **Documents Related to Flash Memory Writing**

Document Name	Document No.
PG-FP3 Flash Memory Programmer User's Manual	U13502E
PG-FP4 Flash Memory Programmer User's Manual	U15260E

Other Related Documents

Document Name	Document No.
★ SEMICONDUCTOR SELECTION GUIDE - Products & Packages -	X13769E
Semiconductor Device Mounting Technology Manual	C10535E
Quality Grades on NEC Semiconductor Devices	C11531E
NEC Semiconductor Device Reliability/Quality Control System	C10983E
Guide to Prevent Damage for Semiconductor Devices by Electrostatic Discharge (ESD)	C11892E

Caution The related documents listed above are subject to change without notice. Be sure to use the latest version of each document for designing.

[MEMO]

NOTES FOR CMOS DEVICES**① PRECAUTION AGAINST ESD FOR SEMICONDUCTORS**

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

② HANDLING OF UNUSED INPUT PINS FOR CMOS

Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to V_{DD} or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

③ STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

Note: Purchase of NEC Electronics I²C components conveys a license under the Philips I²C Patent Rights to use these components in an I²C system, provided that the system conforms to the I²C Standard Specification as defined by Philips.

FIP and IEBus are trademarks of NEC Electronics Corporation.

Windows is either a registered trademark or a trademark of Microsoft Corporation in the United States and/ or other countries.

PC/AT is a trademark of International Business Machines Corporation.

HP9000 series 700 and HP-UX are trademarks of Hewlett-Packard Company.

SPARCstation is a trademark of SPARC International, Inc.

Solaris and SunOS are trademarks of Sun Microsystems, Inc.

Regional Information

Some information contained in this document may vary from country to country. Before using any NEC Electronics product in your application, please contact the NEC Electronics office in your country to obtain a list of authorized representatives and distributors. They will verify:

- Device availability
- Ordering information
- Product release schedule
- Availability of related technical literature
- Development environment specifications (for example, specifications for third-party tools and components, host computers, power plugs, AC supply voltages, and so forth)
- Network requirements

In addition, trademarks, registered trademarks, export restrictions, and other legal issues may also vary from country to country.

NEC Electronics America, Inc. (U.S.)

Santa Clara, California
Tel: 408-588-6000
800-366-9782
Fax: 408-588-6130
800-729-9288

NEC Electronics (Europe) GmbH

Duesseldorf, Germany
Tel: 0211-65 03 01
Fax: 0211-65 03 327

• Sucursal en España

Madrid, Spain
Tel: 091-504 27 87
Fax: 091-504 28 60

• Succursale Française

Vélizy-Villacoublay, France
Tel: 01-30-67 58 00
Fax: 01-30-67 58 99

• Filiale Italiana

Milano, Italy
Tel: 02-66 75 41
Fax: 02-66 75 42 99

• Branch The Netherlands

Eindhoven, The Netherlands
Tel: 040-244 58 45
Fax: 040-244 45 80

• Tyskland Filial

Taeby, Sweden
Tel: 08-63 80 820
Fax: 08-63 80 388

• United Kingdom Branch

Milton Keynes, UK
Tel: 01908-691-133
Fax: 01908-670-290

NEC Electronics Hong Kong Ltd.

Hong Kong
Tel: 2886-9318
Fax: 2886-9022/9044

NEC Electronics Hong Kong Ltd.

Seoul Branch
Seoul, Korea
Tel: 02-528-0303
Fax: 02-528-4411

NEC Electronics Shanghai, Ltd.

Shanghai, P.R. China
Tel: 021-6841-1138
Fax: 021-6841-1137

NEC Electronics Taiwan Ltd.

Taipei, Taiwan
Tel: 02-2719-2377
Fax: 02-2719-5951

NEC Electronics Singapore Pte. Ltd.

Novena Square, Singapore
Tel: 6253-8311
Fax: 6250-3583

These commodities, technology or software, must be exported in accordance with the export administration regulations of the exporting country. Diversion contrary to the law of that country is prohibited.

- **The information in this document is current as of September, 2002. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets or data books, etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.**

- No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Electronics. NEC Electronics assumes no responsibility for any errors that may appear in this document.
- NEC Electronics does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC Electronics products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Electronics or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of a customer's equipment shall be done under the full responsibility of the customer. NEC Electronics assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC Electronics endeavors to enhance the quality, reliability and safety of NEC Electronics products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize risks of damage to property or injury (including death) to persons arising from defects in NEC Electronics products, customers must incorporate sufficient safety measures in their design, such as redundancy, fire-containment and anti-failure features.
- NEC Electronics products are classified into the following three quality grades: "Standard", "Special" and "Specific".

The "Specific" quality grade applies only to NEC Electronics products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.

"Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.

"Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).

"Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).